

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

- Direct Upgrades to TL05x, TL07x, and TL08x BiFET Operational Amplifiers
- Greater Than 2× Bandwidth (10 MHz) and 3× Slew Rate (45 V/μs) Than TL08x
- On-Chip Offset Voltage Trimming for Improved DC Performance
- Wider Supply Rails Increase Dynamic Signal Range to ±19 V

description

The TLE208x series of JFET-input operational amplifiers more than double the bandwidth and triple the slew rate of the TL07x and TL08x families of BiFET operational amplifiers. The TLE208x also have wider supply-voltage rails, increasing the dynamic-signal range for BiFET circuits to ±19 V. On-chip zener trimming of offset voltage yields precision grades for greater accuracy in dc-coupled applications. The TLE208x are pin-compatible with lower performance BiFET operational amplifiers for ease in improving performance in existing designs.

BiFET operational amplifiers offer the inherently higher input impedance of the JFET-input transistors, without sacrificing the output drive associated with bipolar amplifiers. This makes these amplifiers better suited for interfacing with high-impedance sensors or very low level ac signals. They also feature inherently better ac response than bipolar or CMOS devices having comparable power consumption.

Because BiFET operational amplifiers are designed for use with dual power supplies, care must be taken to observe common-mode input-voltage limits and output voltage swing when operating from a single supply. DC biasing of the input signal is required and loads should be terminated to a virtual ground node at mid-supply. Texas Instruments TLE2426 integrated virtual ground generator is useful when operating BiFET amplifiers from single supplies.

The TLE208x are fully specified at ±15 V and ±5 V. For operation in low-voltage and/or single-supply systems, Texas Instruments LinCMOS™ families of operational amplifiers (TLC- and TLV-prefix) are recommended. When moving from BiFET to CMOS amplifiers, particular attention should be paid to slew rate and bandwidth requirements and output loading.

For BiFET circuits requiring low noise and/or tighter dc precision, the TLE207x offer the same ac response as the TLE208x with more stringent dc and noise specifications.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

LinCMOS is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 2001, Texas Instruments Incorporated

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES				CHIP FORM (Y)
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	
0°C to 70°C	3 mV 6 mV	TLE2081ACD TLE2081CD	—	—	TLE2081ACP TLE2081CP	— TLE2081Y
–40°C to 85°C	3 mV 6 mV	TLE2081AID TLE2081ID	—	—	TLE2081AIP TLE2081IP	—
–55°C to 125°C	3 mV 6 mV	—	TLE2081AMFK TLE2081MFK	TLE2081AMJG TLE2081MJG	—	—

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2081ACDR).

‡ Chip forms are tested at T_A = 25°C only.

TLE2082 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES				CHIP FORM (Y)
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	
0°C to 70°C	4 mV 7 mV	TLE2082ACD TLE2082CD	—	—	TLE2082ACP TLE2082CP	—
–40°C to 85°C	4 mV 7 mV	TLE2082AID TLE2082ID	—	—	TLE2082AIP TLE2082IP	TLE2082Y
–55°C to 125°C	4 mV 7 mV	TLE2082AMD TLE2082MD	TLE2082AMFK TLE2082MFK	TLE2082AMJG TLE2082MJG	TLE2082AMP TLE2082MP	—

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2082ACDR).

‡ Chip forms are tested at T_A = 25°C only.

TLE2084 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES				CHIP FORM (Y)
		SMALL OUTLINE (DW)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	
0°C to 70°C	4 mV 7 mV	TLE2084ACDW TLE2084CDW	—	—	TLE2084ACN TLE2084CN	— TLE2084Y
–55°C to 125°C	4 mV 7 mV	—	TLE2084AMFK TLE2084MFK	TLE2084AMJ TLE2084MJ	—	—

† The DW packages are available taped and reeled. Add R suffix to device type (e.g., TLE2084ACDWR).

‡ Chip forms are tested at T_A = 25°C only.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

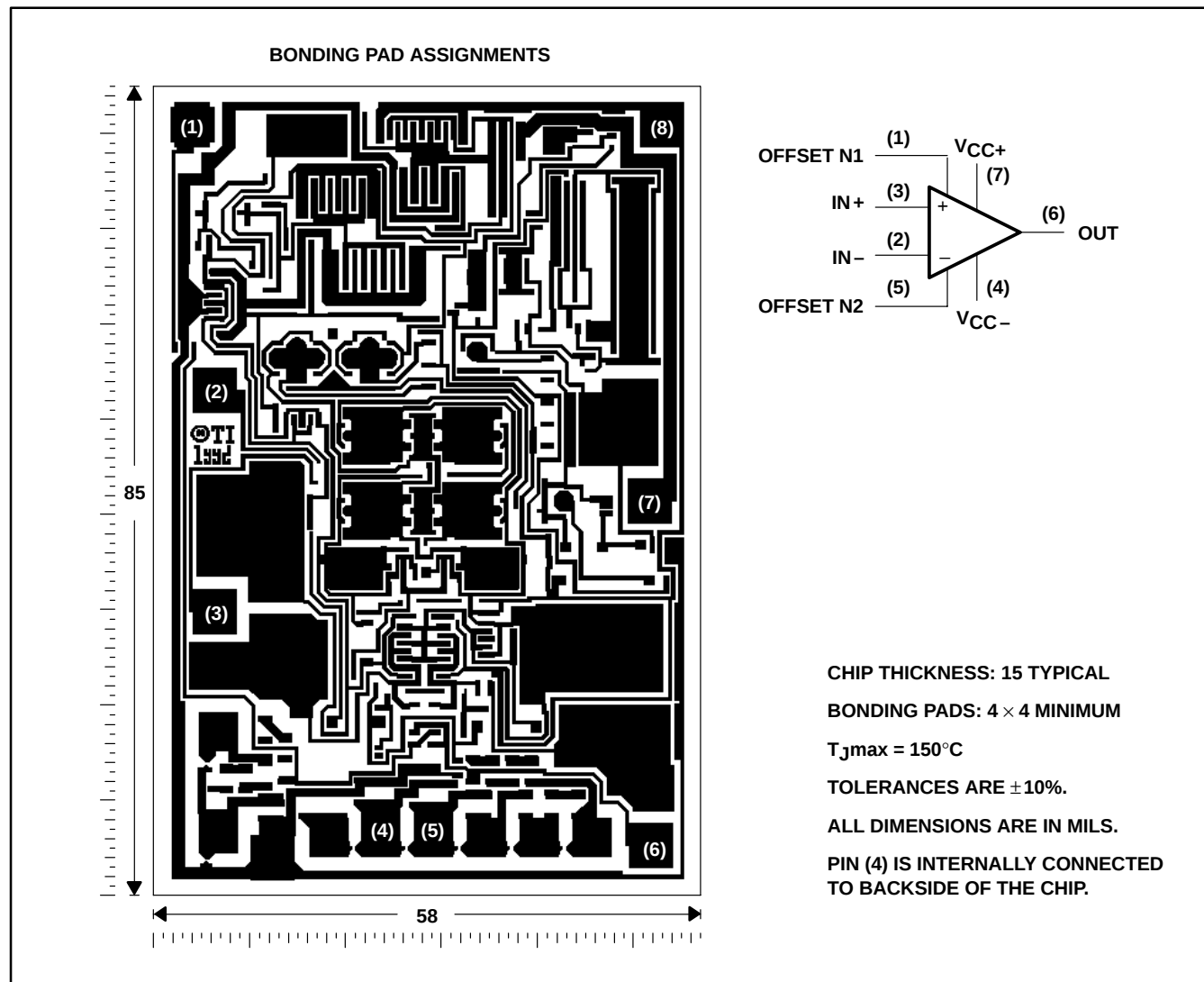
SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081Y chip information

This chip, when properly assembled, displays characteristics similar to the TLE2081. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.

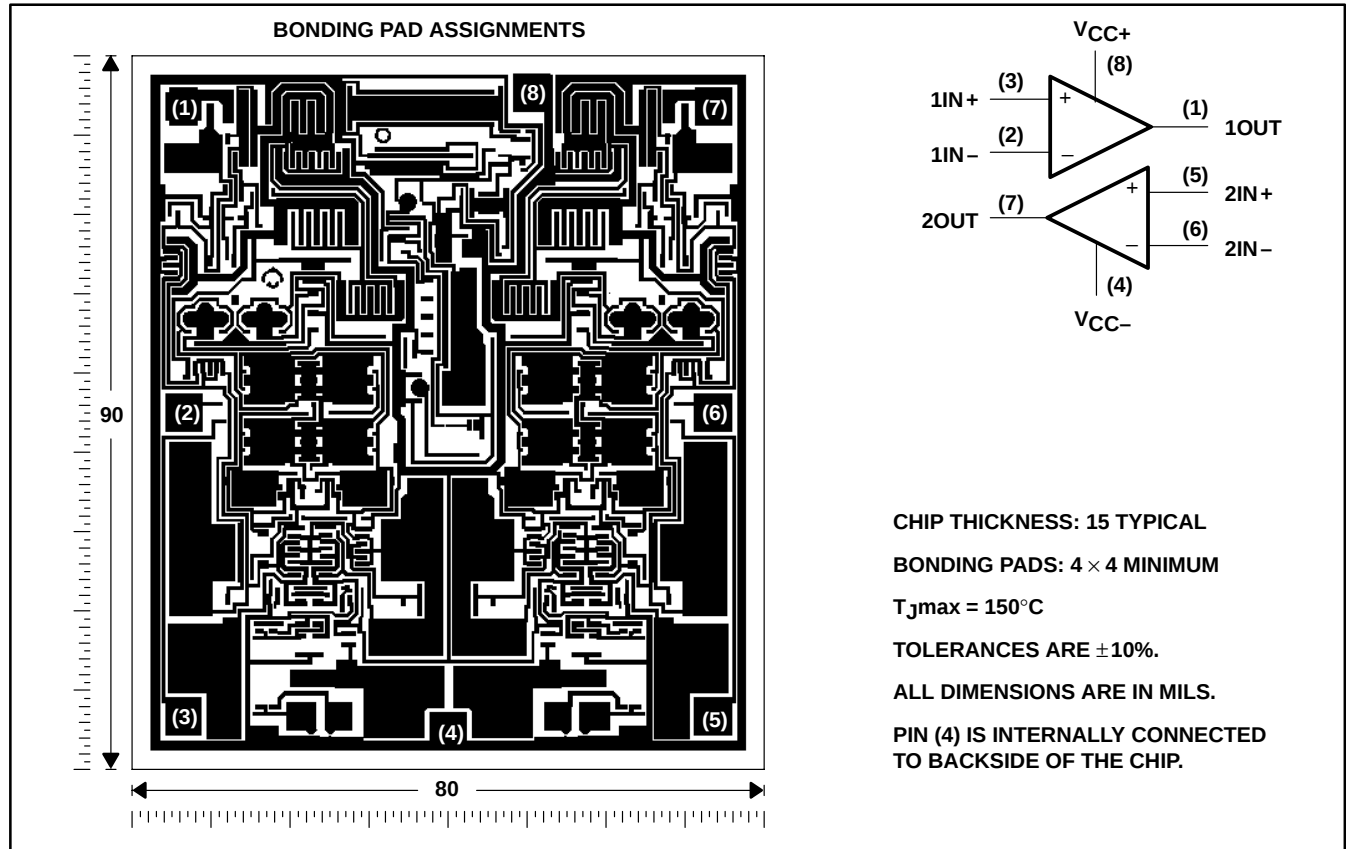


TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082Y chip information

This chip, when properly assembled, displays characteristics similar to the TLE2082. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.

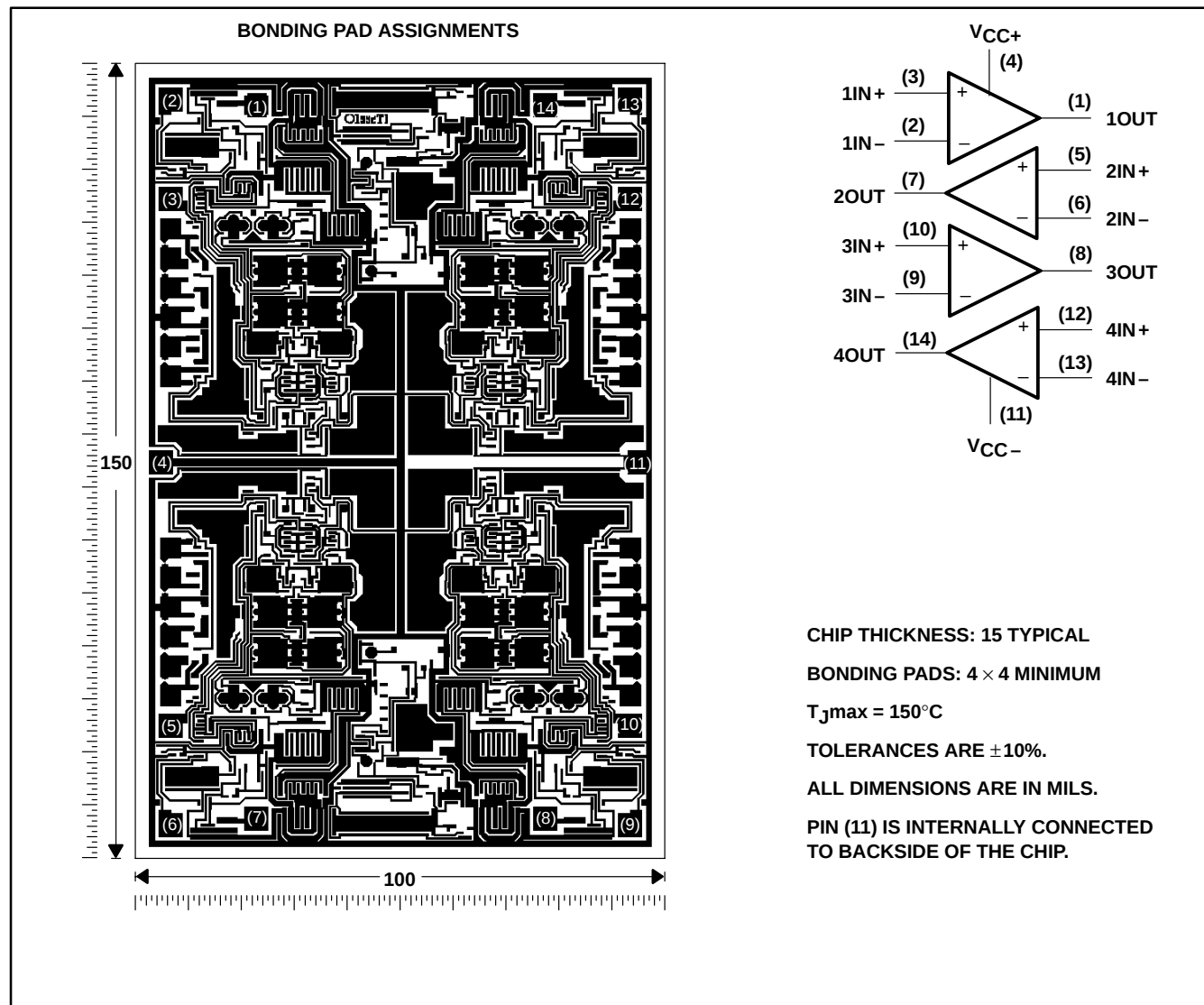


TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

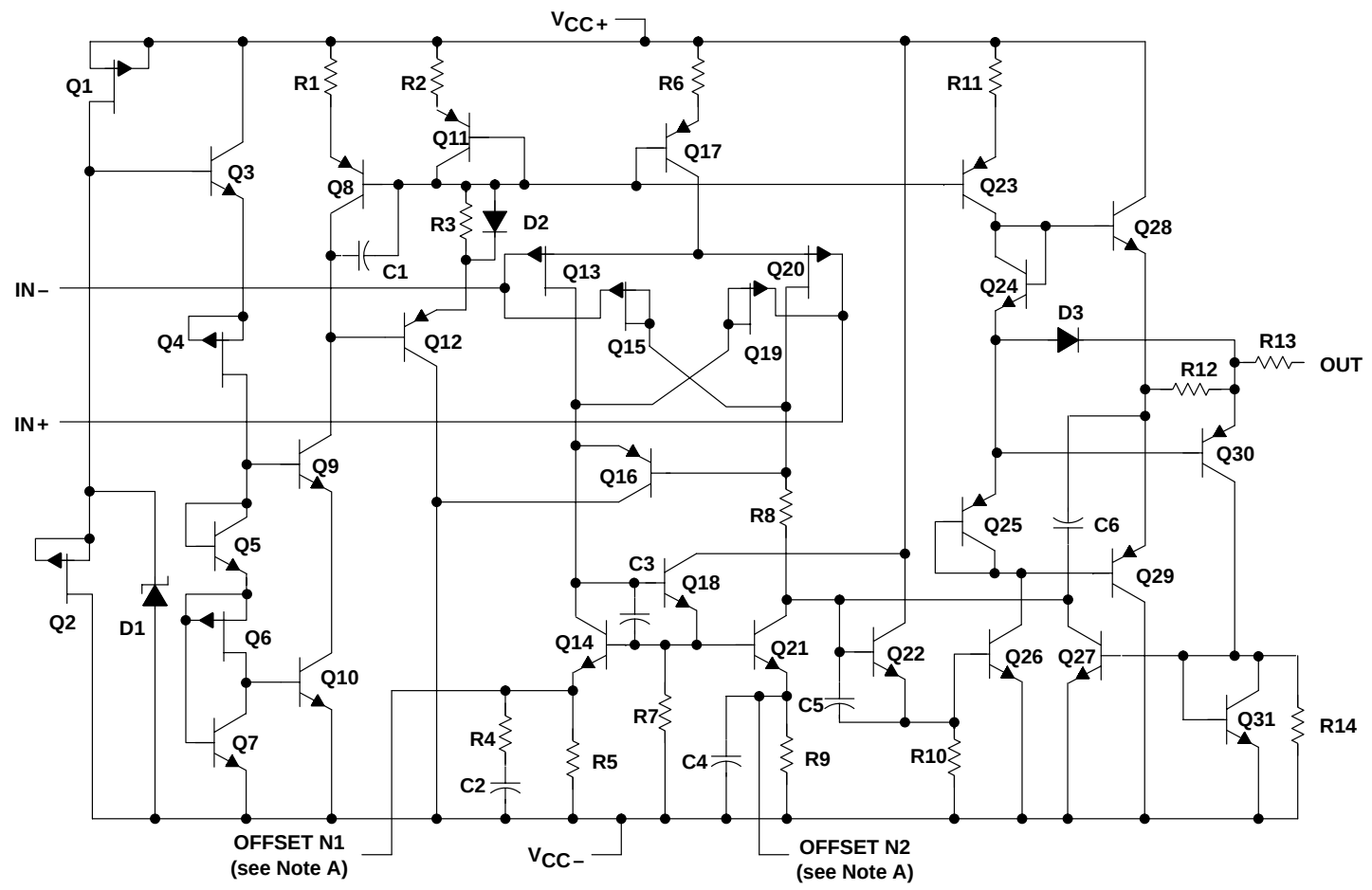
SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2084Y chip information

This chip, when properly assembled, displays characteristics similar to the TLE2084. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



equivalent schematic (each channel)



NOTE A: OFFSET N1 and OFFSET N2 are only available on the TLE2081x devices.

ACTUAL DEVICE COMPONENT COUNT			
COMPONENT	TLE2081	TLE2082	TLE2084
Transistors	33	57	114
Resistors	25	37	74
Diodes	8	5	10
Capacitors	6	11	22

TLE208x, TLE208xA, TLE208xY

EXCALIBUR HIGH-SPEED JFET-INPUT

OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{CC+} (see Note 1)	19 V
Supply voltage, V_{CC-} (see Note 1)	–19 V
Differential input voltage range, V_{ID} (see Note 2)	V_{CC+} to V_{CC-}
Input voltage range, V_I (any input)	V_{CC+} to V_{CC-}
Input current, I_I (each input)	± 1 mA
Output current, I_O (each output)	± 80 mA
Total current into V_{CC+}	160 mA
Total current out of V_{CC-}	160 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	–40°C to 85°C
M suffix	–55°C to 125°C
Storage temperature range	–65°C to 150°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DW or N package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J package	300°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .

2. Differential voltages are at $IN+$ with respect to $IN-$.

3. The output can be shorted to either supply. Temperatures and/or supply voltages must be limited to ensure that the maximum dissipation rate is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW
DW	1025 mW	8.2 mW/°C	656 mW	533 mW	205 mW
FK	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
J	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
N	1150 mW	9.2 mW/°C	736 mW	598 mW	230 mW
P	1000 mW	8.0 mW/°C	640 mW	344 mW	200 mW

recommended operating conditions

		C SUFFIX		I SUFFIX		M SUFFIX		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, $V_{CC\pm}$		± 2.25	± 19	± 2.25	± 19	± 2.25	± 19	V
Common-mode input voltage, V_{IC}	$V_{CC\pm} = \pm 5$ V	–0.9	5	–0.8	5	–0.8	5	V
	$V_{CC\pm} = \pm 15$ V	–10.9	15	–10.8	15	–10.8	15	
Operating free-air temperature, T_A		0	70	–40	85	–55	125	°C



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081C			TLE2081AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0,$ $R_S = 50 \Omega$	25°C	0.34	6		0.3	3		mV
		Full range			8			5	
α_{VIO} Temperature coefficient of input offset voltage		Full range	3.2	29		3.2	29		$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0,$ See Figure 4	25°C	5	100		5	100		nA
		Full range			1.4			1.4	
I_{IB} Input bias current		25°C	15	175		15	175		nA
		Full range			5			5	
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9		V
		Full range	5 to -0.9			5 to -0.9			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	3.8	4.1		3.8	4.1		V
		Full range	3.7			3.7			
	$I_O = -2$ mA	25°C	3.5	3.9		3.5	3.9		
		Full range	3.4			3.4			
	$I_O = -20$ mA	25°C	1.5	2.3		1.5	2.3		
		Full range	1.5			1.5			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-3.5	-4.2		-3.5	-4.2		V
		Full range	-3.4			-3.4			
	$I_O = 2$ mA	25°C	-3.7	-4.1		-3.7	-4.1		
		Full range	-3.6			-3.6			
	$I_O = 20$ mA	25°C	-1.5	-2.4		-1.5	-2.4		
		Full range	-1.5			-1.5			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3$ V	$R_L = 600 \Omega$	25°C	80	91	80	91		dB
			Full range	79		79			
		$R_L = 2$ k Ω	25°C	90	100	90	100		
			Full range	89		89			
		$R_L = 10$ k Ω	25°C	95	106	95	106		
			Full range	94		94			
r_i Input resistance	$V_{IC} = 0$	25°C		10^{12}			10^{12}		Ω
c_i Input capacitance	$V_{IC} = 0,$ See Figure 5	Common mode	25°C	11		11			pF
		Differential	25°C	2.5		2.5			
z_o Open-loop output impedance	$f = 1$ MHz	25°C		80			80		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0, R_S = 50 \Omega$	25°C	70	89		70	89		dB
		Full range	68			68			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5$ V to ± 15 V, $V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99		dB
		Full range	80			80			

† Full range is 0°C to 70°C.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081C			TLE2081AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
		Full range			2.2			2.2	
I_{OS} Short-circuit output current	$V_O = 0$	25°C		–35			–35		mA
	$V_{ID} = 1$ V $V_{ID} = -1$ V			45			45		

† Full range is 0°C to 70°C.

TLE2081C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081C			TLE2081AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR+ Positive slew rate	$V_{O(PP)} = \pm 2.3$ V, $A_{VD} = -1$, $R_L = 2$ k Ω , $C_L = 100$ pF, See Figure 1	25°C		35			35		V/ μ s
		Full range		23			23		
SR– Negative slew rate		25°C		38			38		V/ μ s
		Full range		23			23		
t_s Settling time	$A_{VD} = -1$, 2-V step, $R_L = 1$ k Ω , $C_L = 100$ pF	25°C		0.25			0.25		μ s
	To 10 mV To 1 mV			0.4			0.4		
V_n Equivalent input noise voltage	$R_S = 20$ Ω , See Figure 3	25°C		28			28		nV/ $\sqrt{\text{Hz}}$
				11.6			11.6		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage		25°C		6			6		μ V
				0.6			0.6		
I_n Equivalent input noise current	$V_{IC} = 0$, $f = 10$ kHz	25°C		2.8			2.8		fA/ $\sqrt{\text{Hz}}$
THD + N Total harmonic distortion plus noise	$V_{O(PP)} = 5$ V, $A_{VD} = 10$, $f = 1$ kHz, $R_L = 2$ k Ω , $R_S = 25$ Ω	25°C		0.013%			0.013%		
B_1 Unity-gain bandwidth	$V_I = 10$ mV, $R_L = 2$ k Ω , $C_L = 25$ pF, See Figure 2	25°C		9.4			9.4		MHz
B_{OM} Maximum output-swing bandwidth	$V_{O(PP)} = 4$ V, $A_{VD} = -1$, $R_L = 2$ k Ω , $C_L = 25$ pF	25°C		2.8			2.8		MHz
ϕ_m Phase margin at unity gain	$V_I = 10$ mV, $R_L = 2$ k Ω , $C_L = 25$ pF, See Figure 2	25°C		56°			56°		

† Full range is 0°C to 70°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2081C			TLE2081AC			UNIT	
					MIN	TYP	MAX	MIN	TYP	MAX		
V _{IO}	Input offset voltage	V _{IC} = 0, R _S = 50 Ω	V _O = 0,	25°C	0.49		6	0.47		3	mV	
				Full range			8			5		
α _{VIO}	Temperature coefficient of input offset voltage			Full range	3.2		29	3.2		29	μV/°C	
I _{IO}	Input offset current	V _{IC} = 0, See Figure 4	V _O = 0,	25°C	6		100	6		100	nA	
				Full range			1.4			1.4		
I _{IB}	Input bias current			25°C	20		175	20		175	nA	
				Full range			5			5		
V _{ICR}	Common-mode input voltage range	R _S = 50 Ω		25°C	15 to −11	15 to −11.9		15 to −11	15 to −11.9		V	
				Full range	15 to −10.9			15 to −10.9				
V _{OM+}	Maximum positive peak output voltage swing	I _O = −200 μA		25°C	13.8	14.1		13.8	14.1		V	
				Full range	13.7			13.7				
		I _O = −2 mA		25°C	13.5	13.9		13.5	13.9			
				Full range	13.4			13.4				
		I _O = −20 mA		25°C	11.5	12.3		11.5	12.3			
				Full range	11.5			11.5				
V _{OM−}	Maximum negative peak output voltage swing	I _O = 200 μA		25°C	−13.8	−14.2		−13.8	−14.2		V	
				Full range	−13.7			−13.7				
		I _O = 2 mA		25°C	−13.5	−14		−13.5	−14			
				Full range	−13.4			−13.4				
		I _O = 20 mA		25°C	−11.5	−12.4		−11.5	−12.4			
				Full range	−11.5			−11.5				
A _{VD}	Large-signal differential voltage amplification	V _O = ± 10 V	R _L = 600 Ω	25°C	80	96		80	96		dB	
				Full range	79			79				
			R _L = 2 kΩ		25°C	90	109		90	109		
					Full range	89			89			
			R _L = 10 kΩ		25°C	95	118		95	118		
					Full range	94			94			
r _i	Input resistance	V _{IC} = 0		25°C	10 ¹²		10 ¹²			Ω		
c _i	Input capacitance	V _{IC} = 0, See Figure 5	Common mode	25°C	7.5		7.5			pF		
			Differential	25°C	2.5		2.5					
z _O	Open-loop output impedance	f = 1 MHz		25°C	80		80			Ω		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin} , V _O = 0, R _S = 50 Ω		25°C	80	98		80	98		dB	
				Full range	79			79				
K _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} / ΔV _{IO})	V _{CC±} = ±5 V to ±15 V, V _O = 0, R _S = 50 Ω		25°C	82	99		82	99		dB	
				Full range	80			81				

† Full range is 0°C to 70°C.



TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081C			TLE2081AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
		Full range			2.2			2.2	
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1$ V	-30	-45		-30	-45		mA
		$V_{ID} = -1$ V	30	48		30	48		

† Full range is 0°C to 70°C.

TLE2081C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2081C			TLE2081AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = 10 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	30	40		30	40		V/μs
				Full range	27			27			
SR −	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	27			27			
t _s	Settling time	A _{VD} = −1, 10-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.4			0.4			μs
			To 1 mV		1.5			1.5			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current		V _{IC} = 0, f = 10 kHz	25°C	2.8			2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise		V _{O(PP)} = 20 V, A _{VD} = 10, f = 1 kHz, R _L = 2 kΩ, R _S = 25 Ω	25°C	0.008%			0.008%			
B ₁	Unity-gain bandwidth	V _I = 10 mV, R _L = 2 kΩ, C _L = 25 pF, See Figure 2	25°C	8	10		8	10		MHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 20 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 25 pF	25°C	478	637		478	637		kHz	
φ _m	Phase margin at unity gain	V _I = 10 mV, R _L = 2 kΩ, C _L = 25 pF, See Figure 2	25°C	57°			57°				

† Full range is 0°C to 70°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081I			TLE2081AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50\ \Omega$	25°C	0.34	6		0.3	3		mV
		Full range		7.6			5.6		
α_{VIO} Temperature coefficient of input offset voltage		Full range	3.2	29		3.2	29		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0$, See Figure 4	25°C	5	100		5	100		pA
		Full range		5			5		nA
I_{IB} Input bias current		25°C	15	175		15	175		pA
		Full range		10			10		nA
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9		V
		Full range	5 to -0.8			5 to -0.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	3.8	4.1		3.8	4.1		V
		Full range	3.7			3.7			
	$I_O = -2\ \text{mA}$	25°C	3.5	3.9		3.5	3.9		
		Full range	3.4			3.4			
	$I_O = -20\ \text{mA}$	25°C	1.5	2.3		1.5	2.3		
		Full range	1.5			1.5			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-3.8	-4.2		-3.8	-4.2		V
		Full range	-3.7			-3.7			
	$I_O = 2\ \text{mA}$	25°C	-3.5	-4.1		-3.5	-4.1		
		Full range	-3.4			-3.4			
	$I_O = 20\ \text{mA}$	25°C	-1.5	-2.4		-1.5	-2.4		
		Full range	-1.5			-1.5			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	91	80	91		dB
			Full range	79		79			
		$R_L = 2\ \text{k}\Omega$	25°C	90	100	90	100		
			Full range	89		89			
		$R_L = 10\ \text{k}\Omega$	25°C	95	106	95	106		
			Full range	94		94			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω
c_i Input capacitance	$V_{IC} = 0$, See Figure 5	Common mode	25°C	11		11			pF
		Differential	25°C	2.5		2.5			
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C	80			80			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	70	89		70	89		dB
		Full range	68			68			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V}$ to $\pm 15\ \text{V}$, $V_O = 0, R_S = 50\ \Omega$	25°C	82	99		82	99		dB
		Full range	80			80			

† Full range is -40°C to 85°C .



TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081I			TLE2081AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
		Full range			2.2			2.2	
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1\text{ V}$		–35			–35		mA
		$V_{ID} = -1\text{ V}$		45			45		

† Full range is –40°C to 85°C.

TLE2081I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2081I			TLE2081AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = ±2.3 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	35			35			V/μs
				Full range	22			22			
SR −	Negative slew rate			25°C	38			38			V/μs
				Full range	22			22			
t _s	Settling time	A _{VD} = −1, 2-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.25			0.25			μs
			To 1 mV		0.4			0.4			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0, f = 10 kHz		25°C	2.8			2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 5 V, A _{VD} = 10, f = 1 kHz, R _L = 2 kΩ, R _S = 25 Ω		25°C	0.013%			0.013%			
B ₁	Unity-gain bandwidth	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	9.4			9.4			MHz
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 4 V, A _{VD} = −1, R _L = 2 kΩ , C _L = 25 pF		25°C	2.8			2.8			MHz
φ _m	Phase margin at unity gain	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	56°			56°			

† Full range is –40°C to 85°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081I			TLE2081AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0,$ $R_S = 50 \Omega,$	25°C	0.49	6		0.47	3		mV
		Full range			7.6			5.6	
α_{VIO} Temperature coefficient of input offset voltage		Full range	3.2	29		3.2	29		$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0,$ See Figure 4	25°C	6	100		6	100		pA
		Full range			5			5	nA
I_{IB} Input bias current		25°C	20	175		20	175		pA
		Full range			10			10	nA
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to –11	15 to –11.9		15 to –11	15 to –11.9		V
		Full range	15 to –10.8			15 to –10.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	13.8	14.1		13.8	14.1		V
		Full range	13.7			13.7			
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9		
		Full range	13.4			13.4			
	$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3		
		Full range	11.5			11.5			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	–13.8	–14.2		–13.8	–14.2		V
		Full range	–13.7			–13.7			
	$I_O = 2 \text{ mA}$	25°C	–13.5	–14		–13.5	–14		
		Full range	–13.4			–13.4			
	$I_O = 20 \text{ mA}$	25°C	–11.5	–12.4		–11.5	–12.4		
		Full range	–11.5			–11.5			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96	80	96		dB
			Full range	79		79			
		$R_L = 2 \text{ k}\Omega$	25°C	90	109	90	109		
			Full range	89		89			
		$R_L = 10 \text{ k}\Omega$	25°C	95	118	95	118		
			Full range	94		94			
r_i Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω
c_i Input capacitance	$V_{IC} = 0,$ See Figure 5	Common mode	25°C	7.5		7.5			pF
		Differential	25°C	2.5		2.5			
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0,$ $R_S = 50 \Omega$	25°C	80	98		80	98		dB
		Full range	79			79			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V},$ $V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99		dB
		Full range	80			80			

† Full range is $-40^\circ C$ to $85^\circ C$.



TLE208x, TLE208xA, TLE208xY

EXCALIBUR HIGH-SPEED JFET-INPUT

OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081I			TLE2081AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
		Full range			2.2			2.2	
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1$ V	–30	–45		–30	–45		mA
		$V_{ID} = -1$ V	30	48		30	48		

† Full range is –40°C to 85°C.

TLE2081I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2081I			TLE2081AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = ±10 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	30	40		30	40		V/μs
				Full range	24			24			
SR −	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	24			24			
t _s	Settling time	A _{VD} = −1, 10-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.4			0.4			μs
		To 1 mV	1.5			1.5					
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0, f = 10 kHz		25°C	2.8			2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, A _{VD} = 10, f = 1 kHz, R _L = 2 kΩ, R _S = 25 Ω		25°C	0.008%			0.008%			
B ₁	Unity-gain bandwidth	V _I = 10 mV, C _L = 25 pF, R _L = 2 kΩ, See Figure 2	25°C	8	10		8	10		MHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 20 V, R _L = 2 kΩ, A _{VD} = −1, C _L = 25 pF	25°C	478	637		478	637		kHz	
φ _m	Phase margin at unity gain	V _I = 10 mV, C _L = 25 pF, R _L = 2 kΩ, See Figure 2	25°C	57°			57°				

† Full range is –40°C to 85°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081M			TLE2081AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50\Omega$	25°C		0.34	6		0.3	3	mV
		Full range			11.2			8.2	
α_{VIO} Temperature coefficient of input offset voltage		Full range		3.2	29*		3.2	29*	$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C		5	100		5	100	pA
		Full range			20			20	nA
I_{IB} Input bias current		25°C		15	175		15	175	pA
		Full range			65			65	nA
V_{ICR} Common-mode input voltage range	$R_S = 50\Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9		V
		Full range	5 to -0.8			5 to -0.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\mu A$	25°C	3.8	4.1		3.8	4.1		V
		Full range	3.6			3.6			
	$I_O = -2\text{ mA}$	25°C	3.5	3.9		3.5	3.9		
		Full range	3.3			3.3			
	$I_O = -20\text{ mA}$	25°C	1.5	2.3		1.5	2.3		
		Full range	1.4			1.4			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\mu A$	25°C	-3.8	-4.2		-3.8	-4.2		V
		Full range	-3.6			-3.6			
	$I_O = 2\text{ mA}$	25°C	-3.5	-4.1		-3.5	-4.1		
		Full range	-3.3			-3.3			
	$I_O = 20\text{ mA}$	25°C	-1.5	-2.4		-1.5	-2.4		
		Full range	-1.4			-1.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\text{ V}$	$R_L = 600\Omega$	25°C	80	91	80	91		dB
			Full range	78		78			
		$R_L = 2\text{ k}\Omega$	25°C	90	100	90	100		
			Full range	88		88			
		$R_L = 10\text{ k}\Omega$	25°C	95	106	95	106		
			Full range	93		93			
r_i Input resistance	$V_{IC} = 0$	25°C		10^{12}		10^{12}			Ω
c_i Input capacitance	$V_{IC} = 0, \text{See Figure 5}$	Common mode	25°C		11		11		pF
		Differential	25°C		2.5		2.5		
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		80		80			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\Omega$	25°C	70	89		70	89		dB
		Full range	68			68			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\text{ V to } \pm 15\text{ V}, V_O = 0, R_S = 50\Omega$	25°C	82	99		82	99		dB
		Full range	80			80			

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is $-55^\circ C$ to $125^\circ C$.



TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081M			TLE2081AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.6	2.2	1.35	1.6	2.2	mA
		Full range			2.2			2.2	
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1$ V		–35			–35		mA
		$V_{ID} = -1$ V		45			45		

† Full range is –55°C to 125°C.

TLE2081M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2081M			TLE2081AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = ±2.3 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	35			35			V/μs
				Full range	20*			20*			
SR −	Negative slew rate			25°C	38			38			V/μs
				Full range	20*			20*			
t _s	Settling time	A _{VD} = −1, 2-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.25			0.25			μs
			To 1 mV		0.4			0.4			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0, f = 10 kHz		25°C	2.8			2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 5 V, f = 1 kHz, R _S = 25 Ω	A _{VD} = 10, R _L = 2 kΩ,	25°C	0.013%			0.013%			
B ₁	Unity-gain bandwidth	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	9.4			9.4			MHz
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 4 V, R _L = 2 kΩ ,	A _{VD} = −1, C _L = 25 pF	25°C	2.8			2.8			MHz
ϕ _m	Phase margin at unity gain	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	56°			56°			

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is –55°C to 125°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2081M			TLE2081AM			UNIT	
					MIN	TYP	MAX	MIN	TYP	MAX		
V _{IO}	Input offset voltage	V _{IC} = 0, R _S = 50 Ω	V _O = 0,	25°C	0.49			6	0.47		3	mV
				Full range				11.2			8.2	
α _{VIO}	Temperature coefficient of input offset voltage			Full range	3.2			29*	3.2		29*	μV/°C
I _{IO}	Input offset current	V _{IC} = 0, See Figure 4	V _O = 0,	25°C	6			100	6		100	pA
				Full range				20			20	nA
I _{IB}	Input bias current			25°C	20			175	20		175	pA
				Full range				65			65	nA
V _{ICR}	Common-mode input voltage range	R _S = 50 Ω		25°C	15 to −11	15 to −11.9			15 to −11	15 to −11.9	V	
				Full range	15 to −10.8				15 to −10.8			
V _{OM+}	Maximum positive peak output voltage swing	I _O = −200 μA		25°C	13.8	14.1			13.8	14.1	V	
				Full range	13.6				13.6			
		I _O = −2 mA		25°C	13.5	13.9			13.5	13.9		
				Full range	13.3				13.3			
		I _O = −20 mA		25°C	11.5	12.3			11.5	12.3		
				Full range	11.4				11.4			
V _{OM−}	Maximum negative peak output voltage swing	I _O = 200 μA		25°C	−13.8	−14.2			−13.8	−14.2	V	
				Full range	−13.6				−13.6			
		I _O = 2 mA		25°C	−13.5	−14			−13.5	−14		
				Full range	−13.3				−13.3			
		I _O = 20 mA		25°C	−11.5	−12.4			−11.5	−12.4		
				Full range	−11.4				−11.4			
A _{VD}	Large-signal differential voltage amplification	V _O = ± 10 V	R _L = 600 Ω	25°C	80	96			80	96	dB	
				Full range	78				78			
			R _L = 2 kΩ		25°C	90	109			90		109
					Full range	88				88		
			R _L = 10 kΩ		25°C	95	118			95		118
					Full range	93				93		
r _i	Input resistance	V _{IC} = 0		25°C	10 ¹²			10 ¹²		Ω		
c _i	Input capacitance	V _{IC} = 0, See Figure 5	Common mode	25°C	7.5			7.5		pF		
			Differential	25°C	2.5			2.5				
z _O	Open-loop output impedance	f = 1 MHz		25°C	80			80		Ω		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin} , V _O = 0, R _S = 50 Ω		25°C	80	98			80	98	dB	
				Full range	78				78			
K _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})	V _{CC±} = ±5 V to ±15 V, V _O = 0, R _S = 50 Ω		25°C	82	99			82	99	dB	
				Full range	80				80			

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is $-55^\circ C$ to $125^\circ C$.



TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)(continued)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2081M			TLE2081AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Supply current	$V_O = 0$, No load	25°C	1.35	1.7	2.2	1.35	1.7	2.2	mA
		Full range			2.2			2.2	
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1$ V	–30	–45		–30	–45		mA
		$V_{ID} = -1$ V	30	48		30	48		

† Full range is –55°C to 125°C.

TLE2081M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2081M			TLE2081AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = 10 V, A _{VD} = −1, C _L = 100 pF, R _L = 2 kΩ, See Figure 1		25°C	30	40		30	40		V/μs
	Full range			22			22				
SR −	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	22			22			
t _s	Settling time	A _{VD} = −1, 10-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.4			0.4			μs
			To 1 mV		1.5			1.5			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0,	f = 10 kHz	25°C	2.8			2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, A _{VD} = 10, f = 1 kHz, R _S = 25 Ω		25°C	0.008%			0.008%			
B ₁	Unity-gain bandwidth	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	8*	10		8*	10		MHz
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 20 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 25 pF		25°C	478*	637		478*	637		kHz
φ _m	Phase margin at unity gain	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	57°			57°			

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is –55°C to 125°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2081Y electrical characteristics at $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2081Y			UNIT
				MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$		0.49	6		mV
I_{IO}	Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4		6	100		pA
I_{IB}	Input bias current			20	175		
V_{ICR}	Common-mode input voltage range	$R_S = 50\ \Omega$		15 to –11	15 to 11.9		V
V_{OM+}	Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$		13.8	14.1		V
		$I_O = -2\ \text{mA}$		13.5	13.9		
		$I_O = -20\ \text{mA}$		11.5	12.3		
V_{OM-}	Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$		–13.8	–14.2		V
		$I_O = 2\ \text{mA}$		–13.5	–14		
		$I_O = 20\ \text{mA}$		–11.5	–12.4		
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$	$R_L = 600\ \Omega$	80	96		dB
			$R_L = 2\ \text{k}\Omega$	90	109		
			$R_L = 10\ \text{k}\Omega$	95	118		
r_i	Input resistance	$V_{IC} = 0$		10	12		Ω
c_i	Input capacitance	$V_{IC} = 0$, See Figure 5	Common mode	7.5			pF
			Differential	2.5			
z_o	Open-loop output impedance	$f = 1\ \text{MHz}$		80			Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR\min}$, $V_O = 0$, $R_S = 50\ \Omega$		80	98		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V}$ to $\pm 15\ \text{V}$, $V_O = 0$, $R_S = 50\ \Omega$		82	99		dB
I_{CC}	Supply current	$V_O = 0$, No load		1.35	1.7	2.2	mA
I_{OS}	Short-circuit output current	$V_O = 0$	$V_{ID} = 1\ \text{V}$	–30	–45		mA
			$V_{ID} = -1\ \text{V}$	30	48		

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER			TEST CONDITIONS		T _A [†]	TLE2082C			TLE2082AC			UNIT		
						MIN	TYP	MAX	MIN	TYP	MAX			
V _{IO}	Input offset voltage		V _{IC} = 0, R _S = 50 Ω	V _O = 0,	25°C	0.9		6	0.65		4	mV		
					Full range	8.1		5.1						
α _{VIO}	Temperature coefficient of input offset voltage				Full range	2.3		25	2.3		25	μV/°C		
I _{IO}	Input offset current		V _{IC} = 0, See Figure 4	V _O = 0,	25°C	5		100	5		100	pA		
					Full range	1.4		1.4				nA		
I _{IB}	Input bias current				25°C	15		175	15		175	pA		
					Full range	5		5				nA		
V _{ICR}	Common-mode input voltage range		R _S = 50 Ω		25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9		V		
					Full range	5 to -0.9		5 to -0.9						
V _{OM+}	Maximum positive peak output voltage swing		I _O = -200 μA		25°C	3.8	4.1		3.8	4.1		V		
					Full range	3.7			3.7					
			I _O = -2 mA		25°C	3.5	3.9		3.5	3.9				
					Full range	3.4			3.4					
			I _O = -20 mA		25°C	1.5	2.3		1.5	2.3				
					Full range	1.5			1.5					
V _{OM-}	Maximum negative peak output voltage swing		I _O = 200 μA		25°C	-3.8	-4.2		-3.8	-4.2		V		
					Full range	-3.7			-3.7					
			I _O = 2 mA		25°C	-3.5	-4.1		-3.5	-4.1				
					Full range	-3.4			-3.4					
			I _O = 20 mA		25°C	-1.5	-2.4		-1.5	-2.4				
					Full range	-1.5			-1.5					
A _{VD}	Large-signal differential voltage amplification		V _O = ± 2.3 V	R _L = 600 Ω	25°C	80	91		80	91		dB		
					Full range	79			79					
					R _L = 2 kΩ		25°C	90	100		90		100	
							Full range	89			89			
					R _L = 10 kΩ		25°C	95	106		95		106	
							Full range	94			94			
r _i	Input resistance		V _{IC} = 0		25°C	10 ¹²		10 ¹²			Ω			
c _i	Input capacitance	Common mode	V _{IC} = 0,	See Figure 5	25°C	11		11			pF			
		Differential			25°C	2.5		2.5						
z _O	Open-loop output impedance		f = 1 MHz		25°C	80		80			Ω			
CMRR	Common-mode rejection ratio		V _{IC} = V _{ICR} ^{min} , V _O = 0, R _S = 50 Ω		25°C	70	89		70	89		dB		
					Full range	68			68					
k _{SVR}	Supply-voltage rejection ratio(ΔV _{CC±} /ΔV _{IO})		V _{CC±} = ±5 V to ±15 V, V _O = 0, R _S = 50 Ω		25°C	82	99		82	99		dB		
					Full range	80			80					
I _{CC}	Supply current (both channels)		V _O = 0,	No load	25°C	2.7	2.9	3.9	2.7	2.9	3.9	mA		
					Full range	3.9		3.9						

† Full range is 0°C to 70°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A	TLE2082C			TLE2082AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C		120			120		dB
I_{OS} Short-circuit output current	$V_O = 0$	25°C		–35			–35		mA
				45			45		

TLE2082C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2082C			TLE2082AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = ±2.3 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	35			35			V/μs
				Full range	22			22			
SR −	Negative slew rate			25°C	38			38			V/μs
				Full range	22			22			
t _s	Settling time	A _{VD} = −1, 2-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.25			0.25			μs
			To 1 mV		0.4			0.4			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current		V _{IC} = 0, f = 10 kHz	25°C	2.8			2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise		V _{O(PP)} = 5 V, A _{VD} = 10, f = 1 kHz, R _L = 2 kΩ, R _S = 25 Ω	25°C	0.013%			0.013%			
B ₁	Unity-gain bandwidth	V _I = 10 mV, R _L = 2 kΩ, C _L = 25 pF, See Figure 2	25°C	9.4			9.4			MHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 4 V, A _{VD} = −1, R _L = 2 kΩ , C _L = 25 pF	25°C	2.8			2.8			MHz	
φ _m	Phase margin at unity gain	V _I = 10 mV, R _L = 2 kΩ, C _L = 25 pF, See Figure 2	25°C	56°			56°				

[†] Full range is 0°C to 70°C.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER			TEST CONDITIONS	T _A [†]	TLE2082C			TLE2082AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage		V _{IC} = 0, V _O = 0, R _S = 50 Ω	25°C	1.1 7		0.7 4		mV		
				Full range	8.1		5.1				
αV _{IO}	Temperature coefficient of input offset voltage			Full range	2.4 25		2.4 25		μV/°C		
I _{IO}	Input offset current		V _{IC} = 0, V _O = 0, See Figure 4	25°C	6 100		6 100		pA		
				Full range	1.4		1.4		nA		
I _{IB}	Input bias current			25°C	20 175		20 175		pA		
				Full range	5		5		nA		
V _{ICR}	Common-mode input voltage range		R _S = 50 Ω	25°C	15 to −11 15 to −11.9		15 to −11 15 to −11.9		V		
				Full range	15 to −10.9		15 to −10.9				
V _{OM+}	Maximum positive peak output voltage swing		I _O = −200 μA	25°C	13.8 14.1		13.8 14.1		V		
				Full range	13.6		13.6				
			I _O = −2 mA	25°C	13.5 13.9		13.5 13.9				
				Full range	13.4		13.4				
			I _O = −20 mA	25°C	11.5 12.3		11.5 12.3				
				Full range	11.5		11.5				
V _{OM−}	Maximum negative peak output voltage swing		I _O = 200 μA	25°C	−13.8 −14.2		−13.8 −14.2		V		
				Full range	−13.7		−13.7				
			I _O = 2 mA	25°C	−13.5 −14		−13.5 −14				
				Full range	−13.4		−13.4				
			I _O = 20 mA	25°C	−11.5 −12.4		−11.5 −12.4				
				Full range	−11.5		−11.5				
A _{VD}	Large-signal differential voltage amplification		V _O = ± 10 V	R _L = 600 Ω	25°C	80 96		80 96		dB	
					Full range	79		79			
				R _L = 2 kΩ	25°C	90 109		90 109			
					Full range	89		89			
				R _L = 10 kΩ	25°C	95 118		95 118			
					Full range	94		94			
r _i	Input resistance		V _{IC} = 0	25°C	10 ¹²		10 ¹²		Ω		
c _i	Input capacitance	Common mode	V _{IC} = 0, See Figure 5	25°C	7.5		7.5		pF		
		Differential		25°C	2.5		2.5				
z _O	Open-loop output impedance		f = 1 MHz	25°C	80		80		Ω		
CMRR	Common-mode rejection ratio		V _{IC} = V _{ICRmin} , V _O = 0, R _S = 50 Ω	25°C	80 98		80 98		dB		
				Full range	79		79				
k _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})		V _{CC±} = ±5 V to ±15 V, V _O = 0, R _S = 50 Ω	25°C	82 99		82 99		dB		
				Full range	81		81				

† Full range is 0°C to 70°C.

TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T _A	TLE2082C			TLE2082AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I _{CC}	Supply current (both channels)	V _O = 0,	No load	25°C	2.7	3.1	3.9	2.7	3.1	3.9	mA
				Full range	3.9			3.9			
Crosstalk attenuation		V _I C = 0,	R _L = 2 kΩ	25°C	120			120			dB
I _{OS}	Short-circuit output current	V _O = 0	V _{ID} = 1 V	25°C	−30	−45		−30	−45		mA
			V _{ID} = −1 V		30	48		30	48		

TLE2082C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2082C			TLE2082AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = 10 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	28	40		28	40		V/μs
	Full range			25		25					
SR −	Negative slew rate			25°C	30	45		30	45		V/μs
	Full range			25		25					
t _s	Settling time	A _{VD} = −1, 10-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.4			0.4			μs
			To 1 mV		1.5			1.5			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0, f = 10 kHz	25°C	2.8			2.8			fA/√Hz	
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, A _{VD} = 10, f = 1 kHz, R _L = 2 kΩ, R _S = 25 Ω	25°C	0.008%			0.008%				
B ₁	Unity-gain bandwidth	V _I = 10 mV, C _L = 25 pF, R _L = 2 kΩ, See Figure 2	25°C	8	10		8	10		MHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 20 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 25 pF	25°C	478	637		478	637		kHz	
φ _m	Phase margin at unity gain	V _I = 10 mV, C _L = 25 pF, R _L = 2 kΩ, See Figure 2	25°C	57°			57°				

† Full range is 0°C to 70°C.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2082I			TLE2082AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50\ \Omega$	25°C	0.9	7		0.65	4		mV
		Full range		8.5			5.5		
α_{VIO} Temperature coefficient of input offset voltage		Full range	2.4	25		2.4	25		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	5	100		5	100		pA
		Full range		5			5		nA
I_{IB} Input bias current		25°C	15	175		15	175		pA
		Full range		10			10		nA
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9		V
		Full range	5 to -0.8			5 to -0.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$	25°C	3.8	4.1		3.8	4.1		V
		Full range	3.7			3.7			
	$I_O = -2\ \text{mA}$	25°C	3.5	3.9		3.5	3.9		
		Full range	3.4			3.4			
	$I_O = -20\ \text{mA}$	25°C	1.5	2.3		1.5	2.3		
		Full range	1.5			1.5			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$	25°C	-3.8	-4.2		-3.8	-4.2		V
		Full range	-3.7			-3.7			
	$I_O = 2\ \text{mA}$	25°C	-3.5	-4.1		-3.5	-4.1		
		Full range	-3.4			-3.4			
	$I_O = 20\ \text{mA}$	25°C	-1.5	-2.4		-1.5	-2.4		
		Full range	-1.5			-1.5			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3\ \text{V}$	$R_L = 600\ \Omega$	25°C	80	91	80	91		dB
			Full range	79		79			
		$R_L = 2\ \text{k}\Omega$	25°C	90	100	90	100		
			Full range	89		89			
		$R_L = 10\ \text{k}\Omega$	25°C	95	106	95	106		
			Full range	94		94			
r_i Input resistance	$V_{IC} = 0$	25°C		10^{12}			10^{12}		Ω
c_i Input capacitance	Common mode	25°C		11			11		pF
	Differential	25°C		2.5			2.5		
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C		80			80		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50\ \Omega$	25°C	70	89		70	89		dB
		Full range	68			68			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V}$ to $\pm 15\ \text{V}, V_O = 0, R_S = 50\ \Omega$	25°C	82	99		82	99		dB
		Full range	80			80			
I_{CC} Supply current (both channels)	$V_O = 0, \text{No load}$	25°C	2.7	2.9	3.9	2.7	2.9	3.9	mA
		Full range		3.9			3.9		

† Full range is -40°C to 85°C .



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$ (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	T_A	TLE2082I			TLE2082AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
Crosstalk attenuation	$V_{IC} = 0$, $R_L = 2\text{ k}\Omega$	25°C		120			120		dB
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1\text{ V}$		-35			-35		mA
		$V_{ID} = -1\text{ V}$		45			45		

TLE2082I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5\text{ V}$

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2082I			TLE2082AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = ±2.3 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	35			35			V/μs
				Full range	20			20			
SR −	Negative slew rate			25°C	38			38			V/μs
				Full range	20			20			
t _s	Settling time	A _{VD} = −1, 2-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.25			0.25			μs
			To 1 mV		0.4			0.4			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current		V _{IC} = 0, f = 10 kHz	25°C	2.8			2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise		V _{O(PP)} = 5 V, A _{VD} = 10, f = 1 kHz, R _L = 2 kΩ, R _S = 25 Ω	25°C	0.013%			0.013%			
B ₁	Unity-gain bandwidth	V _I = 10 mV, R _L = 2 kΩ, C _L = 25 pF, See Figure 2	25°C	9.4			9.4			MHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 4 V, A _{VD} = −1, R _L = 2 kΩ , C _L = 25 pF	25°C	2.8			2.8			MHz	
φ _m	Phase margin at unity gain	V _I = 10 mV, R _L = 2 kΩ, C _L = 25 pF, See Figure 2	25°C	56°			56°				

† Full range is 40°C to 85°C.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2082I			TLE2082AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	1.1	7		0.7	4		mV
		Full range		8.5			5.5		
α_{VIO} Temperature coefficient of input offset voltage		Full range	2.4	25		2.4	25		$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	6	100		6	100		pA
		Full range		5			5		nA
I_{IB} Input bias current		25°C	20	175		20	175		pA
		Full range		10			10		nA
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9		V
		Full range	15 to -10.8			15 to -10.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	13.8	14.1		13.8	14.1		V
		Full range	13.7			13.7			
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9		
		Full range	13.4			13.4			
	$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3		
		Full range	11.5			11.5			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-13.8	-14.2		-13.8	-14.2		V
		Full range	-13.7			-13.7			
	$I_O = 2 \text{ mA}$	25°C	-13.5	-14		-13.5	-14		
		Full range	-13.4			-13.4			
	$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4		-11.5	-12.4		
		Full range	-11.5			-11.5			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96	80	96		dB
			Full range	79		79			
		$R_L = 2 \text{ k}\Omega$	25°C	90	109	90	109		
			Full range	89		89			
		$R_L = 10 \text{ k}\Omega$	25°C	95	118	95	118		
			Full range	94		94			
r_i Input resistance	$V_{IC} = 0$	25°C		10^{12}			10^{12}		Ω
c_i Input capacitance	Common mode	$V_{IC} = 0, \text{See Figure 5}$	25°C	7.5		7.5			pF
	Differential		25°C	2.5		2.5			
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C		80			80		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50 \Omega$	25°C	80	98		80	98		dB
		Full range	79			79			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}, V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99		dB
		Full range	80			80			

† Full range is $-40^\circ C$ to $85^\circ C$.

TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T _A	TLE2082I			TLE2082AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I _{CC}	Supply current (both channels)	V _O = 0,	No load	25°C	2.7	3.1	3.9	2.7	3.1	3.9	mA
				Full range	3.9			3.9			
Crosstalk attenuation		V _{IC} = 0,	R _L = 2 kΩ	25°C	120			120			dB
I _{OS}	Short-circuit output current	V _O = 0	V _{ID} = 1 V	25°C	-30	-45		-30	-45		mA
			V _{ID} = -1 V		30	48		30	48		

TLE2082I operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2082I			TLE2082AI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = 10 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	28	40		28	40		V/μs
	Full range			22		22					
SR −	Negative slew rate			25°C	30	45		30	45		V/μs
	Full range			22		22					
t _s	Settling time	A _{VD} = −1, 10-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.4			0.4			μs
			To 1 mV		1.5			1.5			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0, f = 10 kHz	25°C	2.8			2.8			fA/√Hz	
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, A _{VD} = 10, f = 1 kHz, R _S = 25 Ω	25°C	0.008%			0.008%				
B ₁	Unity-gain bandwidth	V _I = 10 mV, C _L = 25 pF, R _L = 2 kΩ, See Figure 2	25°C	8	10		8	10		MHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 20 V, R _L = 2 kΩ, A _{VD} = −1, C _L = 25 pF	25°C	478	637		478	637		kHz	
φ _m	Phase margin at unity gain	V _I = 10 mV, C _L = 25 pF, R _L = 2 kΩ, See Figure 2	25°C	57°			57°				

† Full range is -40°C to 85°C .

TLE208x, TLE208xA, TLE208xY

EXCALIBUR HIGH-SPEED JFET-INPUT

OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2082M			TLE2082AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	0.9	7		0.65	4		mV
		Full range			9.5			6.5	
α_{VIO} Temperature coefficient of input offset voltage		Full range	2.3	25*		2.3	25*		$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	5	100		5	100		pA
		Full range			20			20	nA
I_{IB} Input bias current		25°C	15	175		15	175		pA
		Full range			60			60	nA
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	5 to -1	5 to -1.9		5 to -1	5 to -1.9		V
		Full range	5 to -0.8			5 to -0.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	3.8	4.1		3.8	4.1		V
		Full range	3.6			3.6			
	$I_O = -2 \text{ mA}$	25°C	3.5	3.9		3.5	3.9		
		Full range	3.3			3.3			
	$I_O = -20 \text{ mA}$	25°C	1.5	2.3		1.5	2.3		
		Full range	1.4			1.4			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-3.8	-4.2		-3.8	-4.2		V
		Full range	-3.6			-3.6			
	$I_O = 2 \text{ mA}$	25°C	-3.5	-4.1		-3.5	-4.1		
		Full range	-3.3			-3.3			
	$I_O = 20 \text{ mA}$	25°C	-1.5	-2.4		-1.5	-2.4		
		Full range	-1.4			-1.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3 \text{ V}$	$R_L = 600 \Omega$	25°C	80	91	80	91		dB
			Full range	78		78			
		$R_L = 2 \text{ k}\Omega$	25°C	90	100	90	100		
			Full range	88		88			
		$R_L = 10 \text{ k}\Omega$	25°C	95	106	95	106		
			Full range	93		93			
r_i Input resistance	$V_{IC} = 0$	25°C		10^{12}		10^{12}			Ω
c_i Input capacitance	Common mode	25°C		11		11			pF
	Differential	25°C		2.5		2.5			
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C		80		80			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50 \Omega$	25°C	70	89		70	89		dB
		Full range	68			68			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}, V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99		dB
		Full range	80			80			

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2082M			TLE2082AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I _{CC}	Supply current (both channels)	V _O = 0,	No load	25°C	2.7	2.9	3.6	2.7	2.9	3.6	mA
				Full range	3.6			3.6			
Crosstalk attenuation		V _{IC} = 0,	R _L = 2 kΩ	25°C	120			120			dB
I _{OS}	Short-circuit output current	V _O = 0	V _{ID} = 1 V	25°C	−35			−35			mA
			V _{ID} = −1 V		45			45			

† Full range is –55°C to 125°C.

TLE2082M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER		TEST CONDITIONS		T _A †	TLE2082M			TLE2082AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = ±2.3 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	35			35			V/μs
	Full range			18*			18*				
SR −	Negative slew rate			25°C	38			38			V/μs
	Full range			18*			18*				
t _s	Settling time	A _{VD} = −1, 2-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.25			0.25			μs
		To 1 mV	0.4			0.4					
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
	f = 10 kHz		11.6			11.6					
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0, f = 10 kHz	25°C	2.8			2.8			fA/√Hz	
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 5 V, A _{VD} = 10, f = 1 kHz, R _L = 2 kΩ, R _S = 25 Ω	25°C	0.013%			0.013%				
B ₁	Unity-gain bandwidth	V _I = 10 mV, R _L = 2 kΩ, C _L = 25 pF, See Figure 2	25°C	9.4			9.4			MHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 4 V, A _{VD} = −1, R _L = 2 kΩ , C _L = 25 pF	25°C	2.8			2.8			MHz	
ϕ _m	Phase margin at unity gain	V _I = 10 mV, R _L = 2 kΩ, C _L = 25 pF, See Figure 2	25°C	56°			56°				

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is –55°C to 125°C.



TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$T_A^\dagger$	TLE2082M			TLE2082AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	1.1	7		0.7	4		mV
			Full range			9.5			6.5	
α_{VIO}	Temperature coefficient of input offset voltage		Full range	2.4	25*		2.4	25*		$\mu V/^\circ C$
I_{IO}	Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	6	100		6	100		pA
			Full range			20			20	nA
I_{IB}	Input bias current		25°C	20	175		20	175		pA
			Full range			65			65	nA
V_{ICR}	Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9		V
			Full range	15 to -10.8			15 to -10.8			
V_{OM+}	Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	13.8	14.1		13.8	14.1		V
			Full range	13.6			13.6			
		$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9		
			Full range	13.3			13.3			
		$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3		
			Full range	11.4			11.4			
V_{OM-}	Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-13.8	-14.2		-13.8	-14.2		V
			Full range	-13.6			-13.6			
		$I_O = 2 \text{ mA}$	25°C	-13.5	-14		-13.5	-14		
			Full range	-13.3			-13.3			
		$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4		-11.5	-12.4		
			Full range	-11.4			-11.4			
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96	80	96		dB
				Full range	78		78			
			$R_L = 2 \text{ k}\Omega$	25°C	90	109	90	109		
				Full range	88		88			
			$R_L = 10 \text{ k}\Omega$	25°C	95	118	95	118		
				Full range	93		93			
r_i	Input resistance	$V_{IC} = 0$	25°C	10^{12}			10^{12}			Ω
c_i	Input capacitance	Common mode	25°C	7.5			7.5			pF
		Differential								
z_o	Open-loop output impedance	$f = 1 \text{ MHz}$	25°C	80			80			Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50 \Omega$	25°C	80	98		80	98		dB
			Full range	78			78			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}, V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99		dB
			Full range	80			80			

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C .

TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2082M			TLE2082AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I _{CC}	Supply current (both channels)	V _O = 0,	No load	25°C	2.7	3.1	3.6	2.7	3.1	3.6	mA
				Full range	3.6			3.6			
Crosstalk attenuation		V _{IC} = 0,	R _L = 2 kΩ	25°C	120			120			dB
I _{OS}	Short-circuit output current	V _O = 0	V _{ID} = 1 V	25°C	–30	–45		–30	–45		mA
			V _{ID} = –1 V		30	48		30	48		

† Full range is –55°C to 125°C.

TLE2082M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2082M			TLE2082AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = 10 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	28	40		28	40		V/μs
	Full range			20		20					
SR −	Negative slew rate			25°C	30	45		30	45		V/μs
	Full range			20		20					
t _s	Settling time	A _{VD} = −1, 10-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.4			0.4			μs
		To 1 mV	1.5			1.5					
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0, f = 10 kHz	25°C	2.8			2.8			fA/√Hz	
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, A _{VD} = 10, f = 1 kHz, R _L = 2 kΩ, R _S = 25 Ω	25°C	0.008%			0.008%				
B ₁	Unity-gain bandwidth	V _I = 10 mV, C _L = 25 pF, R _L = 2 kΩ, See Figure 2	25°C	8*	10		8*	10		MHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 20 V, R _L = 2 kΩ, A _{VD} = −1, C _L = 25 pF	25°C	478*	637		478*	637		kHz	
φ _m	Phase margin at unity gain	V _I = 10 mV, C _L = 25 pF, R _L = 2 kΩ, See Figure 2	25°C	57°			57°				

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is –55°C to 125°C.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2082Y electrical characteristics at $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2082Y			UNIT
				MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$		1.1	6		mV
I_{IO}	Input offset current	$V_{IC} = 0$, $V_O = 0$, See Figure 4		6	100		pA
I_{IB}	Input bias current			20	175		pA
V_{ICR}	Common-mode input voltage range	$R_S = 50\ \Omega$		15 to -11	15 to 11.9		V
V_{OM+}	Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$		13.8	14.1		V
		$I_O = -2\text{ mA}$		13.5	13.9		
		$I_O = -20\text{ mA}$		11.5	12.3		
V_{OM-}	Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$		-13.8	-14.2		V
		$I_O = 2\text{ mA}$		-13.5	-14		
		$I_O = 20\text{ mA}$		-11.5	-12.4		
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 10\text{ V}$	$R_L = 600\ \Omega$	80	96		dB
			$R_L = 2\text{ k}\Omega$	90	109		
			$R_L = 10\text{ k}\Omega$	95	118		
r_i	Input resistance	$V_{IC} = 0$		10	12		Ω
c_i	Input capacitance	Common mode	$V_O = 0$, See Figure 5	7.5			pF
		Differential		2.5			
z_o	Open-loop output impedance	$f = 1\text{ MHz}$		80			Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $V_O = 0$, $R_S = 50\ \Omega$		80	98		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$, $V_O = 0$		82	99		dB
I_{CC}	Supply current (both channels)	$V_O = 0$, No load		2.7	3.1	3.9	mA
I_{OS}	Short-circuit output current	$V_O = 0$	$V_{ID} = 1\text{ V}$	-30	-45		mA
			$V_{ID} = -1\text{ V}$	30	48		

TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2084C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2084C			TLE2084AC			UNIT	
					MIN	TYP	MAX	MIN	TYP	MAX		
V _{IO}	Input offset voltage	V _{IC} = 0, V _O = 0, R _S = 50 Ω		25°C	−1.6		7	−0.5		4	mV	
				Full range			9.1			6.1		
αV _{IO}	Temperature coefficient of input offset voltage			Full range	10.1		30	10.1		30	μV/°C	
I _{IO}	Input offset current	V _{IC} = 0, V _O = 0, See Figure 4		25°C	15		100	15		100	pA	
				Full range			1.4			1.4	nA	
I _{IB}	Input bias current			25°C	20		175	20		175	pA	
				Full range			5			5	nA	
V _{ICR}	Common-mode input voltage range	R _S = 50 Ω		25°C	5 to −1	5 to −1.9		5 to −1	5 to −1.9		V	
			Full range	5 to −0.9		5 to −0.9						
V _{OM+}	Maximum positive peak output voltage swing	I _O = −200 μA		25°C	3.8	4.1		3.8	4.1		V	
			Full range	3.7		3.7						
		I _O = −2 mA		25°C	3.5	3.9		3.5	3.9			
			Full range	3.4		3.4						
		I _O = −20 mA		25°C	1.5	2.3		1.5	2.3			
			Full range	1.5		1.5						
V _{OM−}	Maximum negative peak output voltage swing	I _O = 200 μA		25°C	−3.8	−4.2		−3.8	−4.2		V	
			Full range	−3.7		−3.7						
		I _O = 2 mA		25°C	−3.5	−4.1		−3.5	−4.1			
			Full range	−3.4		−3.4						
		I _O = 20 mA		25°C	−1.5	−2.4		−1.5	−2.4			
			Full range	−1.5		−1.5						
A _{VD}	Large-signal differential voltage amplification	V _O = ± 2.3 V	R _L = 600 Ω		25°C	80	91		80	91	dB	
				Full range	79		79					
			R _L = 2 kΩ		25°C	90	100		90	100		
				Full range	89		89					
			R _L = 10 kΩ		25°C	95	106		95	106		
				Full range	94		94					
r _i	Input resistance	V _{IC} = 0		25°C	10 ¹²		10 ¹²			Ω		
c _i	Input capacitance	V _{IC} = 0, See Figure 5	Common mode	25°C	11		11			pF		
			Differential	25°C	2.5		2.5					
z _o	Open-loop output impedance	f = 1 MHz		25°C	80		80			Ω		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin} , V _O = 0, R _S = 50 Ω		25°C	70	89		70	89	dB		
				Full range	68		68					
k _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})	V _{CC±} = ±5 V to ±15 V, V _O = 0, R _S = 50 Ω		25°C	82	99		82	99	dB		
				Full range	80		80					
I _{CC}	Supply current (four amplifiers)	V _O = 0, No load		25°C	5.2	6.3	7.5	5.2	6.3	7.5	mA	
				Full range	7.5			7.5				
a _x	Crosstalk attenuation	V _{IC} = 0,	R _L = 2 kΩ	25°C	120		120			dB		

† Full range is 0°C to 70°C.

TLE208x, TLE208xA, TLE208xY

EXCALIBUR HIGH-SPEED JFET-INPUT

OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2084C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2084C			TLE2084AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I _{OS}	Short-circuit output current	V _O = 0	V _{ID} = 1 V	25°C	–35			–35			mA
			V _{ID} = –1 V		45			45			

† Full range is 0°C to 70°C.

TLE2084C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2084C			TLE2084AC			UNIT	
					MIN	TYP	MAX	MIN	TYP	MAX		
SR +	Positive slew rate	V _{O(PP)} = ±2.3 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	35			35			V/μs	
	Full range			22			22					
SR −	Negative slew rate				25°C	38			38			V/μs
					Full range	22			22			
t _s	Settling time	A _{VD} = −1, 2-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.25			0.25			μs	
			To 1 mV		0.4			0.4				
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz	
			f = 10 kHz		11.6			11.6				
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV	
			f = 0.1Hz to 10 Hz		0.6			0.6				
I _n	Equivalent input noise current	V _{IC} = 0,	f = 10 kHz	25°C	2.8			2.8			fA/√Hz	
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 5 V, f = 1 kHz, R _S = 25 Ω	A _{VD} = 10, R _L = 2 kΩ,	25°C	0.013%			0.013%				
B ₁	Unity-gain bandwidth	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	9.4			9.4			MHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 4 V, R _L = 2 kΩ ,	A _{VD} = −1, C _L = 25 pF	25°C	2.8			2.8			MHz	
φ _m	Phase margin at unity gain	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	56°			56°				

† Full range is 0°C to 70°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2084C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2084C			TLE2084AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	-1.6	7		-0.5	4		mV
		Full range			9.1			6.1	
α_{VIO} Temperature coefficient of input offset voltage		Full range	10.1	30		10.1	30		$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	15	100		15	100		pA
		Full range			1.4			1.4	
I_{IB} Input bias current		25°C	25	175		25	175		pA
		Full range			5			5	
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9		V
		Full range	15 to -10.9			15 to -10.9			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	13.8	14.1		13.8	14.1		V
		Full range	13.7			13.7			
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9		
		Full range	13.4			13.4			
	$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3		
		Full range	11.5			11.5			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-13.8	-14.2		-13.8	-14.2		V
		Full range	-13.7			-13.7			
	$I_O = 2 \text{ mA}$	25°C	-13.7	-14		-13.7	-14		
		Full range	-13.6			-13.6			
	$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4		-11.5	-12.4		
		Full range	-11.5			-11.5			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96	80	96		dB
			Full range	79		79			
		$R_L = 2 \text{ k}\Omega$	25°C	90	109	90	109		
			Full range	89		89			
		$R_L = 10 \text{ k}\Omega$	25°C	95	118	95	118		
			Full range	94		94			
r_i Input resistance	$V_{IC} = 0$	25°C		10^{12}			10^{12}		Ω
c_i Input capacitance	$V_{IC} = 0, \text{See Figure 5}$	Common mode	25°C	7.5		7.5			pF
		Differential	25°C	2.5		2.5			
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C		80		80			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50 \Omega$	25°C	80	98		80	98		dB
		Full range	79			79			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}, V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99		dB
		Full range	81			81			
I_{CC} Supply current (four amplifiers)	$V_O = 0, \text{No load}$	25°C	5.2	6.5	7.5	5.2	6.5	7.5	mA
		Full range			7.5			7.5	
a_x Crosstalk attenuation	$V_{IC} = 0, R_L = 2 \text{ k}\Omega$	25°C		120			120		dB

† Full range is 0°C to 70°C.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2084C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2084C			TLE2084AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1$ V	–30	–45		–30	–45		mA
		$V_{ID} = -1$ V	30	48		30	48		

† Full range is 0°C to 70°C.

TLE2084C operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2084C			TLE2084AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = 10 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	25	40		25	40		V/μs
				Full range	22			22			
SR −	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	25			25			
t _s	Settling time	A _{VD} = −1, 10-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.4			0.4			μs
			To 1 mV		1.5			1.5			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0, f = 10 kHz	25°C	2.8			2.8			fA/√Hz	
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, A _{VD} = 10, f = 1 kHz, R _L = 2 kΩ, R _S = 25 Ω	25°C	0.008%			0.008%				
B ₁	Unity-gain bandwidth	V _I = 10 mV, R _L = 2 kΩ, C _L = 25 pF, See Figure 2	25°C	8	10		8	10		MHz	
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 20 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 25 pF	25°C	478	637		478	637		kHz	
φ _m	Phase margin at unity gain	V _I = 10 mV, R _L = 2 kΩ, C _L = 25 pF, See Figure 2	25°C	57°			57°				

† Full range is 0°C to 70°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2084M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2084M			TLE2084AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0,$ $R_S = 50 \Omega$	25°C	–1.6	7		–0.5	4		mV
		Full range			12.5			9.5	
α_{VIO} Temperature coefficient of input offset voltage		Full range	10.1	30*		10.1	30*		$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0,$ See Figure 4	25°C	15	100		15	100		pA
		Full range		20			20		nA
I_{IB} Input bias current		25°C	20	175		20	175		pA
		Full range		65			65		nA
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	5 to –1	5 to –1.9		5 to –1	5 to –1.9		V
		Full range	5 to –0.8			5 to –0.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	3.8	4.1		3.8	4.1		V
		Full range	3.6			3.6			
	$I_O = -2$ mA	25°C	3.5	3.9		3.5	3.9		
		Full range	3.3			3.3			
	$I_O = -20$ mA	25°C	1.5	2.3		1.5	2.3		
		Full range	1.4			1.4			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	–3.8	–4.2		–3.8	–4.2		V
		Full range	–3.6			–3.6			
	$I_O = 2$ mA	25°C	–3.5	–4.1		–3.5	–4.1		
		Full range	–3.3			–3.3			
	$I_O = 20$ mA	25°C	–1.5	–2.4		–1.5	–2.4		
		Full range	–1.4			–1.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 2.3$ V	$R_L = 600 \Omega$	25°C	80	91	80	91		dB
			Full range	78		78			
		$R_L = 2$ k Ω	25°C	90	100	90	100		
			Full range	88		88			
		$R_L = 10$ k Ω	25°C	95	106	95	106		
			Full range	93		93			
r_i Input resistance	$V_{IC} = 0$	25°C		10^{12}			10^{12}		Ω
c_i Input capacitance	$V_{IC} = 0,$ See Figure 5	Common mode	25°C	11		11			pF
		Differential	25°C	2.5		2.5			
z_o Open-loop output impedance	$f = 1$ MHz	25°C		80			80		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $V_O = 0, R_S = 50 \Omega$	25°C	70	89		70	89		dB
		Full range	68			68			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5$ V to ± 15 V, $V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99		dB
		Full range	80			80			
I_{CC} Supply current (four amplifiers)	$V_O = 0,$ No load	25°C	5.2	6.3	7.5	5.2	6.3	7.5	mA
		Full range			7.5			7.5	
a_x Crosstalk attenuation	$V_{IC} = 0, R_L = 2$ k Ω	25°C		120			120		dB

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is $-55^\circ C$ to $125^\circ C$.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2084M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T _A	TLE2084M			TLE2084AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I _{OS}	Short-circuit output current	V _O = 0	V _{ID} = 1 V	25°C	−35			−35			mA
			V _{ID} = −1 V		45			45			

TLE2084M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 5$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2084M			TLE2084AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = ±2.3 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	35			35			V/μs
				Full range	18*			18*			
SR −	Negative slew rate			25°C	38			38			V/μs
				Full range	18*			18*			
t _s	Settling time	A _{VD} = −1, 2-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.25			0.25			μs
			To 1 mV		0.4			0.4			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0, f = 10 kHz		25°C	2.8			2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 5 V, f = 1 kHz, R _S = 25 Ω	A _{VD} = 10, R _L = 2 kΩ,	25°C	0.013%			0.013%			
B ₁	Unity-gain bandwidth	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	9.4			9.4			MHz
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 4 V, R _L = 2 kΩ ,	A _{VD} = −1, C _L = 25 pF	25°C	2.8			2.8			MHz
ϕ _m	Phase margin at unity gain	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	56°			56°			

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C.



TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2084M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A †	TLE2084M			TLE2084AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	-1.6	7		-0.5	4		mV
		Full range			12.5			7.5	
α_{VIO} Temperature coefficient of input offset voltage		Full range	10.1	30*		10.1	30*		$\mu V/^\circ C$
I_{IO} Input offset current	$V_{IC} = 0, V_O = 0, \text{See Figure 4}$	25°C	15	100		15	100		pA
		Full range			20			20	
I_{IB} Input bias current		25°C	25	175		25	175		pA
		Full range			65			65	
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	15 to -11	15 to -11.9		15 to -11	15 to -11.9		V
		Full range	15 to -10.8			15 to -10.8			
V_{OM+} Maximum positive peak output voltage swing	$I_O = -200 \mu A$	25°C	13.8	14.1		13.8	14.1		V
		Full range	13.6			13.6			
	$I_O = -2 \text{ mA}$	25°C	13.5	13.9		13.5	13.9		
		Full range	13.3			13.3			
	$I_O = -20 \text{ mA}$	25°C	11.5	12.3		11.5	12.3		
		Full range	11.4			11.4			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 200 \mu A$	25°C	-13.8	-14.2		-13.8	-14.2		V
		Full range	-13.6			-13.6			
	$I_O = 2 \text{ mA}$	25°C	-13.5	-14		-13.5	-14		
		Full range	-13.3			-13.3			
	$I_O = 20 \text{ mA}$	25°C	-11.5	-12.4		-11.5	-12.4		
		Full range	-11.4			-11.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}$	$R_L = 600 \Omega$	25°C	80	96	80	96		dB
			Full range	78		78			
		$R_L = 2 \text{ k}\Omega$	25°C	90	109	90	109		
			Full range	88		88			
		$R_L = 10 \text{ k}\Omega$	25°C	95	118	95	118		
			Full range	93		93			
r_i Input resistance	$V_{IC} = 0$	25°C		10^{12}			10^{12}		Ω
c_i Input capacitance	$V_{IC} = 0, \text{See Figure 5}$	Common mode	25°C	7.5		7.5			pF
		Differential	25°C	2.5		2.5			
z_o Open-loop output impedance	$f = 1 \text{ MHz}$	25°C		80			80		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, V_O = 0, R_S = 50 \Omega$	25°C	80	98		80	98		dB
		Full range	78			78			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 5 \text{ V to } \pm 15 \text{ V}, V_O = 0, R_S = 50 \Omega$	25°C	82	99		82	99		dB
		Full range	80			80			
I_{CC} Supply current (four amplifiers)	$V_O = 0, \text{No load}$	25°C	5.2	6.5	7.5	5.2	6.5	7.5	mA
		Full range			7.5			7.5	
a_x Crosstalk attenuation	$V_{IC} = 0, R_L = 2 \text{ k}\Omega$	25°C		120			120		dB

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is $-55^\circ C$ to $125^\circ C$.

TLE208x, TLE208xA, TLE208xY

EXCALIBUR HIGH-SPEED JFET-INPUT

OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2084M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS		T _A	TLE2084M			TLE2084AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
I _{OS}	Short-circuit output current	V _O = 0	V _{ID} = 1 V	25°C	-30	-45		-30	-45		mA
			V _{ID} = -1 V		30	48		30	48		

TLE2084M operating characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2084M			TLE2084AM			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	V _{O(PP)} = 10 V, A _{VD} = −1, R _L = 2 kΩ, C _L = 100 pF, See Figure 1		25°C	25	40		25	40		V/μs
				Full range	17			17			
SR −	Negative slew rate			25°C	30	45		30	45		V/μs
				Full range	20			20			
t _s	Settling time	A _{VD} = −1, 10-V step, R _L = 1 kΩ, C _L = 100 pF	To 10 mV	25°C	0.4			0.4			μs
			To 1 mV		1.5			1.5			
V _n	Equivalent input noise voltage	R _S = 20 Ω, See Figure 3	f = 10 Hz	25°C	28			28			nV/√Hz
			f = 10 kHz		11.6			11.6			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 10 Hz to 10 kHz	25°C	6			6			μV
			f = 0.1 Hz to 10 Hz		0.6			0.6			
I _n	Equivalent input noise current	V _{IC} = 0,	f = 10 kHz	25°C	2.8			2.8			fA/√Hz
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, f = 1 kHz, R _S = 25 Ω	A _{VD} = 10, R _L = 2 kΩ,	25°C	0.008%			0.008%			
B ₁	Unity-gain bandwidth	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	8*	10		8*	10		MHz
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 20 V, R _L = 2 kΩ,	A _{VD} = −1, C _L = 25 pF	25°C	478*	637		478*	637		kHz
φ _m	Phase margin at unity gain	V _I = 10 mV, C _L = 25 pF,	R _L = 2 kΩ, See Figure 2	25°C	57°			57°			

*On products compliant with MIL-PRF-38535, Class B, this parameter is not production tested.

† Full range is -55°C to 125°C.

TLE208x, TLE208xA, TLE208xY
EXCALIBUR HIGH-SPEED JFET-INPUT
OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TLE2084Y electrical characteristics at $V_{CC\pm} = \pm 15$ V, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

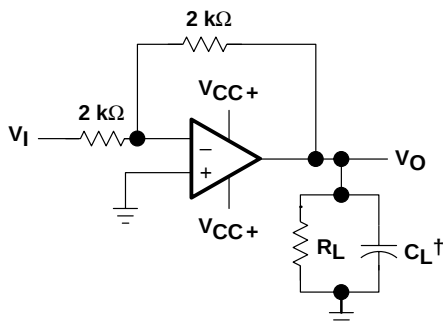
PARAMETER		TEST CONDITIONS		TLE2084Y			UNIT
				MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{IC} = 0$, $R_S = 50\ \Omega$	$V_O = 0$,			7	mV
I_{IO}	Input offset current	$V_{IC} = 0$,	$V_O = 0$,		15	100	pA
I_{IB}	Input bias current	See Figure 4			25	175	pA
V_{ICR}	Common-mode input voltage range	$R_S = 50\ \Omega$		15 to –11	15 to 11.9		V
V_{OM+}	Maximum positive peak output voltage swing	$I_O = -200\ \mu\text{A}$		13.8	14.1		V
		$I_O = -2\ \text{mA}$		13.5	13.9		
		$I_O = -20\ \text{mA}$		11.5	12.3		
V_{OM-}	Maximum negative peak output voltage swing	$I_O = 200\ \mu\text{A}$		–13.8	–14.2		V
		$I_O = 2\ \text{mA}$		–13.5	–14		
		$I_O = 20\ \text{mA}$		–11.5	–12.4		
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$	$R_L = 600\ \Omega$	80	96		dB
			$R_L = 2\ \text{k}\Omega$	90	109		
			$R_L = 10\ \text{k}\Omega$	95	118		
r_i	Input resistance	$V_{IC} = 0$		10 ¹²			Ω
c_i	Input capacitance	$V_{IC} = 0$, See Figure 5	Common mode	7.5			pF
			Differential	2.5			
z_o	Open-loop output impedance	$f = 1\ \text{MHz}$		80			Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	$V_O = 0$,	80	98		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 5\ \text{V}$ to $\pm 15\ \text{V}$, $V_O = 0$, $R_S = 50\ \Omega$		82	99		dB
I_{CC}	Supply current (four amplifiers)	$V_O = 0$,	No load	5.2	6.5	7.5	mA
I_{OS}	Short-circuit output current	$V_O = 0$	$V_{ID} = 1\ \text{V}$	–30	–45		mA
			$V_{ID} = -1\ \text{V}$	30	48		



TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

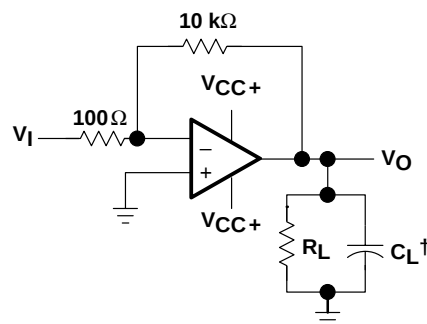
SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

PARAMETER MEASUREMENT INFORMATION



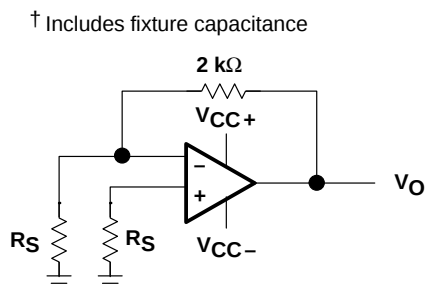
† Includes fixture capacitance

Figure 1. Slew-Rate Test Circuit



† Includes fixture capacitance

Figure 2. Unity-Gain Bandwidth and Phase-Margin Test Circuit



† Includes fixture capacitance

Figure 3. Noise-Voltage Test Circuit

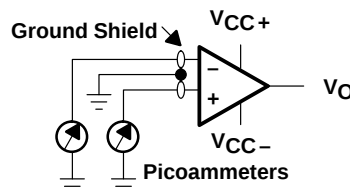


Figure 4. Input-Bias and Offset-Current Test Circuit

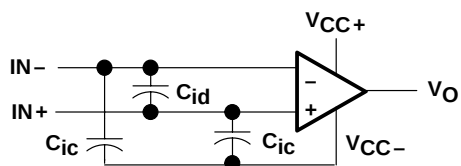


Figure 5. Internal Input Capacitance

typical values

Typical values presented in this data sheet represent the median (50% point) of device parametric performance.

input bias and offset current

At the picoampere bias-current level typical of the TLE208x and TLE208xA, accurate measurement of the bias becomes difficult. Not only does this measurement require a picoammeter, but test socket leakages can easily exceed the actual device bias currents. To accurately measure these small currents, Texas Instruments uses a two-step process. The socket leakage is measured using picoammeters with bias voltages applied but with no device in the socket. The device is then inserted in the socket and a second test is performed that measures both the socket leakage and the device input bias current. The two measurements are then subtracted algebraically to determine the bias current of the device.

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	Distribution	6, 7, 8
α_{VIO}	Input offset voltage temperature coefficient	Distribution	9, 10, 11
I_{IO}	Input offset current	vs Free-air temperature	12 – 15
I_{IB}	Input bias current	vs Free-air temperature vs Supply voltage	12 – 15 16
V_{ICR}	Common-mode input voltage range	vs Free-air temperature	17
V_{ID}	Differential input voltage	vs Output voltage	18, 19
V_{OM+}	Maximum positive peak output voltage	vs Output current vs Free-air temperature vs Supply voltage	20, 21 24, 25 26
V_{OM-}	Maximum negative peak output voltage	vs Output current vs Free-air temperature vs Supply voltage	22, 23 24, 25 26
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	27
V_O	Output voltage	vs Settling time	28
A_{VD}	Large-signal differential voltage amplification	vs Load resistance vs Free-air temperature	29 30, 31
A_{VD}	Small-signal differential voltage amplification	vs Frequency	32, 33
$CMRR$	Common-mode rejection ratio	vs Frequency vs Free-air temperature	34 35
k_{SVR}	Supply-voltage rejection ratio	vs Frequency vs Free-air temperature	36 37
I_{CC}	Supply current	vs Supply voltage vs Free-air temperature vs Differential input voltage	38, 39, 40 41, 42, 43 44 – 49
I_{OS}	Short-circuit output current	vs Supply voltage vs Elapsed time vs Free-air temperature	50 51 52
SR	Slew rate	vs Free-air temperature vs Load resistance vs Differential input voltage	53, 54 55 56
V_n	Equivalent input noise voltage	vs Frequency	57
V_n	Input-referred noise voltage	vs Noise bandwidth frequency Over a 10-second time interval	58 59
	Third-octave spectral noise density	vs Frequency bands	60
$THD + N$	Total harmonic distortion plus noise	vs Frequency	61, 62
B_1	Unity-gain bandwidth	vs Load capacitance	63
	Gain-bandwidth product	vs Free-air temperature vs Supply voltage	64 65
	Gain margin	vs Load capacitance	66
ϕ_m	Phase margin	vs Free-air temperature vs Supply voltage vs Load capacitance	67 68 69
	Phase shift	vs Frequency	32, 33

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TYPICAL CHARACTERISTICS

Table of Graphs (Continued)

		FIGURE
Noninverting large-signal pulse response	vs Time	70
Small-signal pulse response	vs Time	71
z_o Closed-loop output impedance	vs Frequency	72
a_x Crosstalk attenuation	vs Frequency	73

DISTRIBUTION OF TLE2081
INPUT OFFSET VOLTAGE

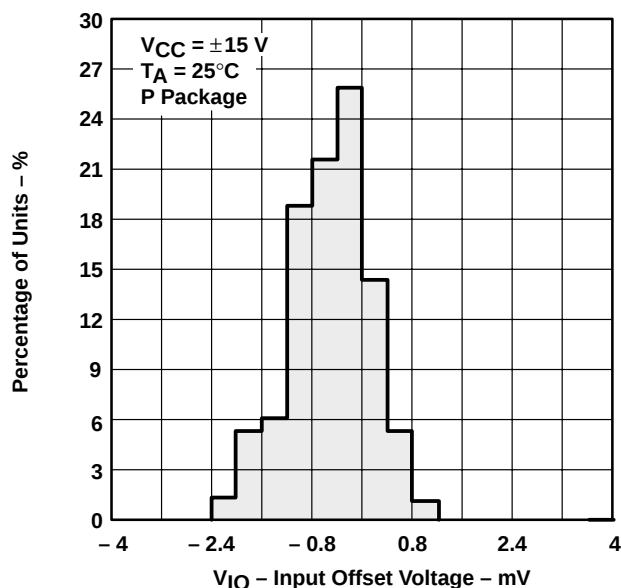


Figure 6

DISTRIBUTION OF TLE2082
INPUT OFFSET VOLTAGE

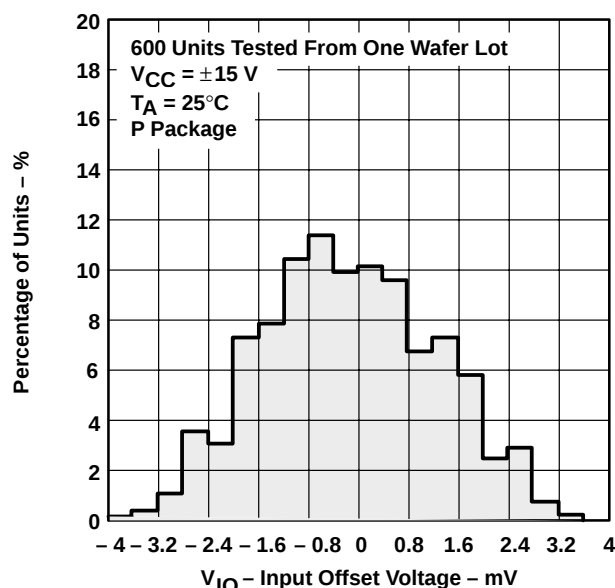


Figure 7

TYPICAL CHARACTERISTICS

**DISTRIBUTION OF TLE2084
INPUT OFFSET VOLTAGE**

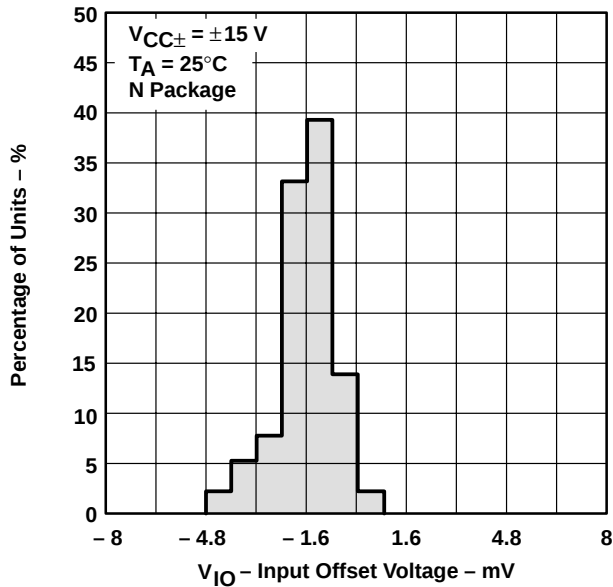


Figure 8

**DISTRIBUTION OF TLE2081 INPUT OFFSET
VOLTAGE TEMPERATURE COEFFICIENT**

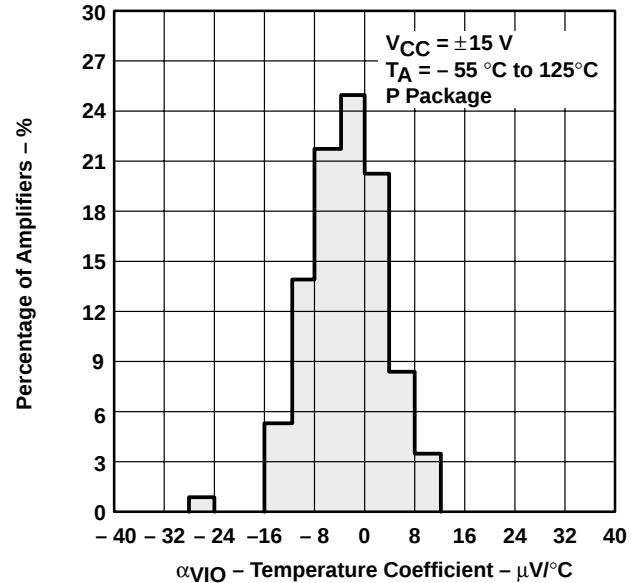


Figure 9

**DISTRIBUTION OF TLE2082 INPUT OFFSET
VOLTAGE TEMPERATURE COEFFICIENT**

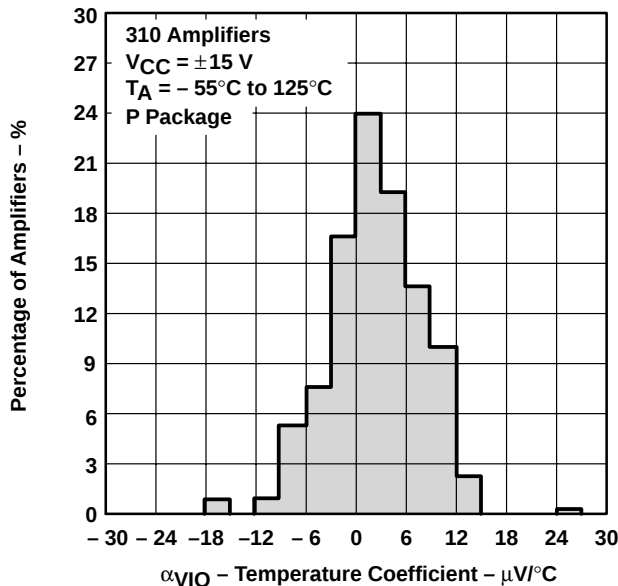


Figure 10

**DISTRIBUTION OF TLE2084 INPUT OFFSET
VOLTAGE TEMPERATURE COEFFICIENT**

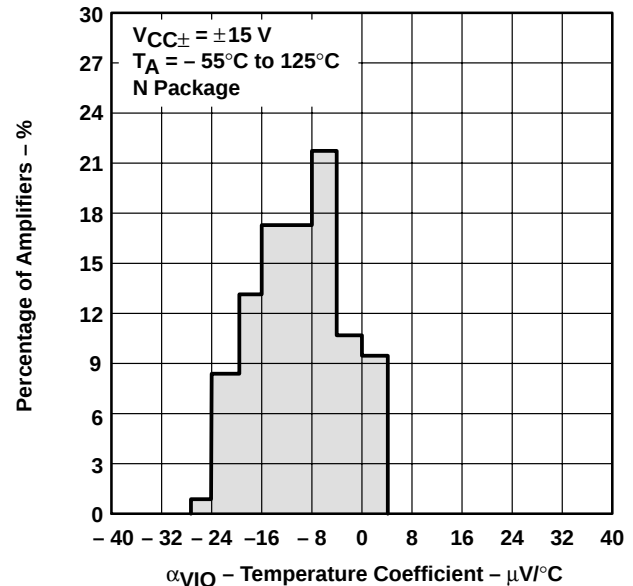


Figure 11

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TYPICAL CHARACTERISTICS†

TLE2081 AND TLE2082
INPUT BIAS CURRENT AND INPUT OFFSET CURRENT
VS
FREE-AIR TEMPERATURE

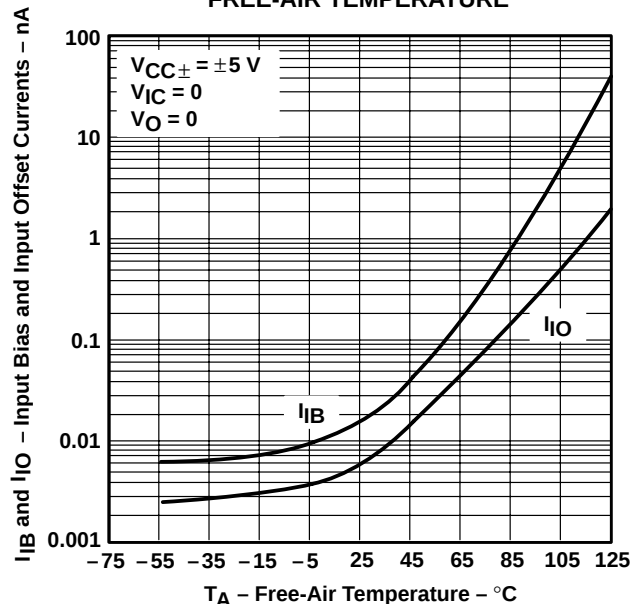


Figure 12

TLE2084
INPUT BIAS CURRENT AND INPUT OFFSET CURRENT
VS
FREE-AIR TEMPERATURE

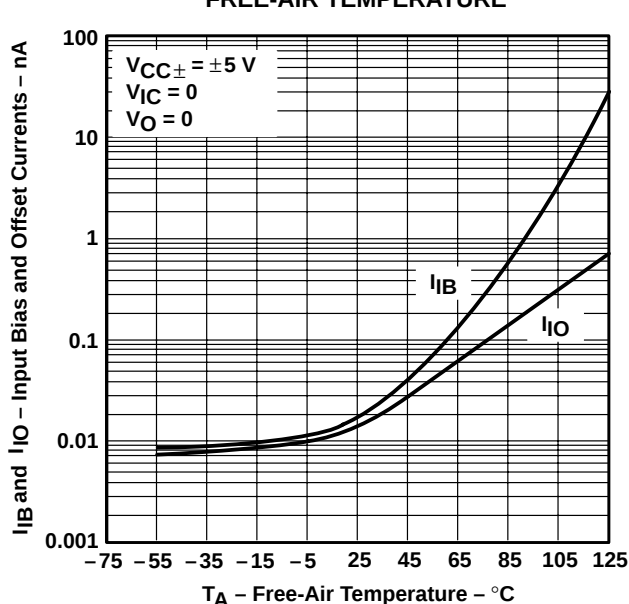


Figure 13

TLE2081 AND TLE2082
INPUT BIAS CURRENT AND INPUT OFFSET CURRENT
VS
FREE-AIR TEMPERATURE

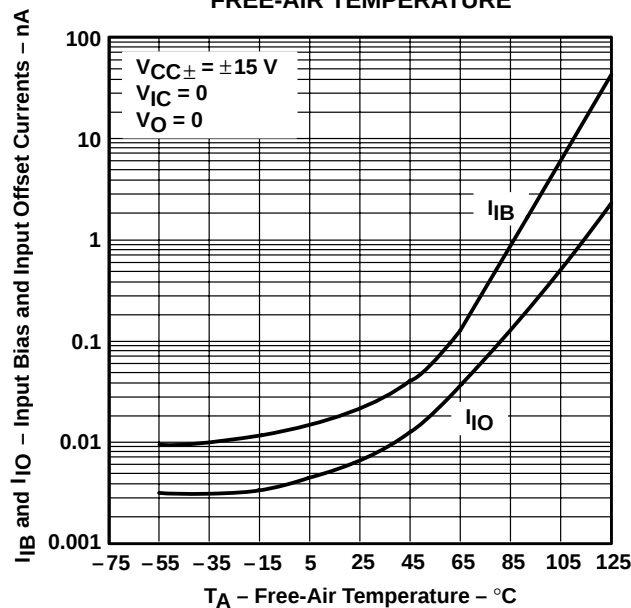


Figure 14

TLE2084
INPUT BIAS CURRENT AND INPUT OFFSET CURRENT
VS
FREE-AIR TEMPERATURE

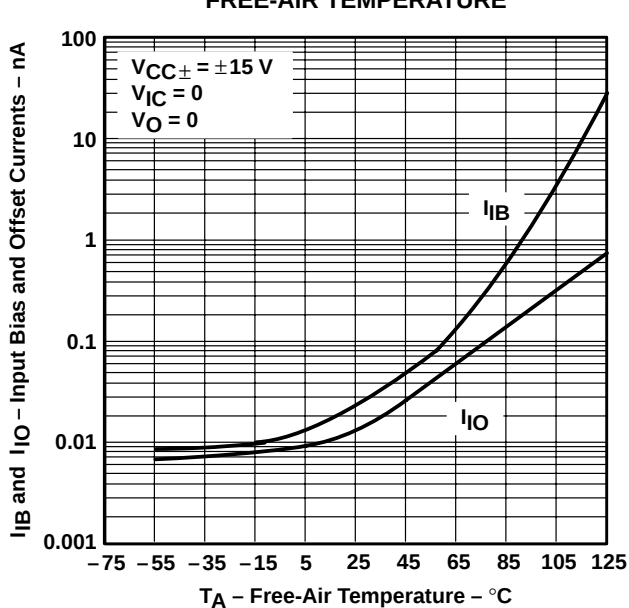
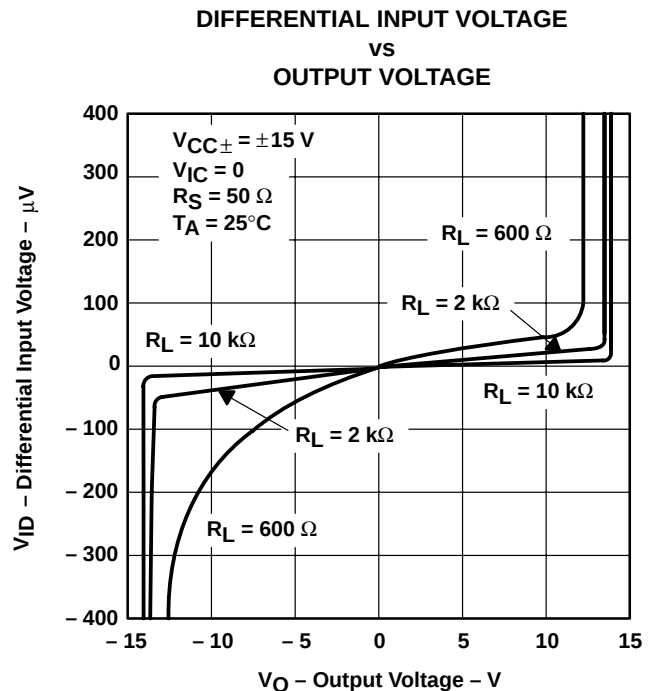
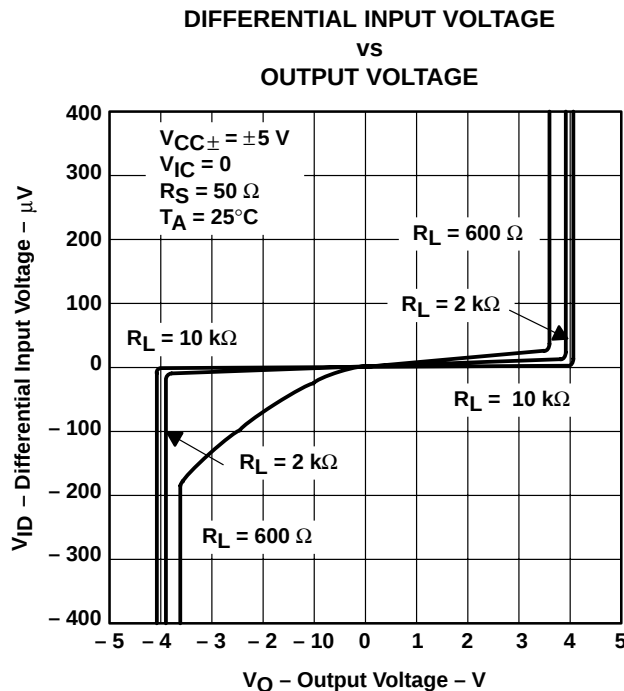
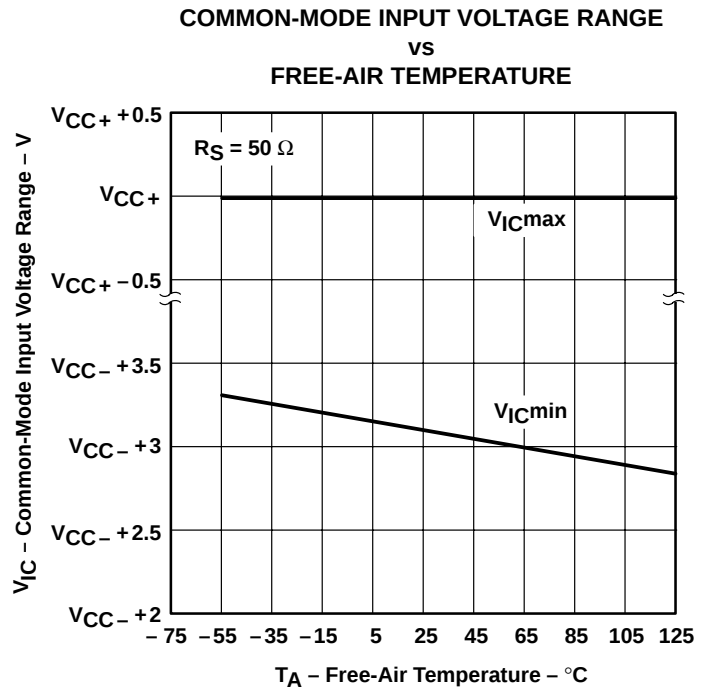
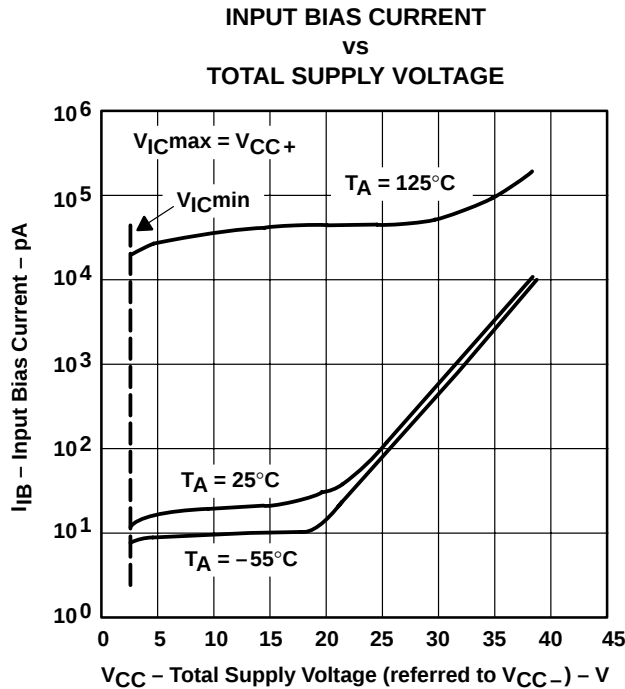


Figure 15

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TYPICAL CHARACTERISTICS†

TLE2081 AND TLE2082
MAXIMUM POSITIVE PEAK OUTPUT VOLTAGE
VS
OUTPUT CURRENT

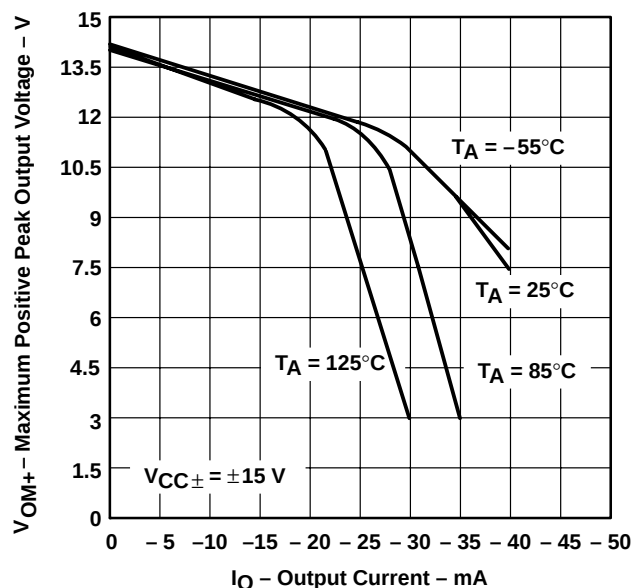


Figure 20

TLE2084
MAXIMUM POSITIVE PEAK OUTPUT VOLTAGE
VS
OUTPUT CURRENT

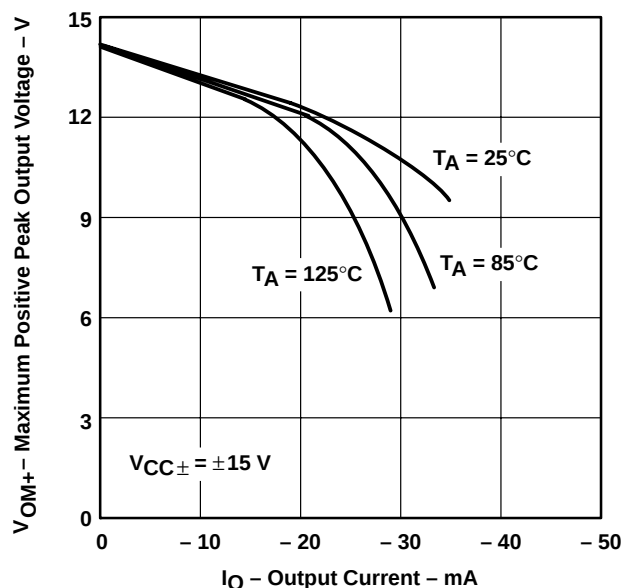


Figure 21

TLE2081 AND TLE2082
MAXIMUM NEGATIVE PEAK OUTPUT VOLTAGE
VS
OUTPUT CURRENT

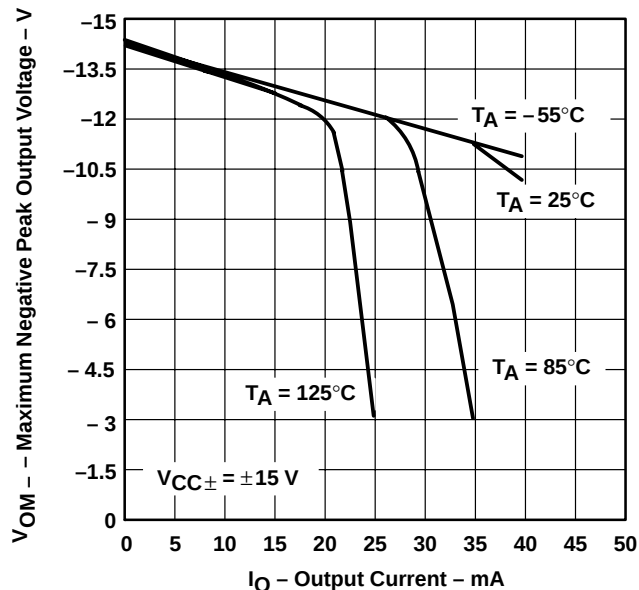


Figure 22

TLE2084
MAXIMUM NEGATIVE PEAK OUTPUT VOLTAGE
VS
OUTPUT CURRENT

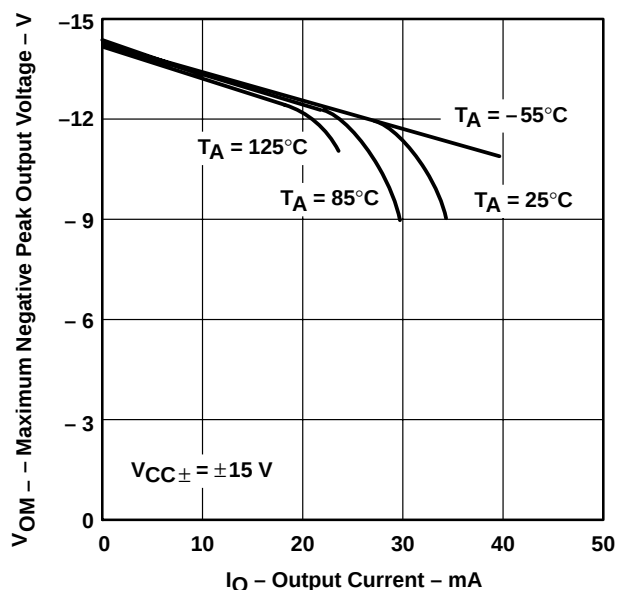


Figure 23

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

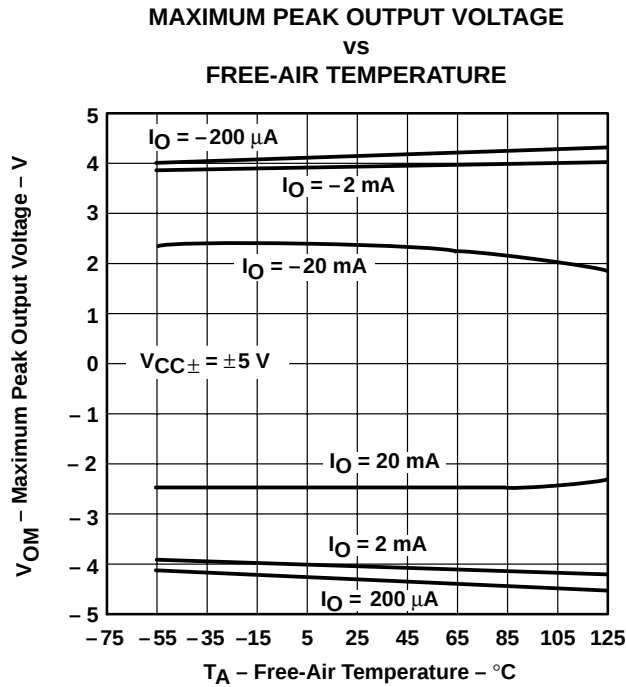


Figure 24

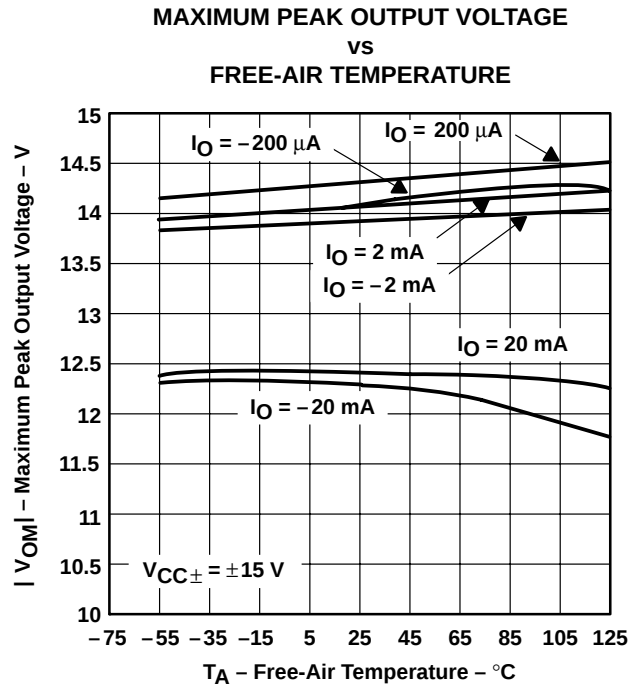


Figure 25

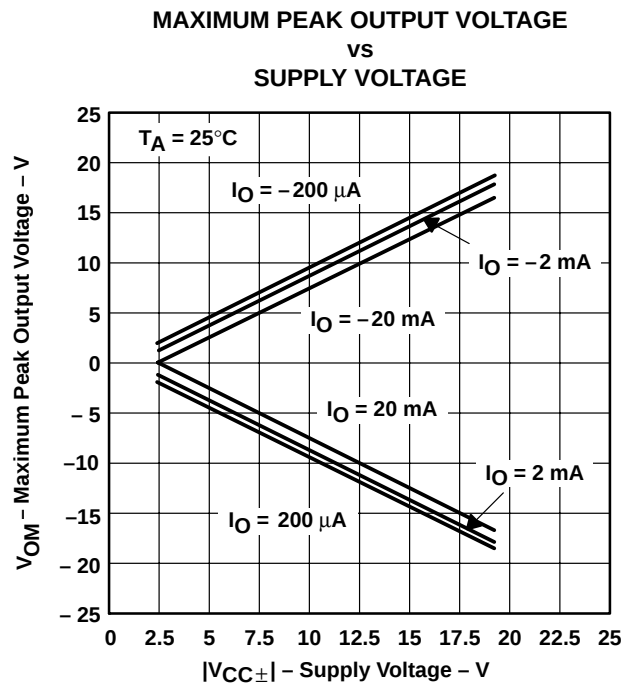


Figure 26

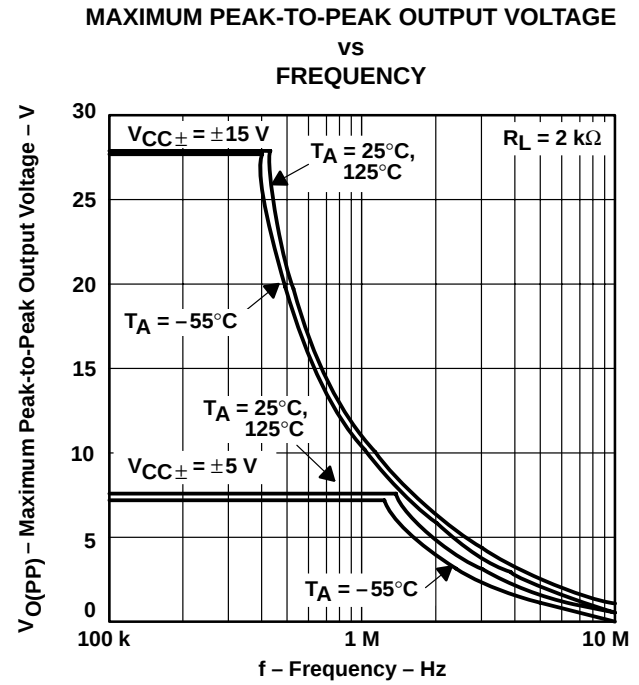


Figure 27

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TYPICAL CHARACTERISTICS†

OUTPUT VOLTAGE
VS
SETTLING TIME

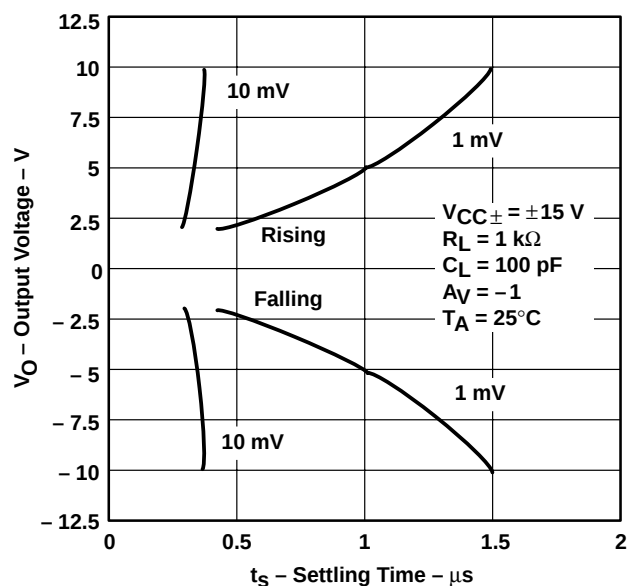


Figure 28

LARGE-SIGNAL DIFFERENTIAL
VOLTAGE AMPLIFICATION
VS
LOAD RESISTANCE

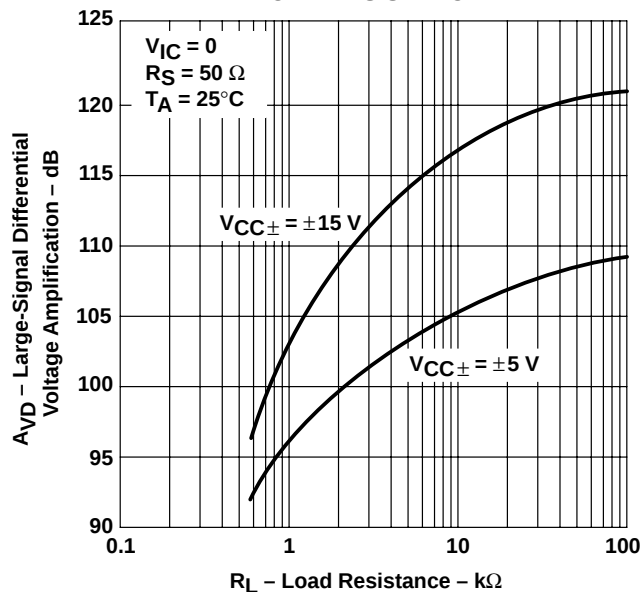


Figure 29

LARGE-SIGNAL DIFFERENTIAL
VOLTAGE AMPLIFICATION
VS
FREE-AIR TEMPERATURE

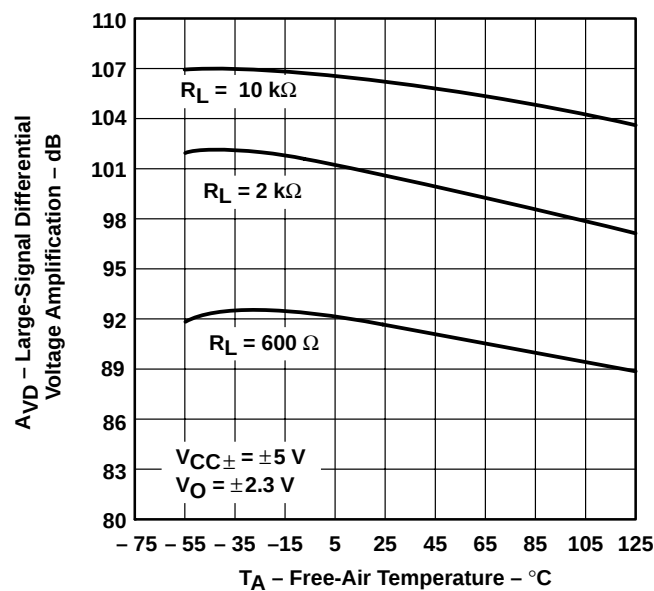


Figure 30

LARGE-SIGNAL DIFFERENTIAL
VOLTAGE AMPLIFICATION
VS
FREE-AIR TEMPERATURE

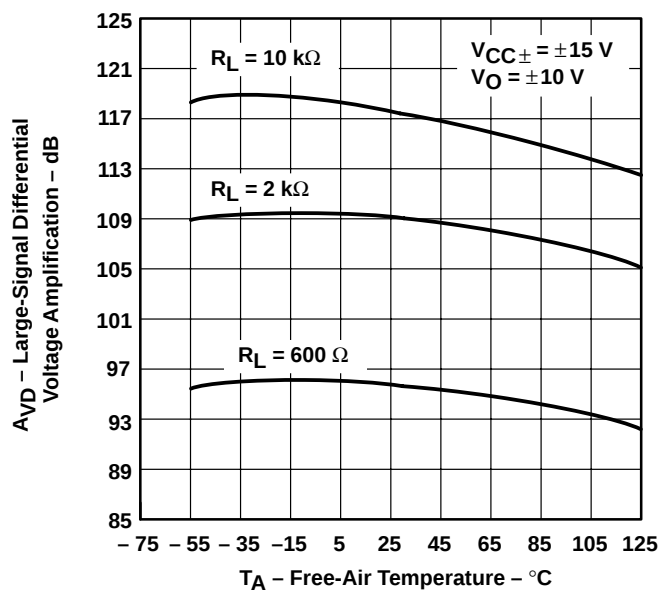


Figure 31

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

SMALL-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT

vs

FREQUENCY

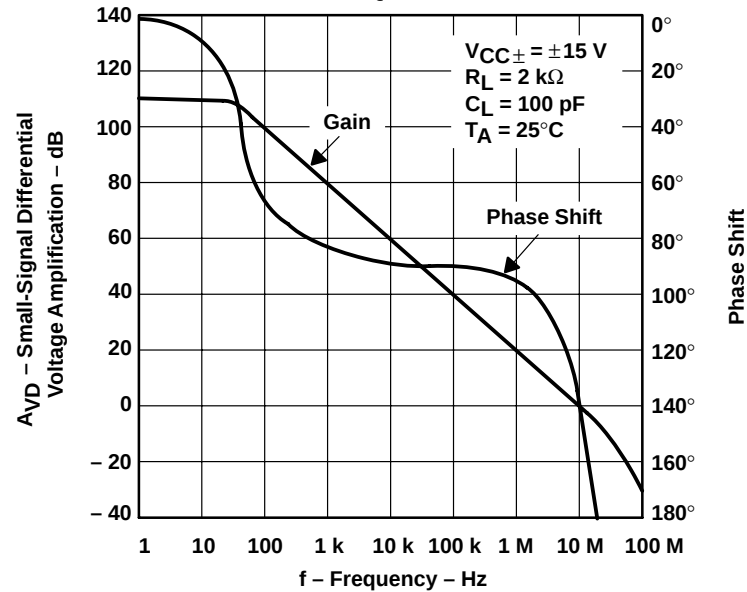


Figure 32

SMALL-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT

vs

FREQUENCY

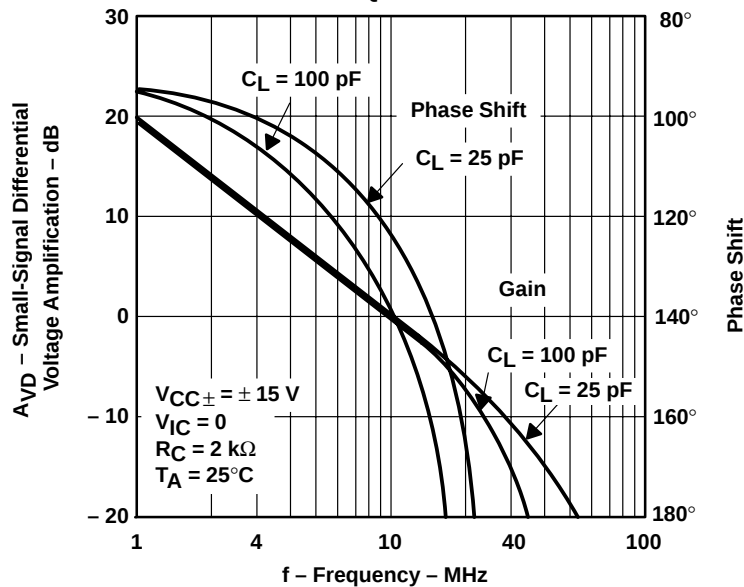


Figure 33

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TYPICAL CHARACTERISTICS†

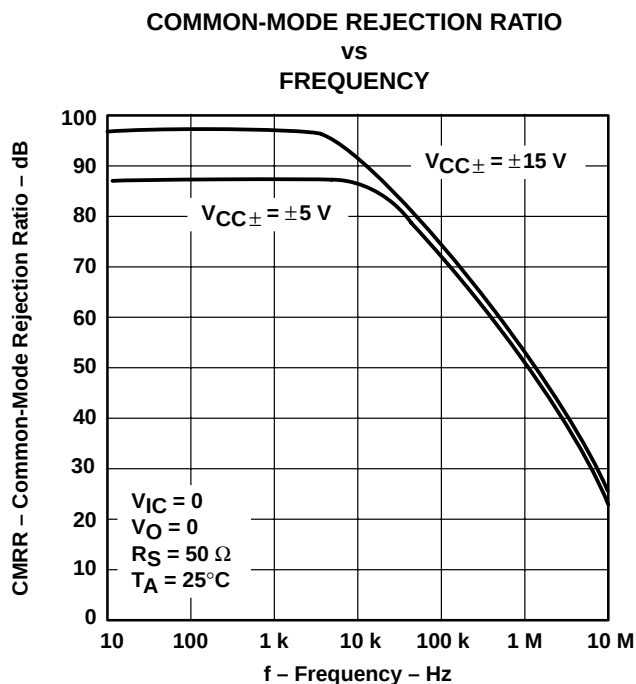


Figure 34

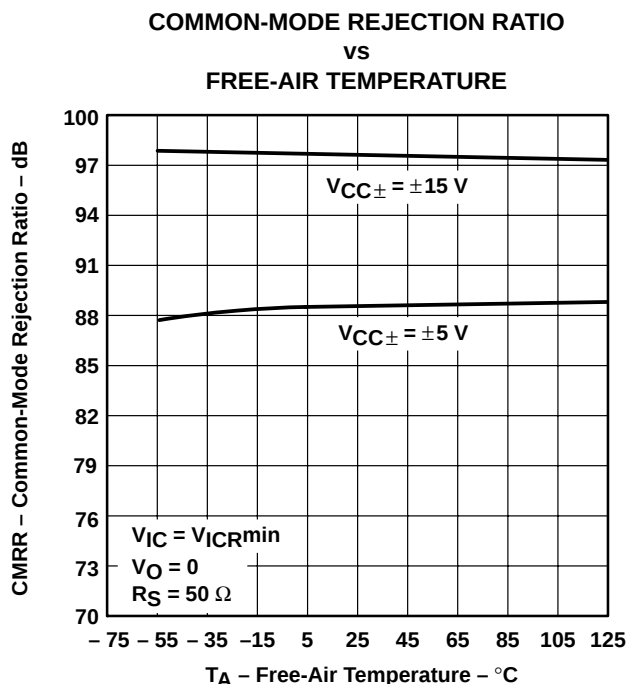


Figure 35

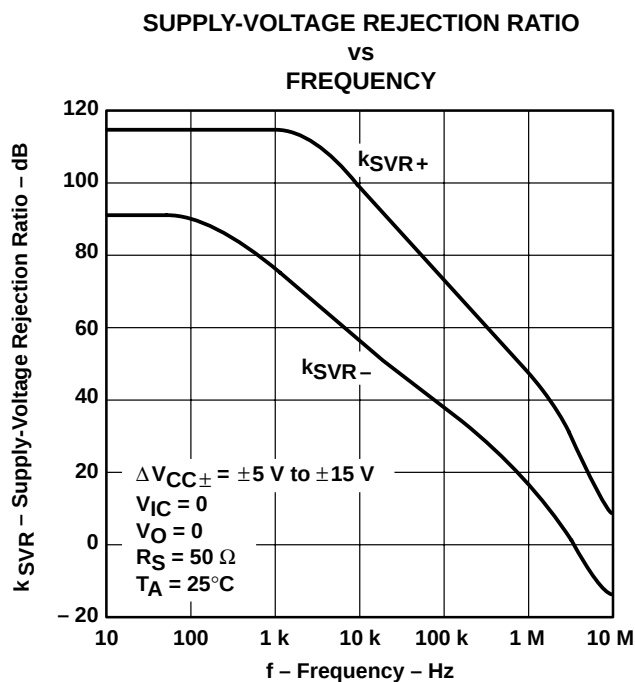


Figure 36

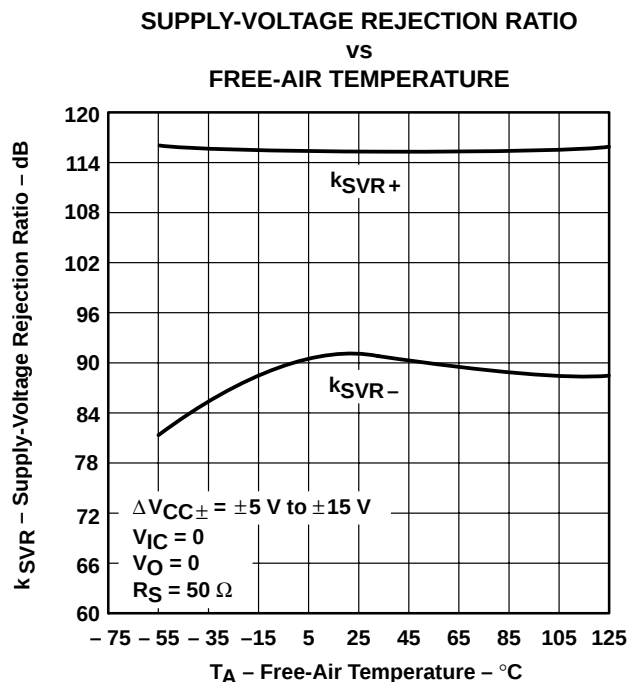


Figure 37

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

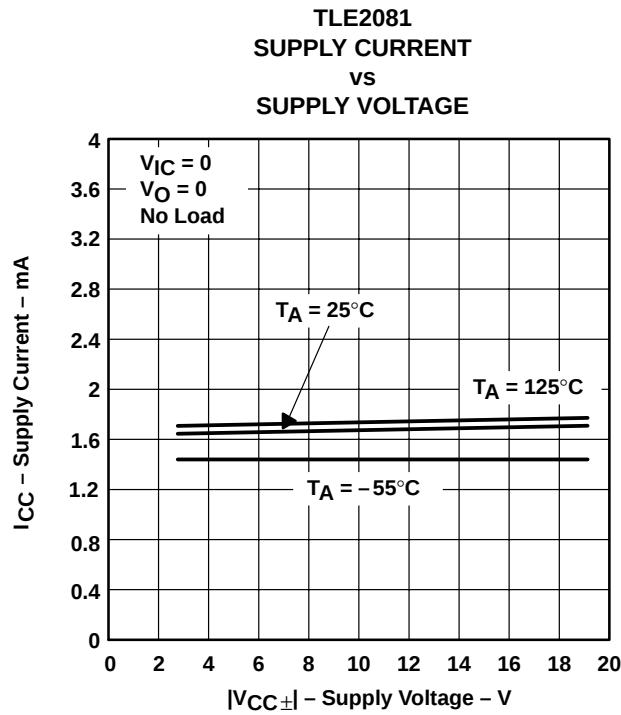


Figure 38

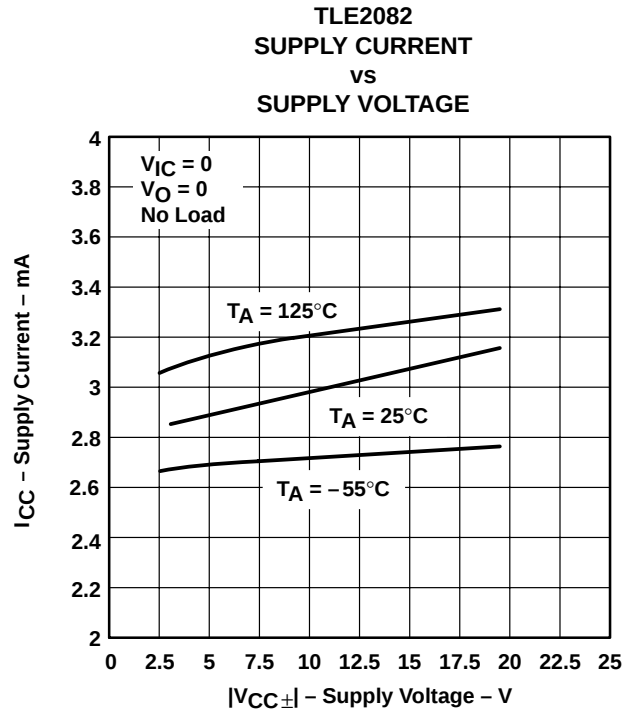


Figure 39

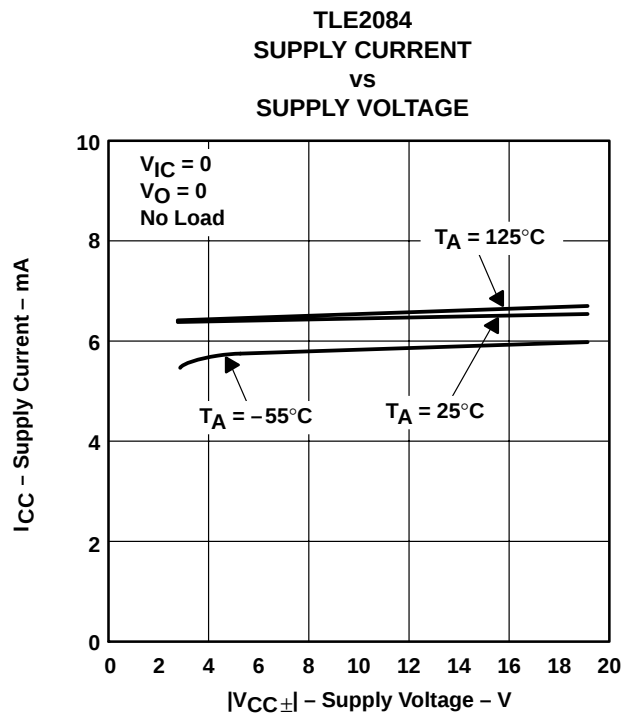


Figure 40

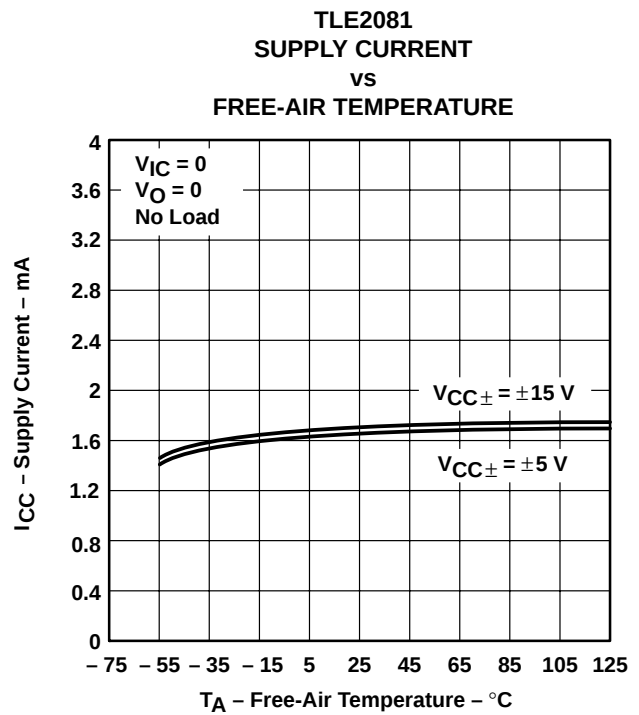


Figure 41

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TYPICAL CHARACTERISTICS†

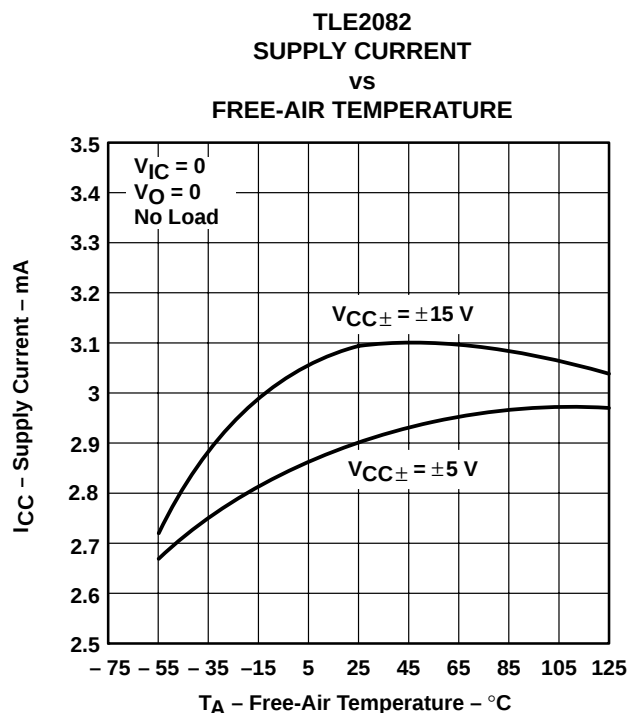


Figure 42

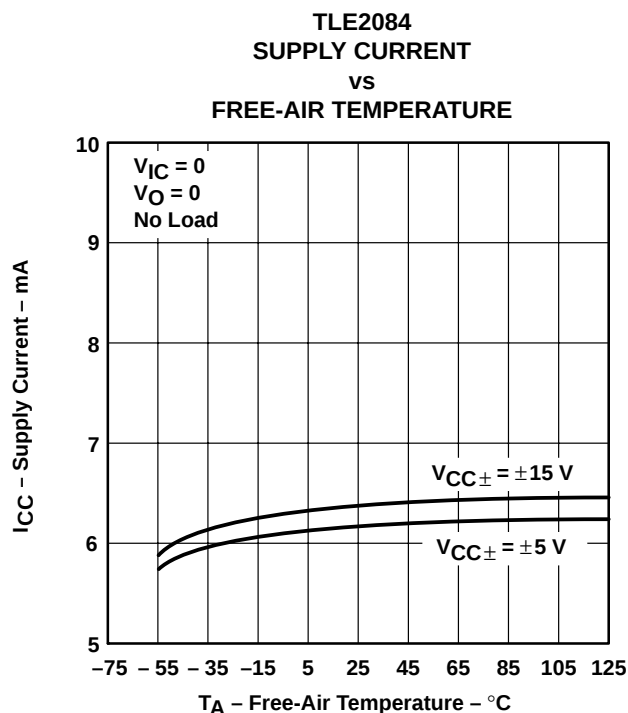


Figure 43

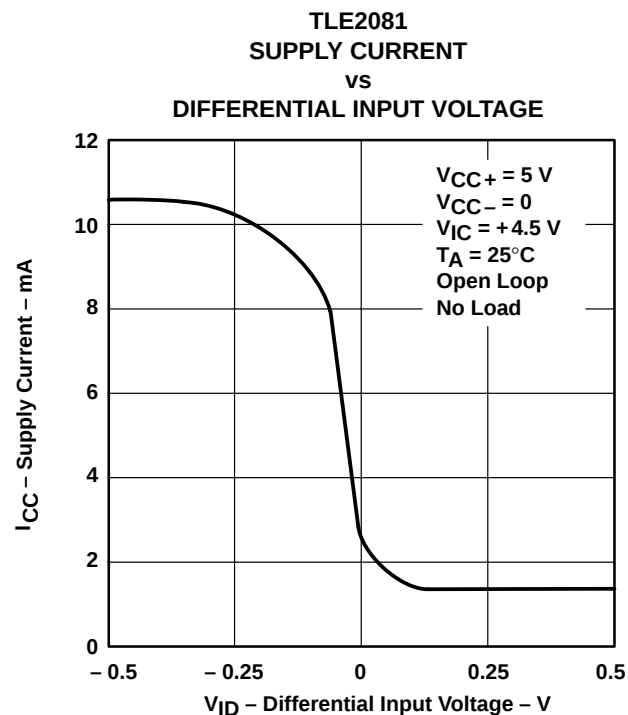


Figure 44

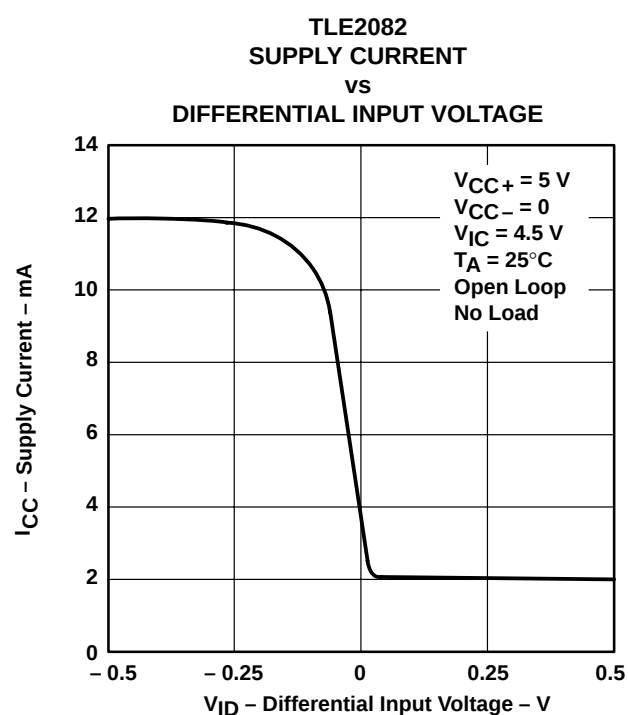
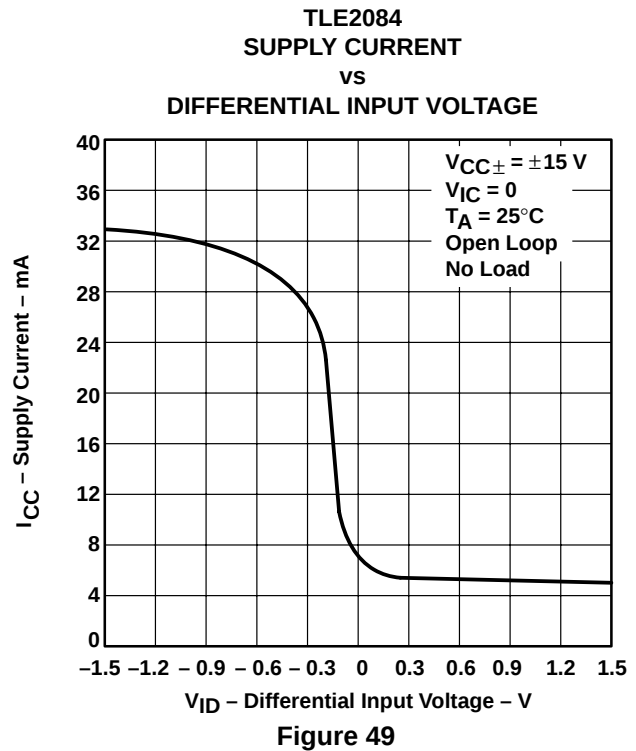
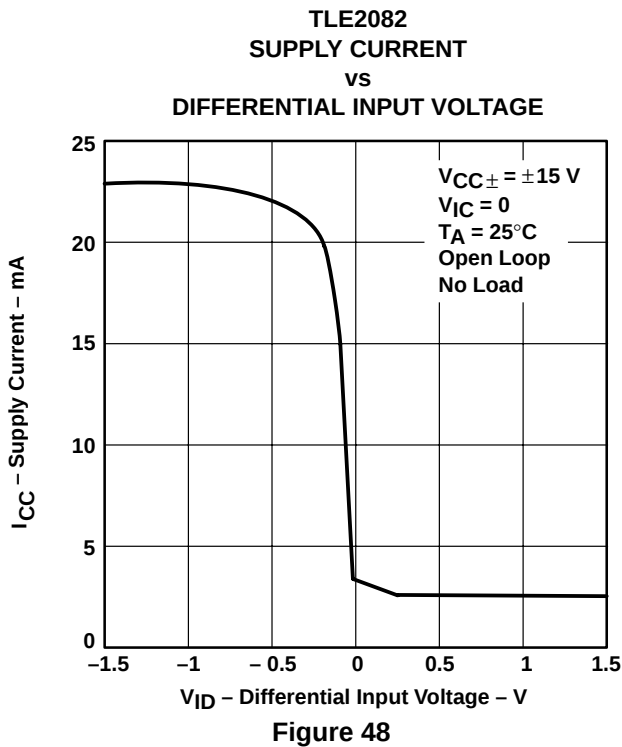
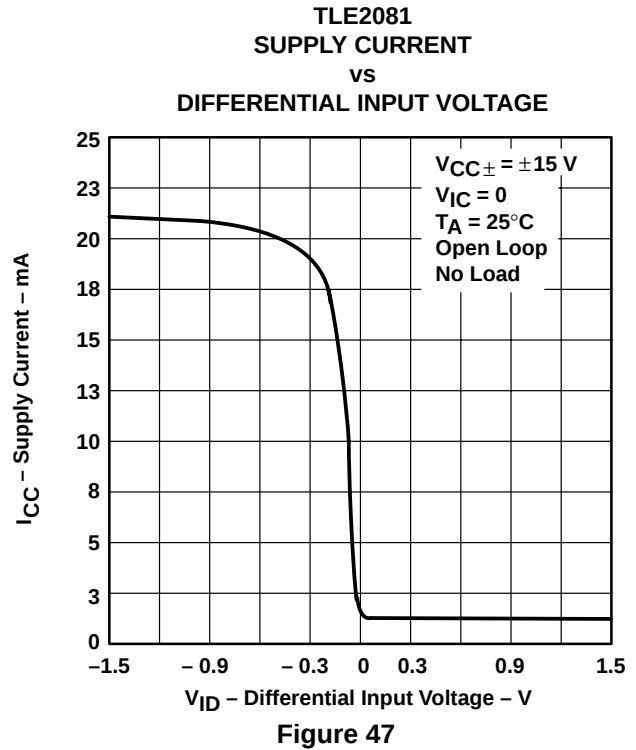
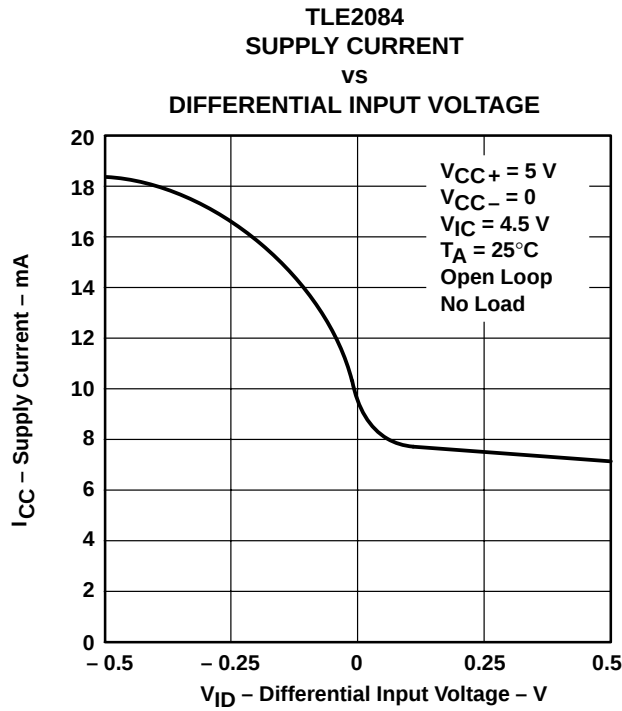


Figure 45

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TYPICAL CHARACTERISTICS†

SHORT-CIRCUIT OUTPUT CURRENT
VS
SUPPLY VOLTAGE

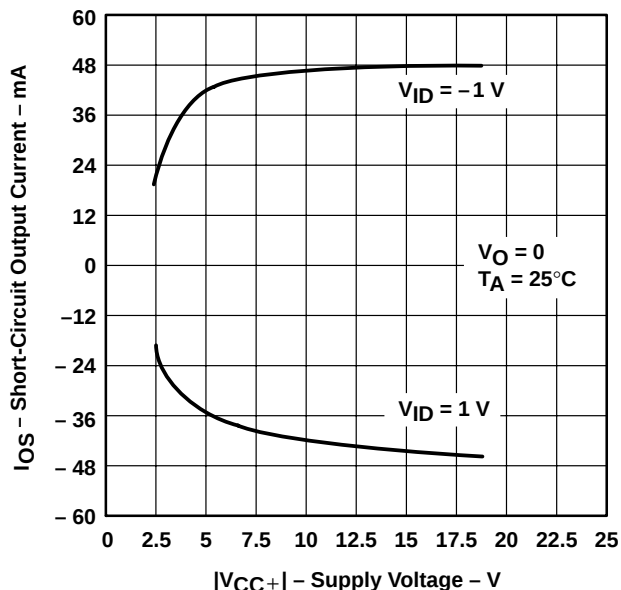


Figure 50

SHORT-CIRCUIT OUTPUT CURRENT
VS
ELAPSED TIME

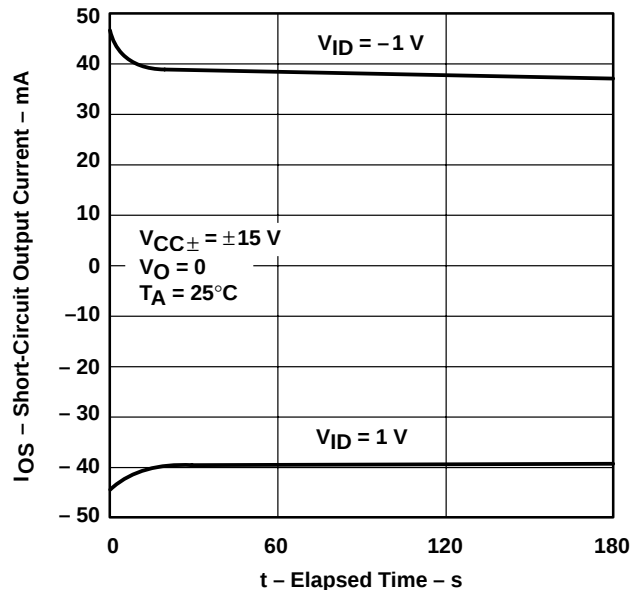


Figure 51

SHORT-CIRCUIT OUTPUT CURRENT
VS
FREE-AIR TEMPERATURE

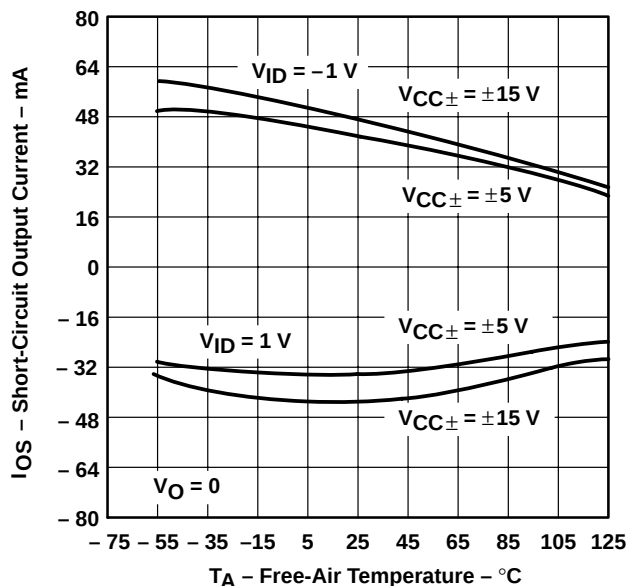


Figure 52

SLEW RATE
VS
FREE-AIR TEMPERATURE

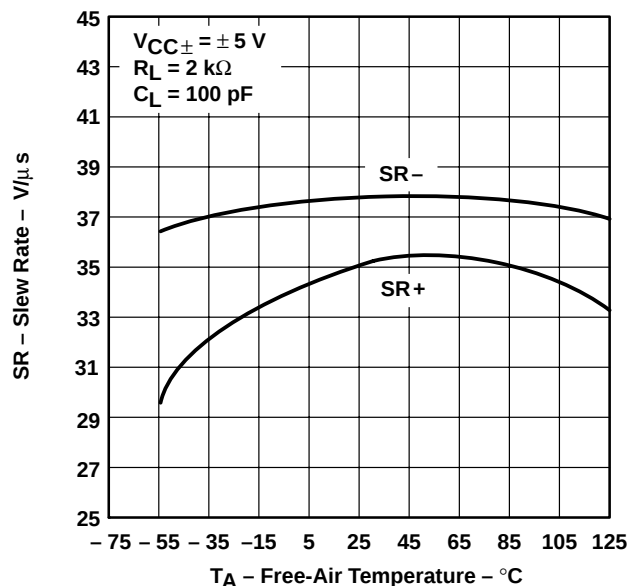


Figure 53

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TYPICAL CHARACTERISTICS†

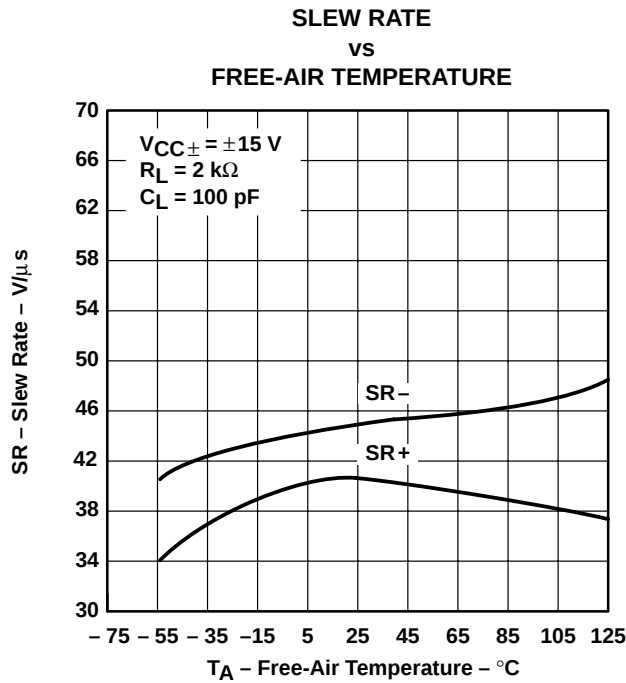


Figure 54

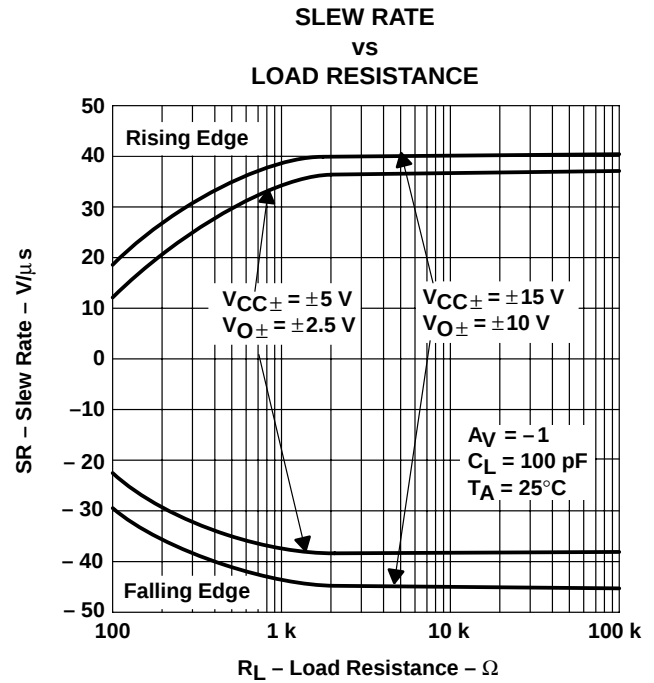


Figure 55

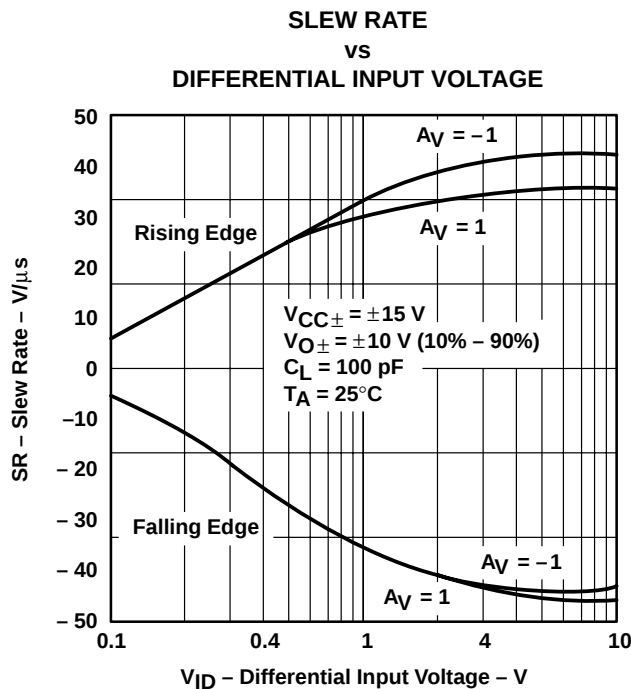


Figure 56

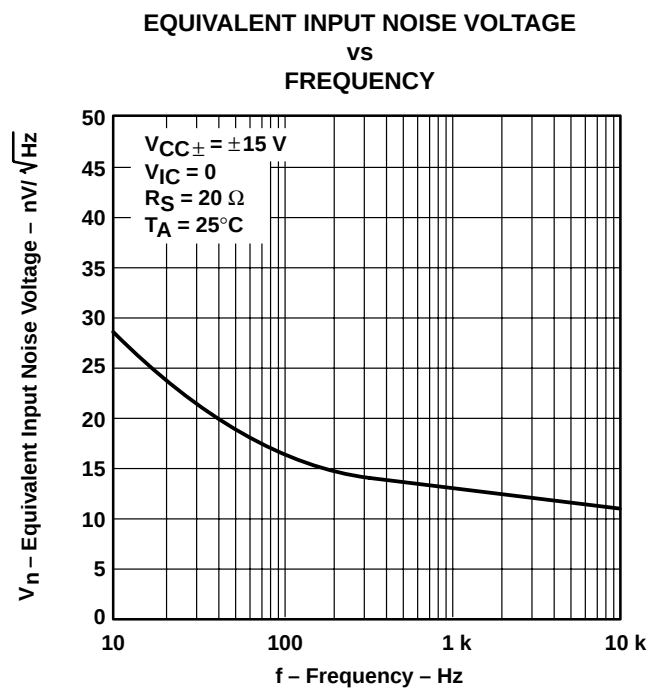


Figure 57

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TYPICAL CHARACTERISTICS

INPUT-REFERRED NOISE VOLTAGE
vs
NOISE BANDWIDTH FREQUENCY

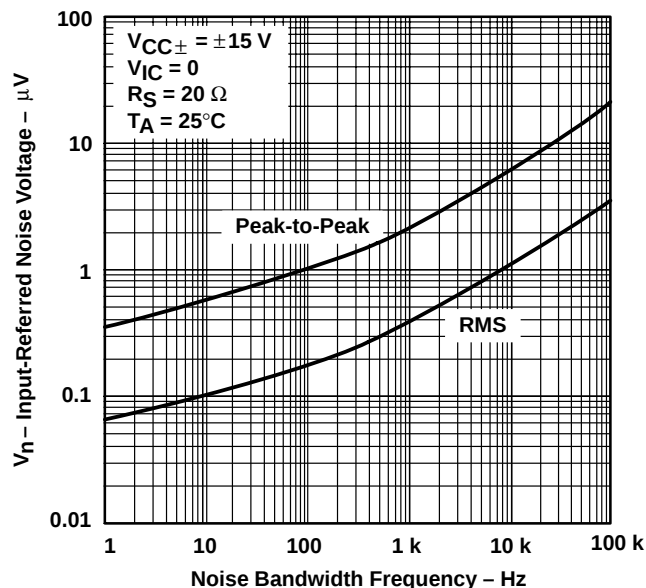


Figure 58

INPUT-REFERRED NOISE VOLTAGE
OVER A 10-SECOND TIME INTERVAL

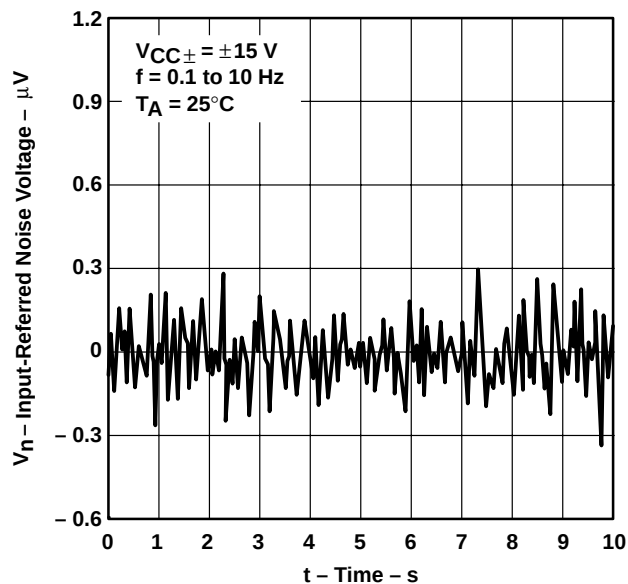


Figure 59

THIRD-OCTAVE SPECTRAL NOISE DENSITY
vs
FREQUENCY BANDS

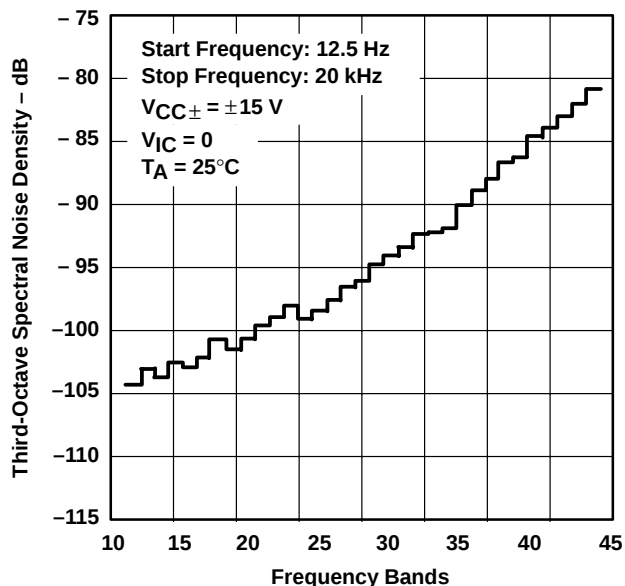


Figure 60

TOTAL HARMONIC DISTORTION PLUS NOISE
vs
FREQUENCY

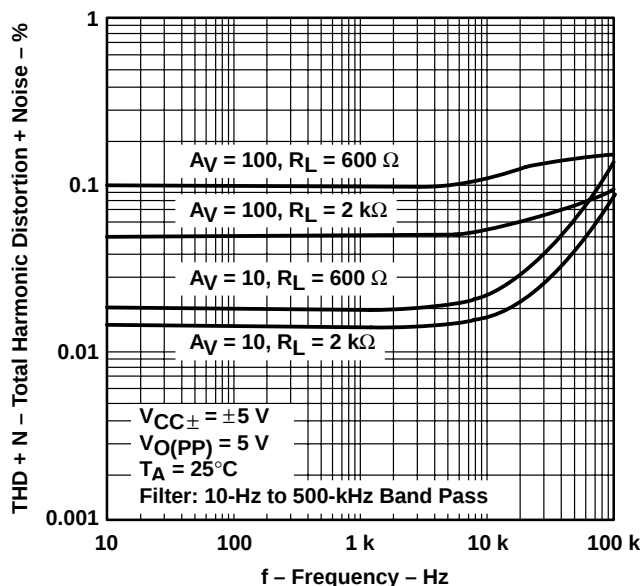


Figure 61

TYPICAL CHARACTERISTICS†

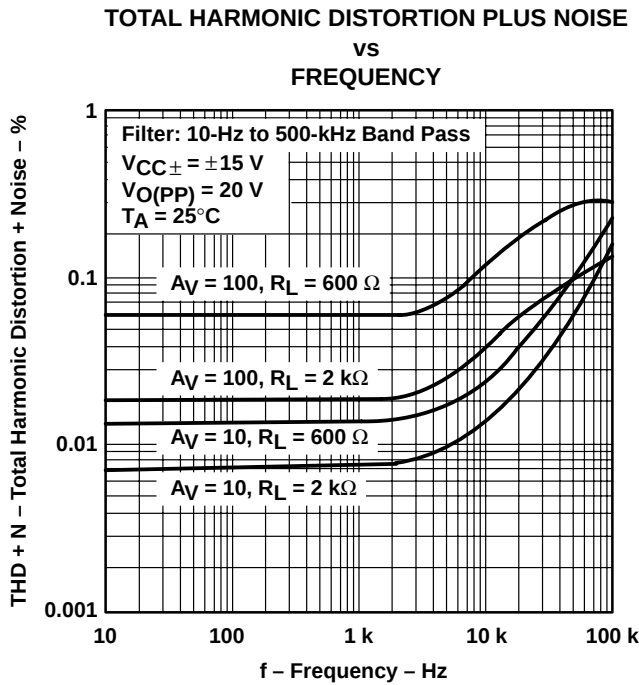


Figure 62

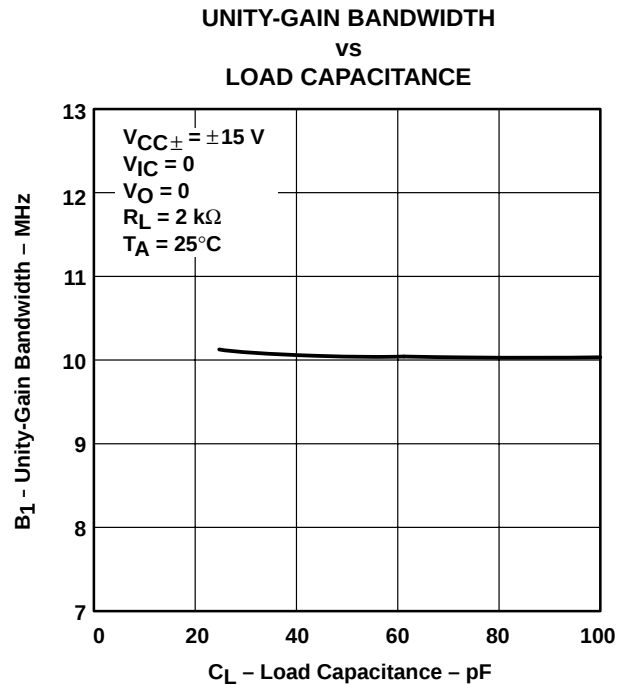


Figure 63

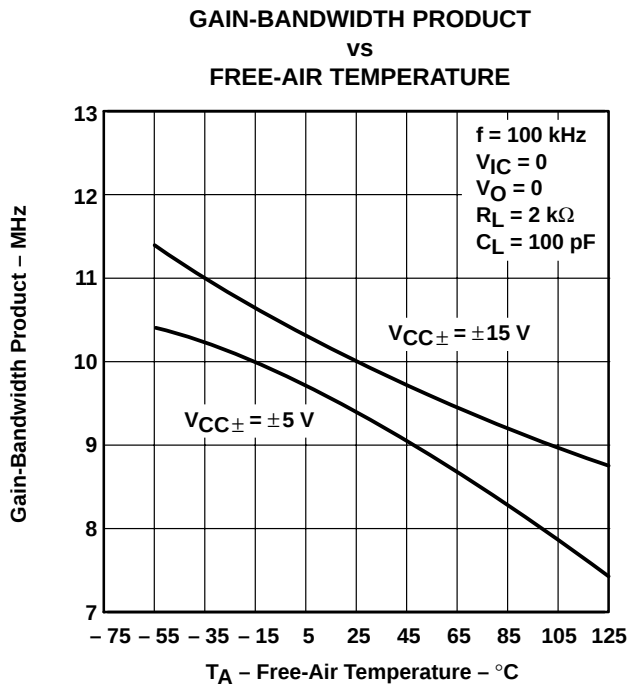


Figure 64

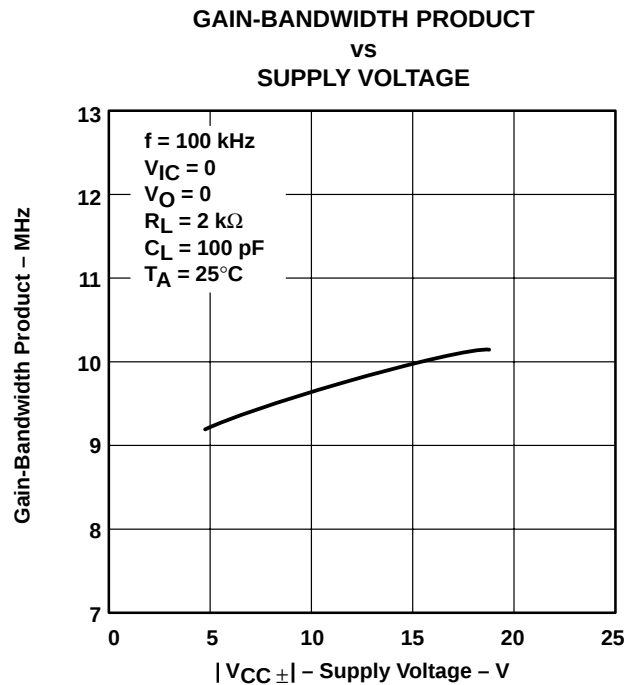


Figure 65

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE208x, TLE208xA, TLE208xY EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

TYPICAL CHARACTERISTICS†

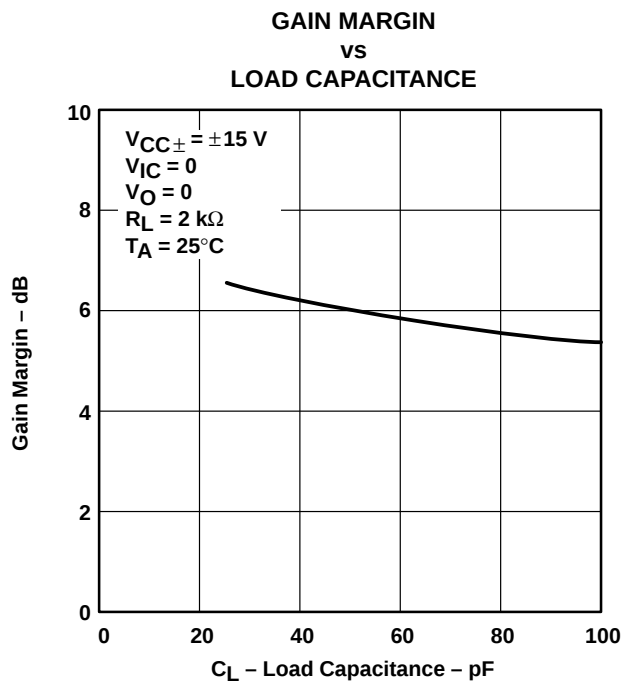


Figure 66

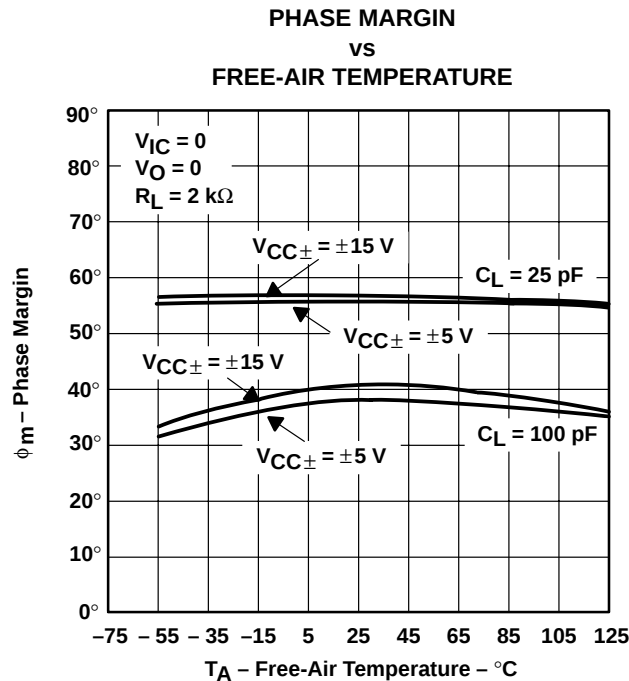


Figure 67

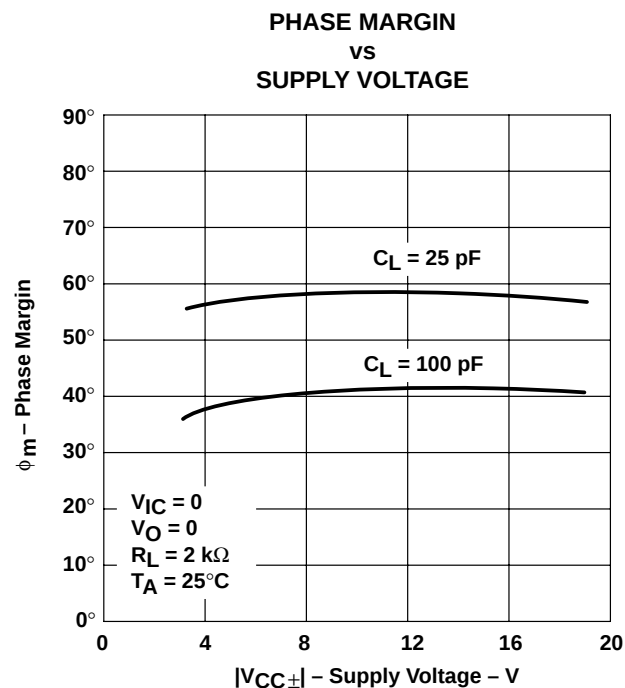


Figure 68

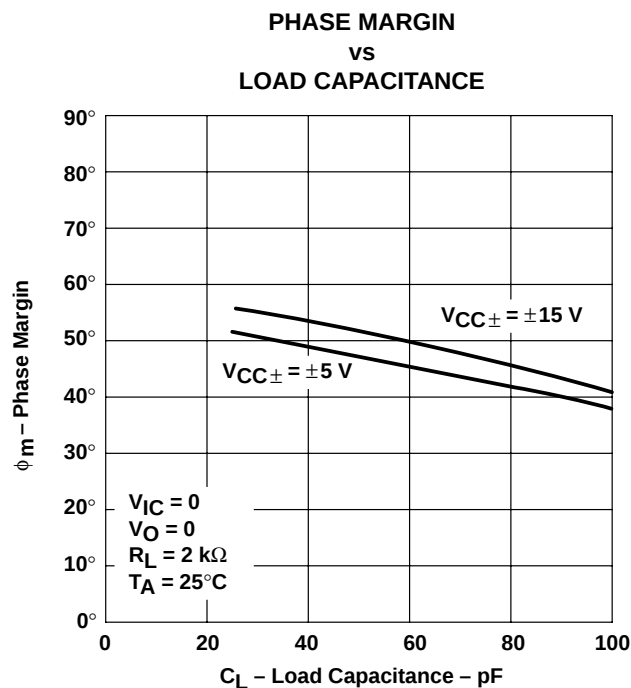


Figure 69

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS†

NONINVERTING LARGE-SIGNAL
PULSE RESPONSE

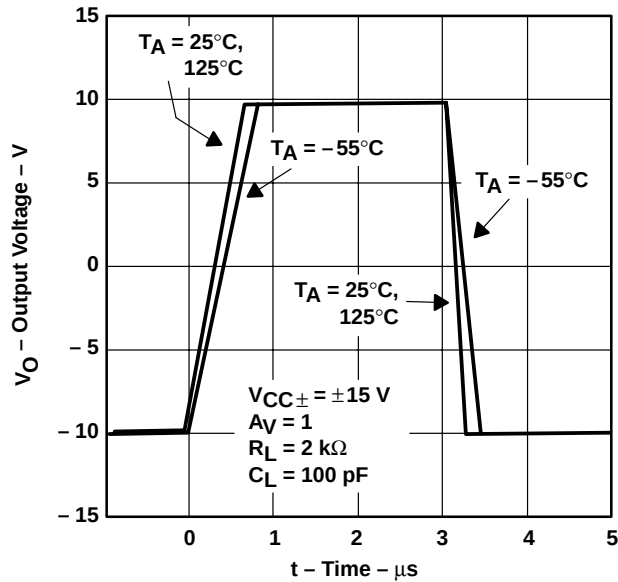


Figure 70

SMALL-SIGNAL PULSE RESPONSE

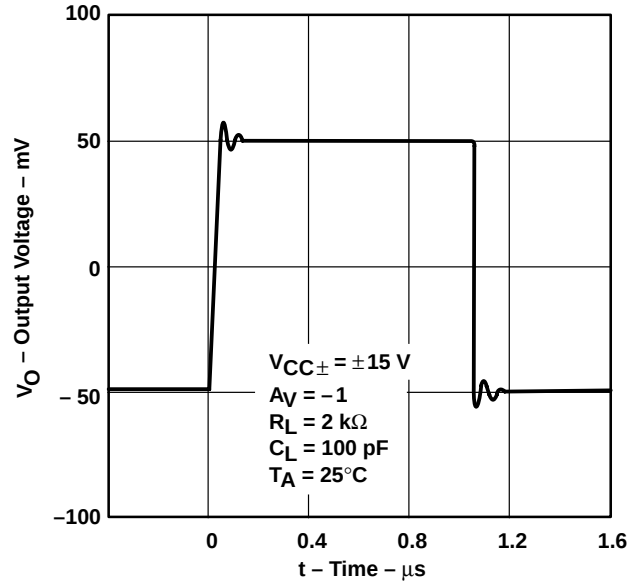


Figure 71

CLOSED-LOOP OUTPUT IMPEDANCE
VS
FREQUENCY

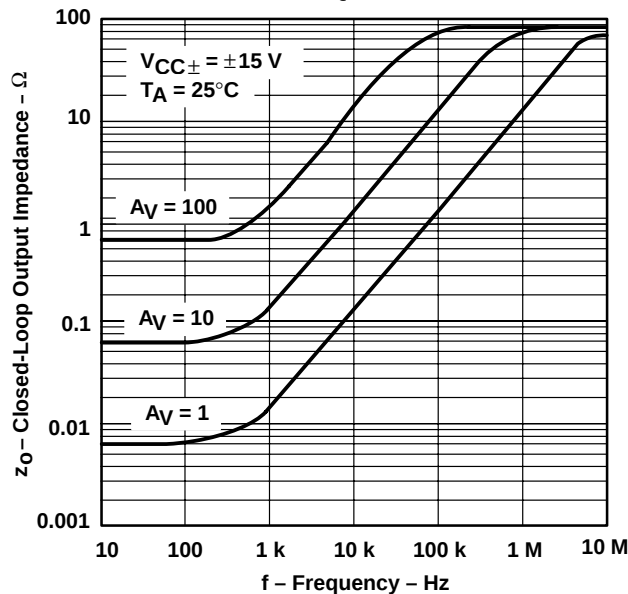


Figure 72

TLE2082 AND TLE2084
CROSSTALK ATTENUATION
VS
FREQUENCY

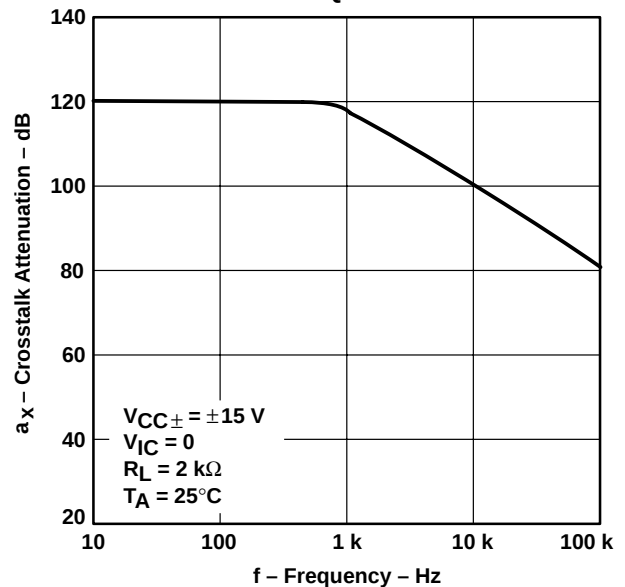


Figure 73

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TLE208x, TLE208xA, TLE208xB EXCALIBUR HIGH-SPEED JFET-INPUT OPERATIONAL AMPLIFIERS

SLOS182B – FEBRUARY 1997 – REVISED JUNE 2001

APPLICATION INFORMATION

input characteristics

The TLE208x, TLE208xA, and TLE208xB are specified with a minimum and a maximum input voltage that if exceeded at either input could cause the device to malfunction. Because of the extremely high input impedance and resulting low bias current requirements, the TLE208x, TLE208xA, and TLE208xB are well suited for low-level signal processing; however, leakage currents on printed-circuit boards and sockets can easily exceed bias current requirements and cause degradation in system performance. It is good practice to include guard rings around inputs (see Figure 74). These guards should be driven from a low-impedance source at the same voltage level as the common-mode input.

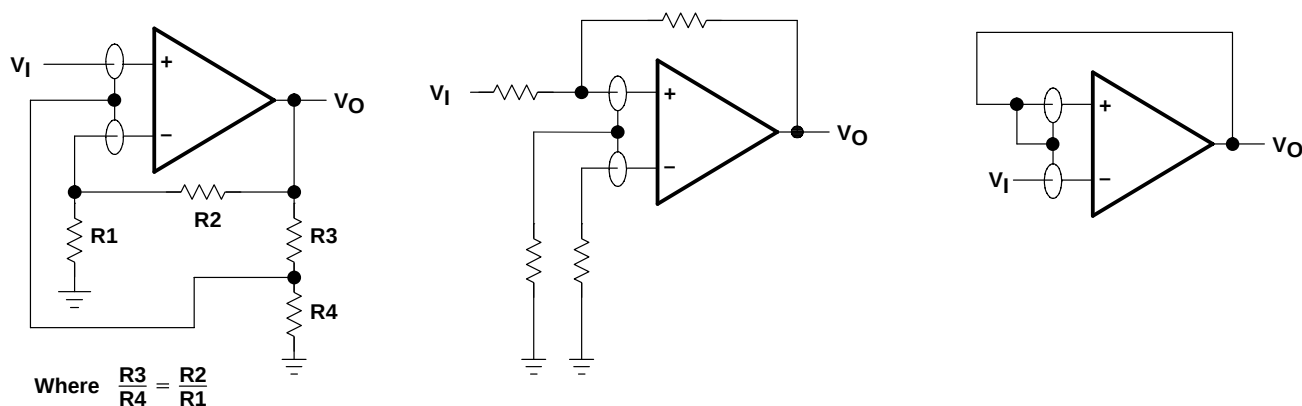


Figure 74. Use of Guard Rings

TLE2081 input offset voltage nulling

The TLE2061 series offers external null pins that can be used to further reduce the input offset voltage. The circuit of Figure 75 can be connected as shown if the feature is desired. When external nulling is not needed, the null pins may be left unconnected.

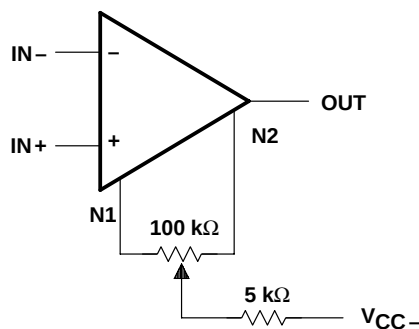


Figure 75. Input Offset Voltage Nulling

APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using *PSpice™ Parts™* model generation software. The Boyle macromodel (see Note 4) and subcircuit in Figure 58 were generated using the TLE208x typical electrical and operating characteristics at $T_A = 25^\circ\text{C}$. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 4: G.R. Boyle, B.M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

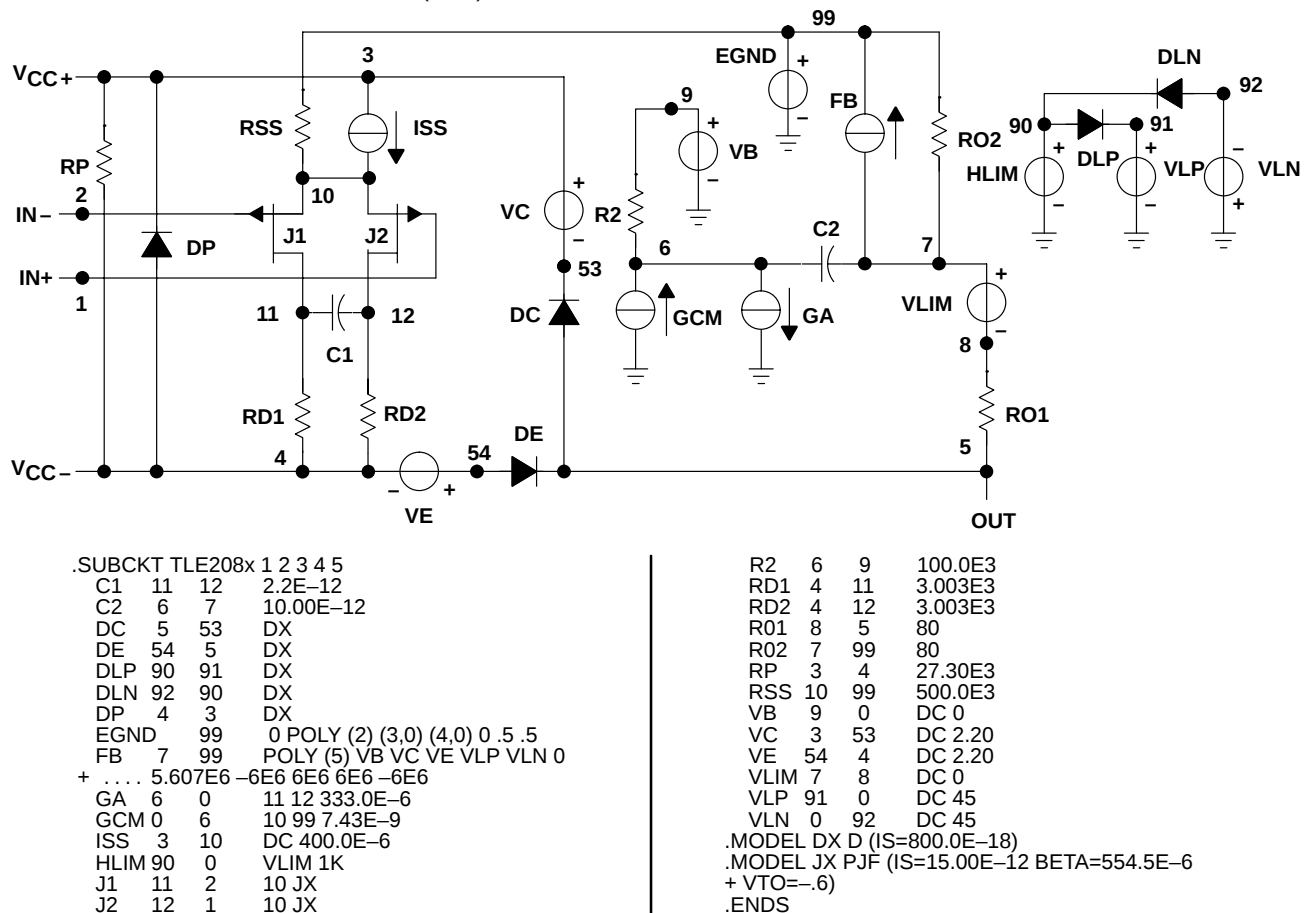


Figure 76. Boyle Macromodel and Subcircuit

PSpice and *Parts* are trademarks of MicroSim Corporation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLE2081ACD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	2081AC
TLE2081ACDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2081AC
TLE2081ACDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2081AC
TLE2081ACP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2081AC
TLE2081ACP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2081AC
TLE2081AID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2081AI
TLE2081AID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2081AI
TLE2081AIP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2081AI
TLE2081AIP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2081AI
TLE2081CD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	2081C
TLE2081CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2081C
TLE2081CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2081C
TLE2081CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2081CP
TLE2081CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2081CP
TLE2081ID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 85	2081I
TLE2081IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2081I
TLE2081IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2081I
TLE2081IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLE2081IP
TLE2081IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2081IP
TLE2082ACD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	2082AC
TLE2082ACDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2082AC
TLE2082ACDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2082AC
TLE2082ACP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLE2082AC
TLE2082ACP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2082AC
TLE2082AID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 85	2082AI
TLE2082AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2082AI
TLE2082AIDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2082AI
TLE2082AIDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2082AI
TLE2082AIDRG4.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2082AI

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLE2082AIP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLE2082AI
TLE2082AIP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2082AI
TLE2082CD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	2082C
TLE2082CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2082C
TLE2082CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2082C
TLE2082CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLE2082CP
TLE2082CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2082CP
TLE2082CPE4	Active	Production	PDIP (P) 8	50 TUBE	-	Call TI	Call TI	See TLE2082CP	
TLE2082ID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 85	2082I
TLE2082IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2082I
TLE2082IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2082I
TLE2082IDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2082I
TLE2082IDRG4.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2082I
TLE2082IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLE2082IP
TLE2082IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2082IP
TLE2084ACDW	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLE2084AC
TLE2084ACDW.A	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLE2084AC
TLE2084ACN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2084ACN
TLE2084ACN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2084ACN
TLE2084CDW	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLE2084C
TLE2084CDW.A	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLE2084C
TLE2084CDWR	Active	Production	SOIC (DW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	TLE2084C
TLE2084CDWR.A	Active	Production	SOIC (DW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLE2084C
TLE2084CN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLE2084CN
TLE2084CN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2084CN
TLE2084IDW	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLE2084I
TLE2084IDW.A	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TLE2084I

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

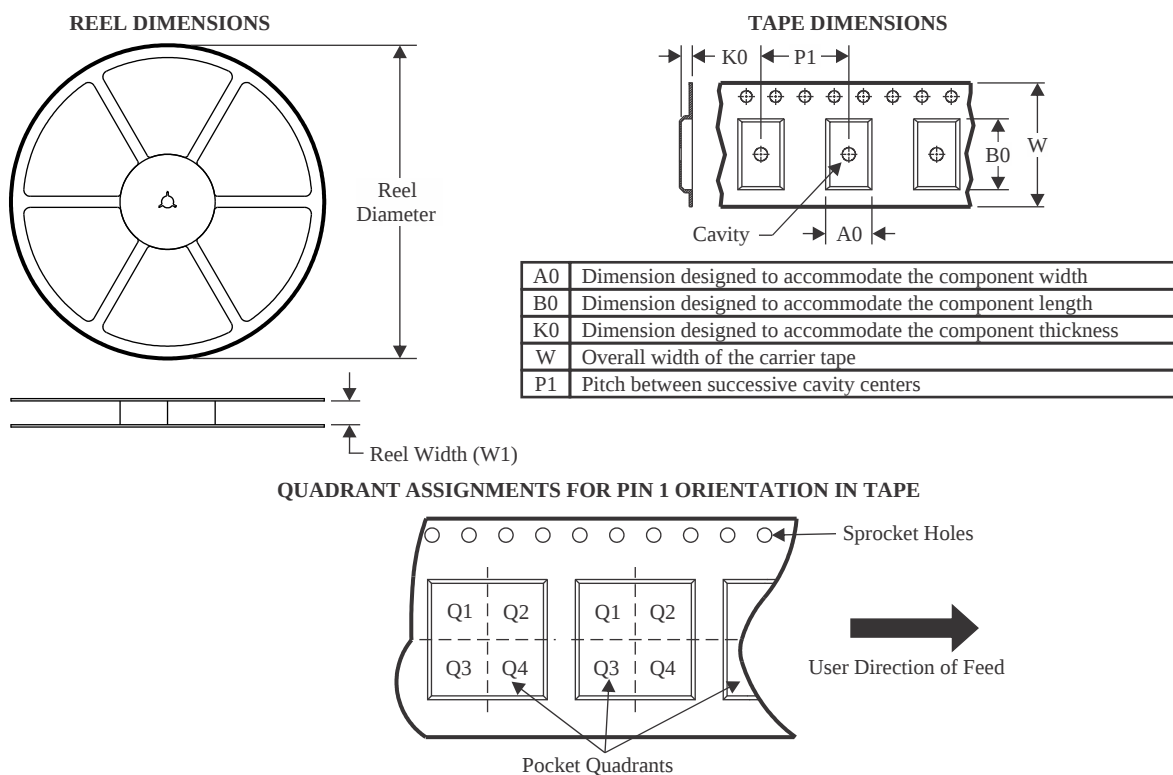
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

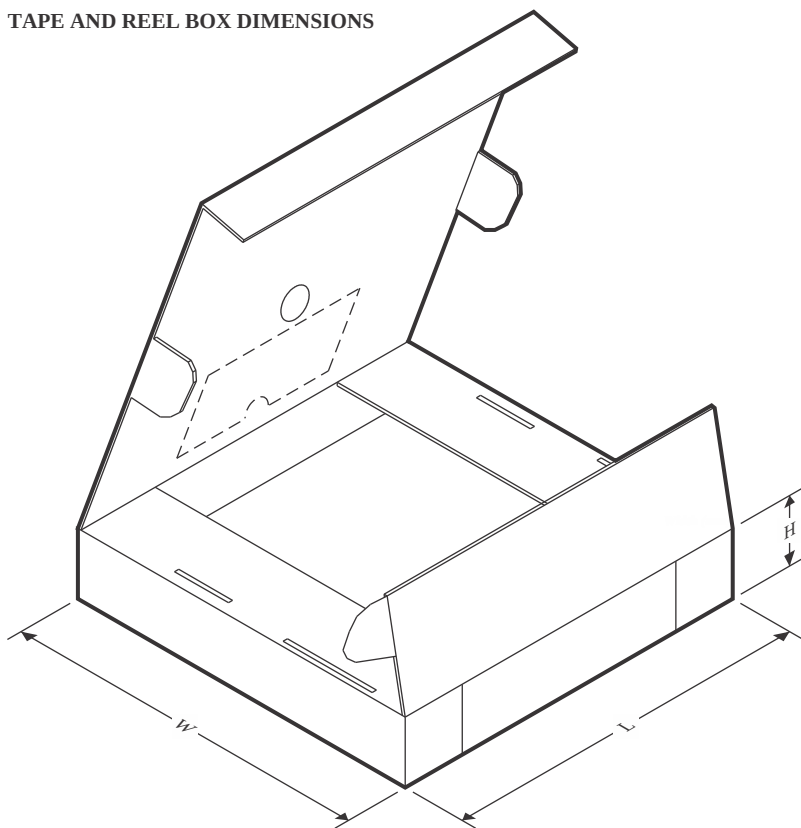
TAPE AND REEL INFORMATION



*All dimensions are nominal

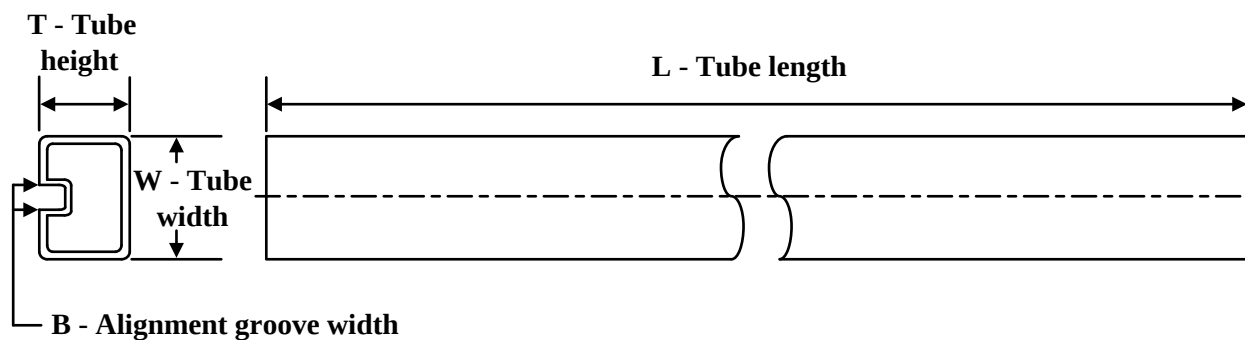
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLE2081ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2081CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2081IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2082ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2082AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2082AIDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2082CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2082IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2082IDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2084CDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLE2081ACDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2081CDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2081IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2082ACDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2082AIDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2082AIDRG4	SOIC	D	8	2500	353.0	353.0	32.0
TLE2082CDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2082IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2082IDRG4	SOIC	D	8	2500	353.0	353.0	32.0
TLE2084CDWR	SOIC	DW	16	2000	350.0	350.0	43.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLE2081ACP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2081ACP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2081AID	D	SOIC	8	75	505.46	6.76	3810	4
TLE2081AID	D	SOIC	8	75	507	8	3940	4.32
TLE2081AID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLE2081AID.A	D	SOIC	8	75	507	8	3940	4.32
TLE2081AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2081AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2081CP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2081CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2081IP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2081IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2082ACP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2082ACP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2082AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2082AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2082CP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2082CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2082IP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2082IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2084ACDW	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2084ACDW.A	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2084ACN	N	PDIP	14	25	506	13.97	11230	4.32
TLE2084ACN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLE2084CDW	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2084CDW.A	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2084CN	N	PDIP	14	25	506	13.97	11230	4.32
TLE2084CN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLE2084IDW	DW	SOIC	16	40	506.98	12.7	4826	6.6

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLE2084IDW.A	DW	SOIC	16	40	506.98	12.7	4826	6.6

GENERIC PACKAGE VIEW

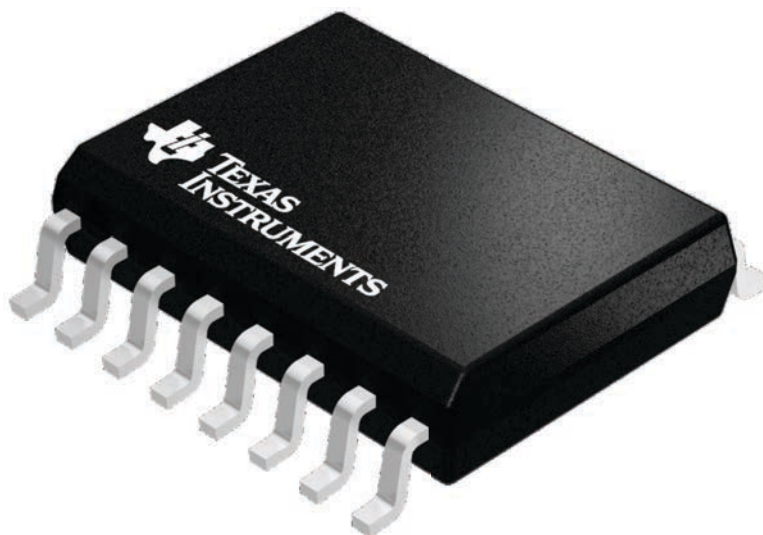
DW 16

SOIC - 2.65 mm max height

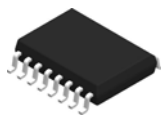
7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4224780/A

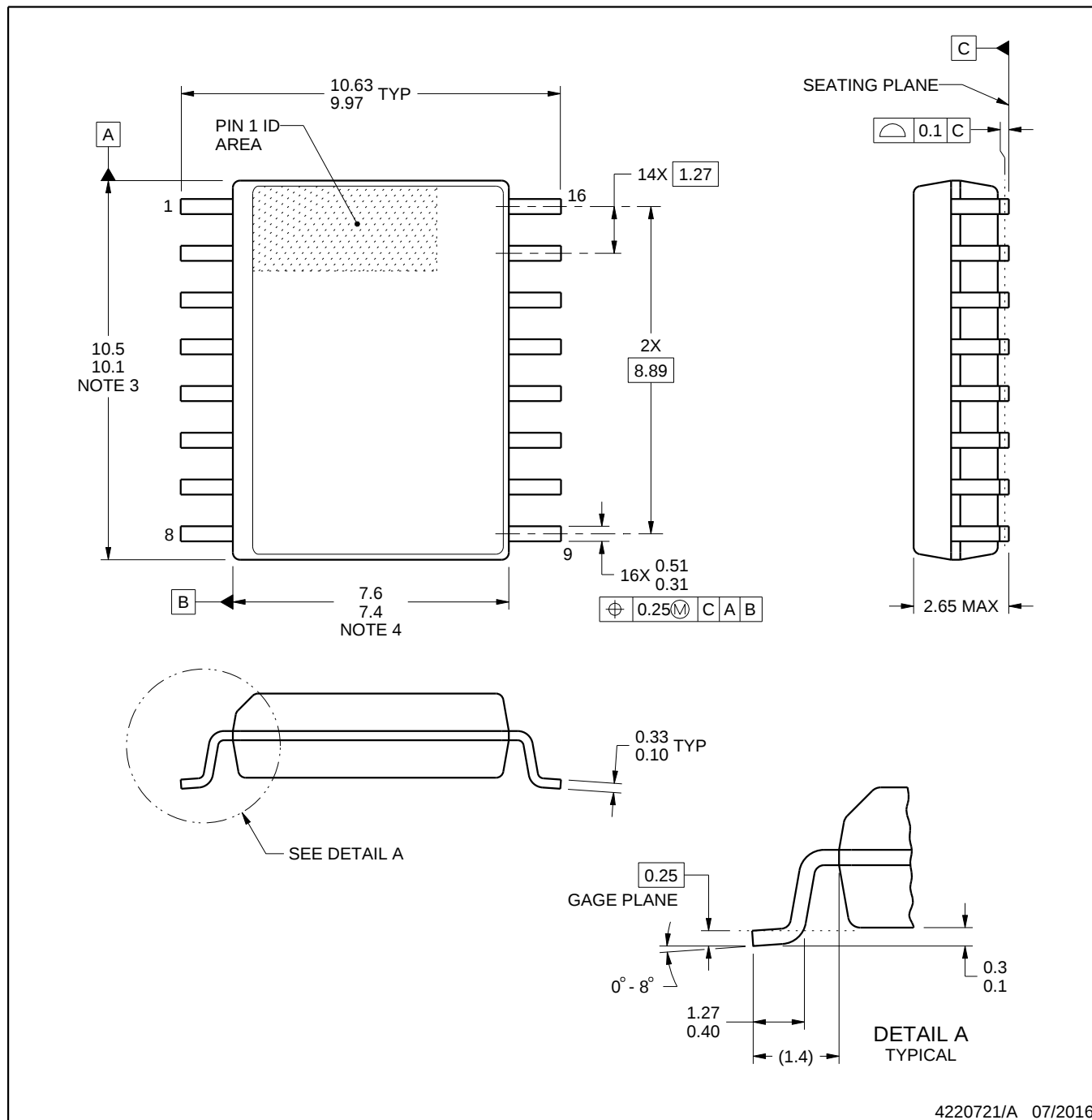


DW0016A

PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



4220721/A 07/2016

NOTES:

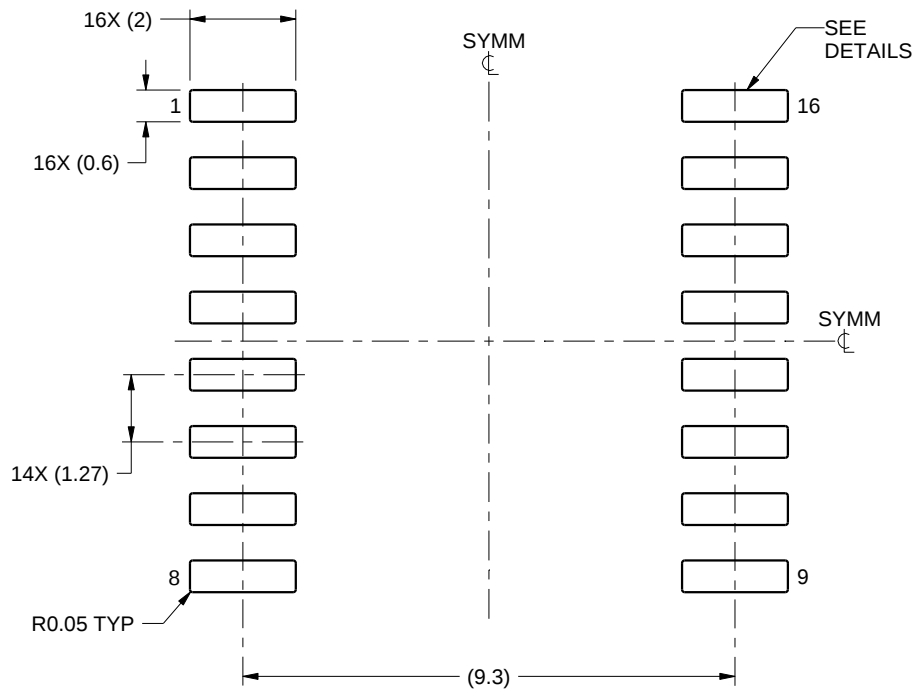
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

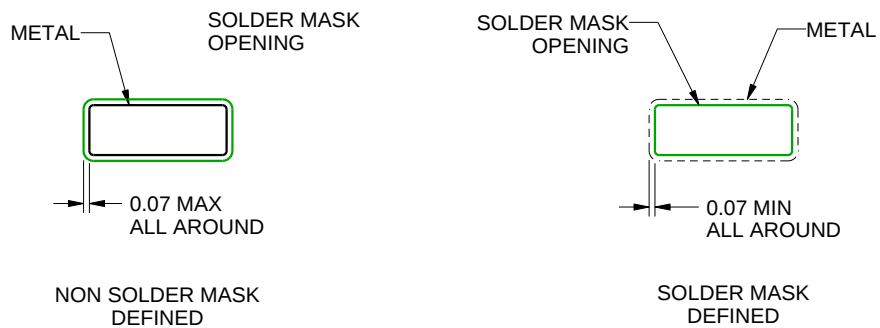
DW0016A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:7X



SOLDER MASK DETAILS

4220721/A 07/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

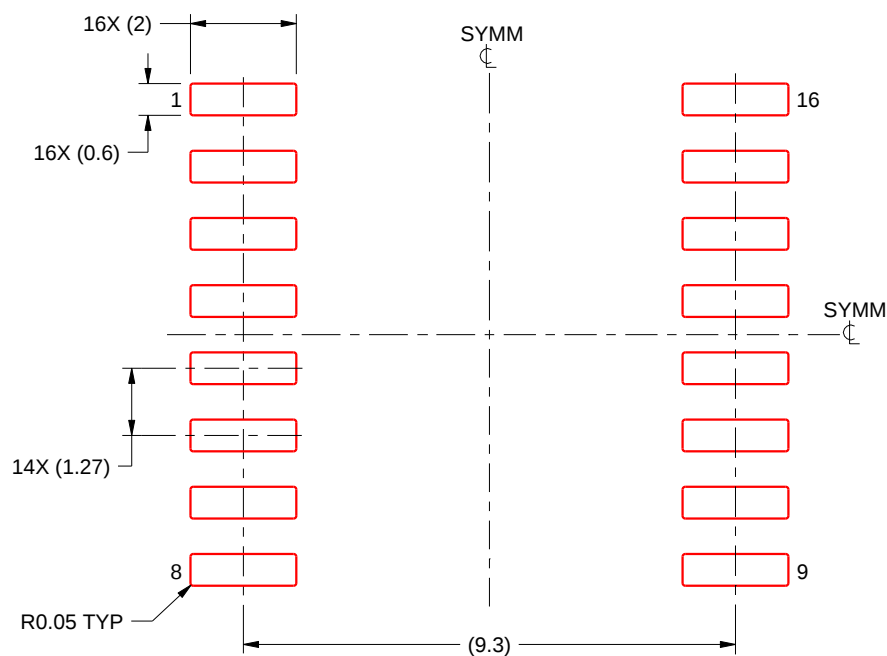
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0016A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

4220721/A 07/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

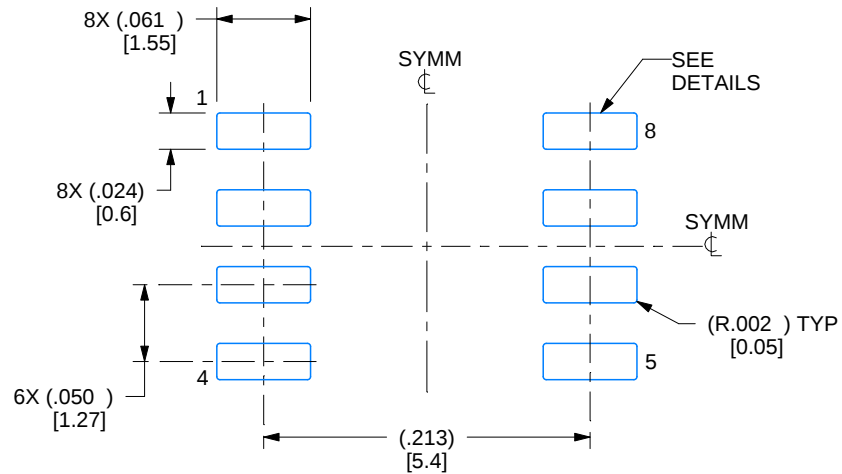


1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

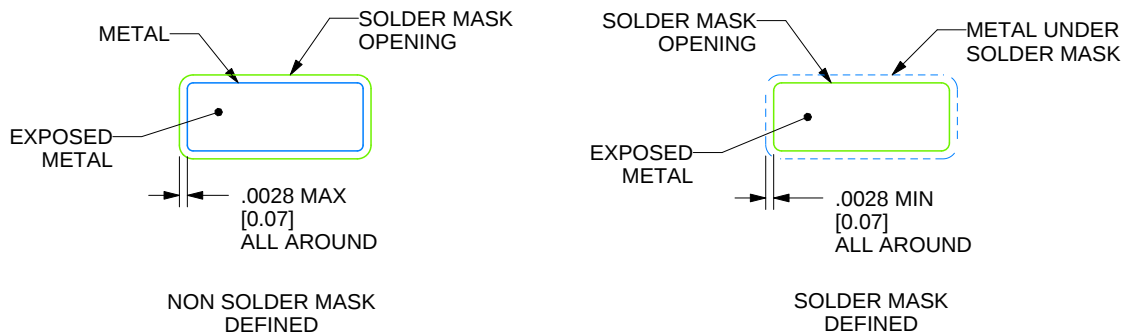
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

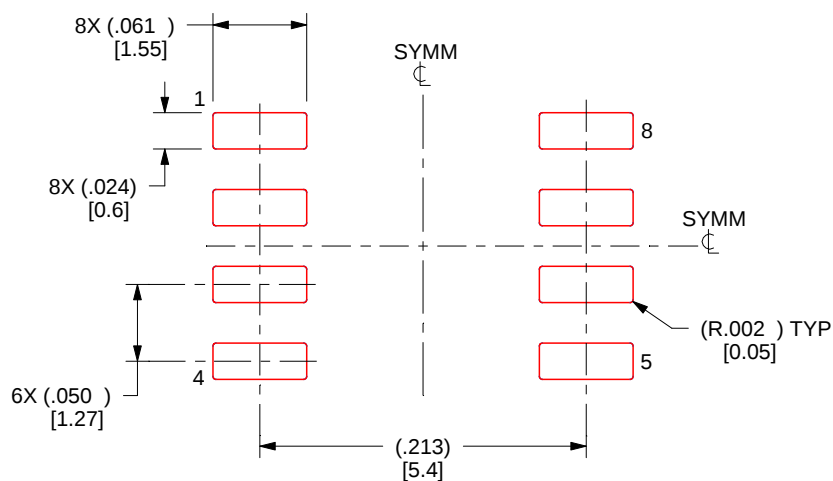
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

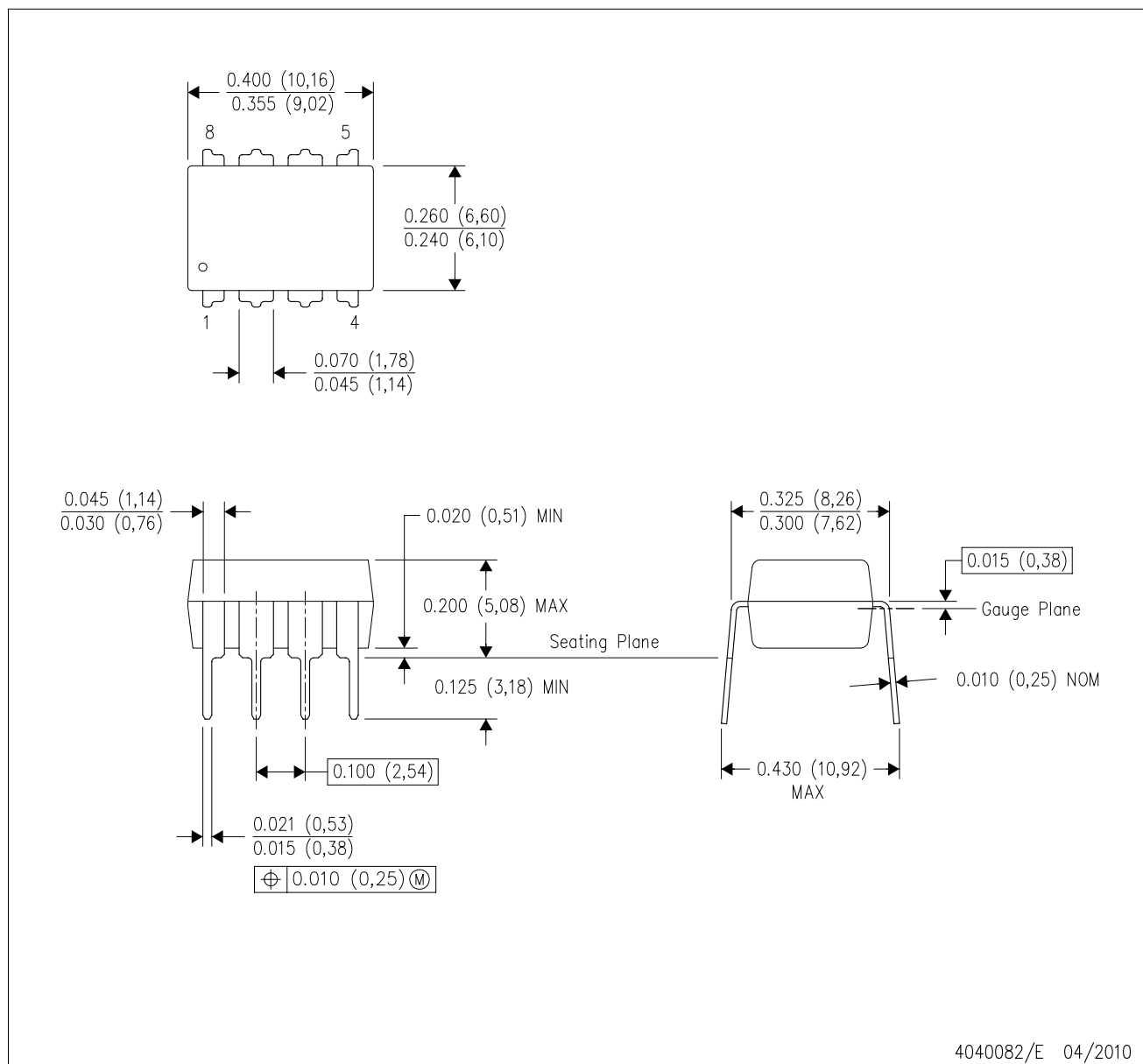
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE

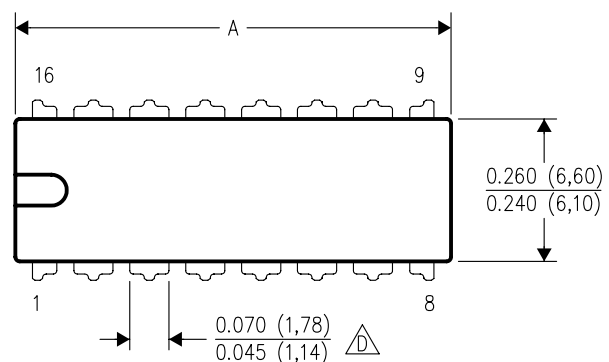


- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

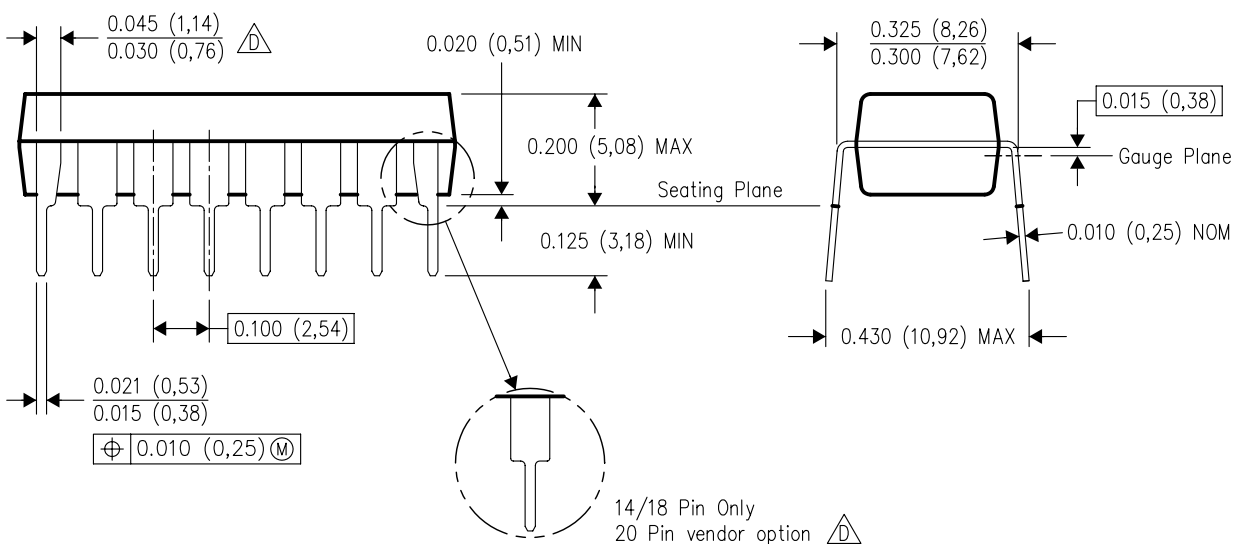
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2025, Texas Instruments Incorporated